

## PCTEST ENGINEERING LABORATORY, INC.

7185 Oakland Mills Road, Columbia, MD 21046 USA Tel. 410.290.6652 / Fax 410.290.6654 http://www.pctest.com



## **HEARING AID COMPATIBILITY**

**Applicant Name:** 

Samsung Electronics Co., Ltd. 129, Samsung-ro, Maetan dong, Yeongtong-gu, Suwon-si Gveongqi-do 16677, Korea

**Date of Testing:** 11/06/2017 - 12/11/2017 **Test Site/Location:** PCTEST Lab, Columbia, MD, USA **Test Report Serial No.:** 1M1711060289-13-R1.A3L

FCC ID: A3LSMG965U

APPLICANT: SAMSUNG ELECTRONICS CO., LTD.

Scope of Test: RF Emissions Testing

Application Type: Certification CFR §20.19(b) FCC Rule Part(s): **HAC Standard:** ANSI C63.19-2011

CTIA Test Plan for Hearing Aid Compatibility Rev 3.1, February 2017

285076 D01 HAC Guidance v05

285076 D02 T-Coil testing for CMRS IP v03

**DUT Type:** Portable Handset

Model: SM-G965U

Additional Model(s): SM-G965U1, SM-G965W

Test Device Serial No.: Pre-Production Sample [S/N: 37046]

C63.19-2011 HAC Category: M4 (RF EMISSIONS CATEGORY)

Note: This revised Test Report (S/N: 1M1711060289-13-R1.A3L) supersedes and replaces the previously issued test report on the same subject device for the same type of testing as indicated. Please discard or destroy the previously issued test report(s) and dispose of it accordingly.

This wireless portable device has been shown to be hearing-aid compatible under the above rated category, specified in ANSI/IEEE Std. C63.19-2011 and has been tested in accordance with the specified measurement procedures. Hearing-Aid Compatibility is based on the assumption that all production units will be designed electrically identical to the device tested in this report. Test results reported herein relate only to the item(s) tested. North America bands only.

I attest to the accuracy of data. All measurements reported herein were performed by me or were made under my supervision and are correct to the best of my knowledge and belief. I assume full responsibility for the completeness of these measurements and vouch for the qualifications of all persons taking them.









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## 1. INTRODUCTION

On July 10, 2003, the Federal Communications Commission (FCC) adopted new rules requiring wireless manufacturers and service providers to provide digital wireless phones that are compatible with hearing aids. The FCC has modified the exemption for wireless phones under the Hearing Aid Compatibility Act of 1998 (HAC Act) in WT Docket 01-309 RM-8658¹ to extend the benefits of wireless telecommunications to individuals with hearing disabilities. These benefits encompass business, social and emergency communications, which increase the value of the wireless network for everyone. An estimated more than 10% of the population in the United States show signs of hearing impairment and of that fraction, almost 80% use hearing aids. Approximately 500 million people worldwide suffer from hearing loss.

## **Compatibility Tests Involved:**

The standard calls for wireless communications devices to be measured for:

- RF Electric-field emissions
- T-coil mode, magnetic-signal strength in the audio band
- T-coil mode, magnetic-signal frequency response through the audio band
- T-coil mode, magnetic-signal and noise articulation index

The hearing aid must be measured for:

- RF immunity in microphone mode
- RF immunity in T-coil mode

In the following tests and results, this report includes the evaluation for a wireless communications device.



Figure 1-1 Hearing Aid in-vitu

<sup>&</sup>lt;sup>1</sup> FCC Rule & Order, WT Docket 01-309 RM-8658

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#### 2. **DUT DESCRIPTION**



FCC ID: A3LSMG965U

Manufacturer: Samsung Electronics Co., Ltd.

129, Samsung-ro, Maetan dong,

Yeongtong-gu, Suwon-si Gyeonggi-do 16677, Korea

Model: SM-G965U

Additional Model(s): SM-G965U1. SM-G965W

Serial Number: 37046

Antenna Configurations: Internal Antenna

**HAC Test Configurations:** Cell. CDMA, 564\*, 1013, 384, 777, BT Off, WLAN Off, LTE Off

> PCS CDMA, 25, 600, 1175, BT Off, WLAN Off, LTE Off GSM 850, 128, 190, 251, BT Off, WLAN Off, LTE Off GSM 1900, 512, 661, 810, BT Off, WLAN Off, LTE Off

LTE TDD B41 PC3; BW's: 20MHz; 39750, 40185, 40620, 41055, 41490; BT Off, WLAN Off LTE TDD B41 PC2; BW's: 5MHz; 39750, 40185, 40620, 41055, 41490; BT Off, WLAN Off

\*Note: Cell. CDMA Ch. 564 is the Part 90S test channel.

DUT Type: Portable Handset

#### Power Reduction for WIFI

This device uses an independent fixed level power reduction mechanism for all WIFI operations during voice or VoIP held to ear scenarios. Reduced powers were used to evaluate for low-power exemption in Section 9.II for WIFI. Detailed descriptions of the power reduction mechanism are included in the operational description.

#### II. LTE Band Selection

This device supports the following pairs of LTE bands with similar frequencies: LTE B12 & B17, LTE B5 & B26, LTE B4 & B66, LTE B2 & B25, and LTE B38 & B41. Each pair of LTE bands has the same target power and shares the same transmission path. Since the supported frequency spans for the smaller LTE bands are completely covered by the larger LTE bands, only the larger LTE bands (LTE B12, LTE B26, LTE B66, LTE B25, and LTE B41) were evaluated for hearing-aid compliance.

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Table 2-1: SM-G965U & SM-G965U1 HAC Air Interfaces

	lab	16 2-1. SWI-0300	O & SIVI-GS	65U1 HAC Air interraces	
Air-Interface	Band (MHz)	Type Transport	HAC Tested	Simultaneous But Not Tested	Name of Voice Service
	835		V	V M/IEL DT	CMADC Mains
CDMA	1900	VO	Yes	Yes: WIFI or BT	CMRS Voice
	EVDO	VD	No <sup>1</sup>	Yes: WIFI or BT	Google Duo
	850	VO	Yes	Yes: WIFI or BT	CMRS Voice
GSM	1900	VO	163	res. Wiri of B1	CIVINS VOICE
	GPRS/EDGE	VD	No <sup>1</sup>	Yes: WIFI or BT	Google Duo
	850				
UMTS	1700	VD	No <sup>1</sup>	Yes: WIFI or BT	CMRS Voice
OIVITS	1900				
	HSPA	VD	No <sup>1</sup>	Yes: WIFI or BT	Google Duo
	680 (B71)				
	700 (B12)			Yes: WIFI or BT	
Γ	700 (B17)		No <sup>1</sup>		VolTE
	780 (B13)				
	790 (B14)				
	850 (B5)	VD			
LTE (FDD)	850 (B26)				VoLTE Google Duo
	1700 (B4)				Coogle Duo
	1700 (B66)				
	1900 (B2)				
	1900 (B25)				
	2300 (B30)				
	2500 (B7)				
LTE (TDD)	2600 (B38)	VD	Yes	Yes: WIFI or BT	Google Duo
LIL (IDD)	2600 (B41)	VD	163	res. Wiri of Bi	doogle Duo
	2450				
	5200 (U-NII 1)				VoWIFI
WIFI	5300 (U-NII 2A)	VD	No <sup>1</sup>	Yes: CDMA, GSM, UMTS, or LTE	Google Duo
	5500 (U-NII 2C)				6.0 2 40
	5800 (U-NII 3)				
ВТ	2450	DT	No	Yes: CDMA, GSM, UMTS, or LTE	N/A
Type Transport			Notes:		
VO = Voice Only DT = Digital Data - Not intended for CMRS Service		1. Evaluated f	or MIF and low-power exemption.	•	
VD = CMRS and IP Voice over Data Transport					

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Table 2-2: SM-G965W HAC Air Interfaces

		1 able 2-2. 3	MI-GBOOM II	AC Air Interfaces	
Air-Interface	Band (MHz)	Type Transport	HAC Tested	Simultaneous But Not Tested	Name of Voice Service
	850	VO	Yes	Yes: WIFI or BT	CMRS Voice
GSM	1900	VO	163	res. Wiri of bi	CIVINS VOICE
	GPRS/EDGE	VD	No <sup>1</sup>	Yes: WIFI or BT	Google Duo
	850				
UMTS	1700	VD	No <sup>1</sup>	Yes: WIFI or BT	CMRS Voice
OIVITS	1900				
	HSPA	VD	No <sup>1</sup>	Yes: WIFI or BT	Google Duo
	700 (B12)				
	700 (B17)			Yes: WIFI or BT	VoLTE Google Duo
	780 (B13)	VD	No <sup>1</sup>		
LTE (FDD)	850 (B5)				
	1700 (B4)				
LIL (FDD)	1700 (B66)				
	1900 (B2)				
	1900 (B25)				
	2300 (B30)				
	2500 (B7)				
LTE (TDD)	2600 (B38)	VD	Yes Yes: WIFI or BT G	Google Duo	
LIL (IDD)	2600 (B41)	VD	163	Tes. WIIT OF BT	Google Duo
	2450				
	5200 (U-NII 1)				\/o\\/!\[!
WIFI	5300 (U-NII 2A)	VD	No <sup>1</sup>	Yes: GSM, UMTS, or LTE	VoWIFI Google Duo
	5500 (U-NII 2C)				
	5800 (U-NII 3)				
BT	2450	DT	No	Yes: GSM, UMTS, or LTE	N/A
Type Transport VO = Voice Only DT = Digital Data - Not intended for CMRS Service VD = CMRS and IP Voice over Data Transport			Notes: 1. Evaluated fo	or MIF and low-power exemption	

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# 3. ANSI/IEEE C63.19 PERFORMANCE CATEGORIES

## I. RF EMISSIONS

The ANSI Standard presents performance requirements for acceptable interoperability of hearing aids with wireless communications devices. When these parameters are met, a hearing aid operates acceptably in close proximity to a wireless communications device.

Category	Telephone RF Parameters		
Near field Category	E-field emissions CW dB(V/m)		
	f < 960 MHz		
M1	50 to 55		
M2	45 to 50		
M3	40 to 45		
M4	< 40		
	f > 960 MHz		
M1	40 to 45		
M2	35 to 40		
M3	30 to 35		
M4	< 30		
Table 3-1 WD near-field categories as defined in ANSI C63.19-2011			

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## 4. SYSTEM SPECIFICATIONS

#### **ER3DV6 E-Field Probe Description**

Construction: One dipole parallel, two dipoles normal to probe axis

Built-in shielding against static charges

Calibration: In air from 100 MHz to 3.0 GHz

(absolute accuracy ±6.0%, k=2)

Frequency: 100 MHz to > 6 GHz;

Linearity: ± 0.2 dB (100 MHz to 3 GHz)

Directivity  $\pm 0.2$  dB in air (rotation around probe axis)

± 0.4 dB in air (rotation normal to probe axis)

Dynamic Range 2 V/m to > 1000 V/m

(M3 or better device readings fall well below diode

compression point)

Linearity: ± 0.2 dB

Dimensions Overall length: 330 mm (Tip: 16 mm)

Tip diameter: 8 mm (Body: 12 mm)

Distance from probe tip to dipole centers: 2.5 mm



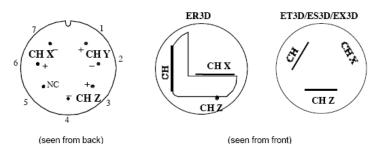
Figure 4-1 E-field Free-space Probe

#### **Probe Tip Description**

HAC field measurements take place in the close near field with high gradients. Increasing the measuring distance from the source will generally decrease the measured field values (in case of the validation dipole approx. 10% per mm).

The electric field probes have an irregular internal geometry because it is physically not possible to have the 3 orthogonal sensors situated with the same center. The effect of the different sensor centers is accounted for in the HAC uncertainty budget ("sensor displacement"). Their geometric center is at 2.5mm from the tip, and the element ends are 1.1mm closer to the tip.

#### Connector Plan



The antistatic shielding inside the probe is connected to the probe connector case.

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#### **Instrumentation Chain**

### **Equation 1**

## Conversion of Connector Voltage u, to E-Field E,

$$E_i = \sqrt{\frac{u_i + (u_i^2 \cdot CF)/(DCP)}{Norm_i \cdot ConvF}}$$

whereby

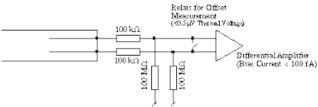
E<sub>i</sub>: electric field in V/m

 $u_i$ : voltage of channel i at the connector in  $\mu V$ Norm: sensitivity of channel i in  $\mu V/(V/m)^2$ enhancement factor in liquid (ConvF=1 for Air)

DCP: diode compression point in  $\mu V$ 

CF: signal crest factor (peak power/average power)

#### Conditions of Calibration



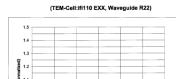
Please note

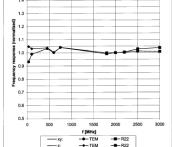
- a lower input impedance of the amplifier will result in different sensitivity factors Norm, and DCP
- · larger bias currents will cause higher offset

### **Probe Response to Frequency**

The E-field sensors have inherently a very flat frequency response. They are calibrated with a number of frequencies resulting in a common calibration factor, with the frequency behavior documented in the calibration certificate (See also below).

Frequency Response of E-Field





Uncertainty of Frequency Response of E-field: ± 6.3% (k=2

Figure 4-2 E-Field Probe Frequency Response

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#### **SPEAG Robotic System**

E-field measurements are performed using the DASY5 automated dosimetric assessment system. The DASY5 is made by Schmid & Partner Engineering AG (SPEAG) in Zurich, Switzerland and consists of high precision robotics system (Staubli), robot controller, Intel CORE i7 computer, near-field probe, probe alignment sensor, and the HAC phantom. The robot is a six-axis industrial robot performing precise movements to position the probe to the location (points) of maximum electromagnetic field (EMF).



**Figure 4-3** SPEAG Robotic System

## **System Hardware**

A cell controller system contains the power supply, robot controller, teach pendant (Joystick), and a remote control used to drive the robot motors. The PC consists of the computer with operating system and RF Measurement Software DASY5 v52.8 (with HAC Extension), A/D interface card, monitor, mouse, and keyboard. The Staubli Robot is connected to the cell controller to allow software manipulation of the robot. A data acquisition electronic (DAE) circuit that performs the signal amplification, signal multiplexing, AD-conversion, offset measurements, mechanical surface detection, collision detection, etc. is connected to the Electro-optical coupler (EOC). The EOC performs the conversion from the optical into digital electric signal of the DAE and transfers data to the PC plug-in card.

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#### **System Electronics**

The DAE consists of a highly sensitive electrometer-grade preamplifier with auto-zeroing, a channel and gain-switching multiplexer, a fast 16 bit AD-converter and a command decoder and control logic unit. Transmission to the PC-card is accomplished through an optical downlink for data and status information and an optical uplink for commands and clock lines. The mechanical probe mounting device includes two different sensor systems for frontal and sidewise probe contacts. They are also used for mechanical surface detection and probe collision detection. The robot uses its own controller with a built in VME-bus computer.

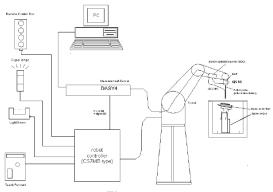


Figure 4-4 SPEAG Robotic System Diagram

#### **DASY5 Instrumentation Chain**

The first step of the evaluation is a linearization of the filtered input signal to account for the compression characteristics of the detector diode. The compensation depends on the input signal, the diode type and the DC-transmission factor from the diode to the evaluation electronics. If the exciting field is pulsed, the crest factor of the signal must be known to correctly compensate for peak power. The formula for each channel can be given as:

$$V_i = U_i + U_i^2 \cdot \frac{cf}{dcp_i}$$

with  $V_i$  = compensated signal of channel i (i = x, y, z)  $U_i$  = input signal of channel i (i = x, y, z) cf = crest factor of exciting field (DASY parameter)  $dcp_i$  = diode compression point (DASY parameter)

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From the compensated input signals the primary field data for each channel can be evaluated:

$$\mathbf{E} - \text{fieldprobes}: \qquad E_i = \sqrt{\frac{V_i}{Norm_i \cdot ConvF}}$$

with  $V_i$  = compensated signal of channel i  $Norm_i$  = sensor sensitivity of channel i (i = x, y, z)(i = x, v, z)

 $\mu V/(V/m)^2$  for E-field Probes

= sensitivity enhancement in solution

= electric field strength of channel i in V/m

The RSS value of the field components gives the total field strength (Hermitian magnitude):

$$E_{tot} = \sqrt{E_x^2 + E_y^2 + E_z^2}$$

The primary field data are used to calculate the derived field units.

The measurement/integration time per point, as specified by the system manufacturer is >500ms.

The signal response time is evaluated as the time required by the system to reach 90% of the expected final value after an on/off switch of the power source with an integration time of 500ms and a probe response time of <5 ms. In the current implementation, DASY5 waits longer than 100ms after having reached the grid point before starting a measurement, i.e., the response time uncertainty is negligible.

If the device under test does not emit a CW signal, the integration time applied to measure the electric field at a specific point may introduce additional uncertainties due to the discretization. The tolerances for the different systems had the worst-case of 2.6%.

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#### TEST PROCEDURE 5.

#### **RF EMISSIONS**

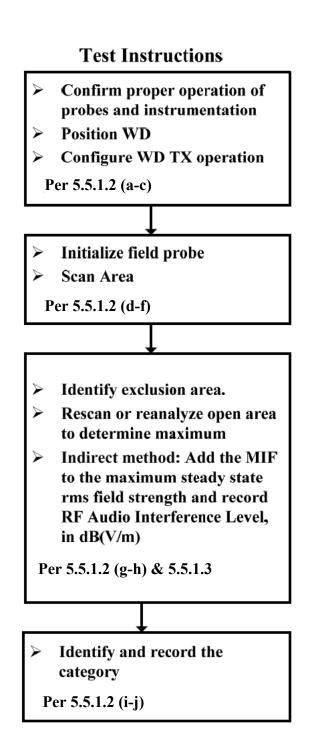


Figure 5-1 RF Emissions Flow Chart

	_			
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#### **Test Setup**

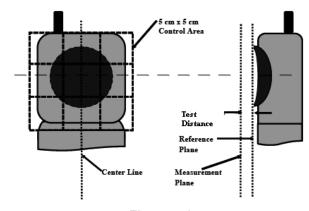


Figure 5-2
E-Field Emissions Test Setup Diagram (See Test Photographs for actual WD scan grid overlay)

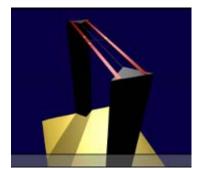


Figure 5-3 HAC Phantom

#### **RF Emissions Test Procedure:**

The following illustrate a typical RF emissions test scan over a wireless communications device:

- 1. Proper operation of the field probe, probe measurement system, other instrumentation, and the positioning system was confirmed.
- 2. WD is positioned in its intended test position, acoustic output point of the device perpendicular to the field probe.
- 3. The WD operation for maximum rated RF output power was configured and confirmed with the base station simulator, at the test channel and other normal operating parameters as intended for the test. The battery was ensured to be fully charged before each test.
- 4. The center sub-grid was centered over the center of the acoustic output (also audio band magnetic output, if applicable). The WD audio output was positioned tangent (as physically possible) to the measurement plane.
- 5. A surface calibration was performed before each setup change to ensure repeatable spacing and proper maintenance of the measurement plane using the HAC Phantom.
- 6. The measurement system measured the field strength at the reference location.
- 7. Measurements at 2mm or 5mm increments in the 5 x 5 cm region were performed at a distance 15 mm from the center point of the probe measurement element to the WD. A 360° rotation about the azimuth axis at the maximum interpolated position was measured. For the worst-case condition, the peak reading from this rotation was used in re-evaluating the HAC category.
- 8. The system performed a drift evaluation by measuring the field at the reference location. If the power drift deviated by more than 5%, the HAC test and drift measurements were repeated.

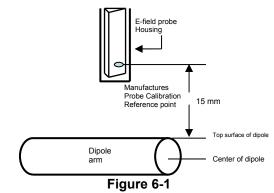
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## 6. SYSTEM CHECK

## I. System Check Parameters

The input signal was an un-modulated continuous wave. The following points were taken into consideration in performing this check:

- Average Input Power P = 100mW RMS (20dBm RMS) after adjustment for return loss
- The test fixture must meet the 2 wavelength separation criterion
- The proper measurement of the 15 mm probe to dipole separation, which is measured from top surface of the dipole to the calibration reference point of the sensor, defined by the probe manufacturer is shown in the following diagram:



Separation Distance from Dipole to Field Probe

RF power was recorded using both an average reading meter and a peak reading meter. Readings of the probe are provided by the measurement system.

To assure proper operation of the near-field measurement probe the input power to the dipole shall be commensurate with the full rated output power of the wireless device [e.g. - for a cellular phone wireless device the average peak antenna input power will be on the order of 100mW (20dBm) RMS] after adjustment for any mismatch.

## II. Validation Procedure

A dipole antenna meeting the requirements given in C63.19 was placed in the position normally occupied by the WD.

The length of the dipole was scanned, and the average peak value was recorded.

#### **Measurement of CW**

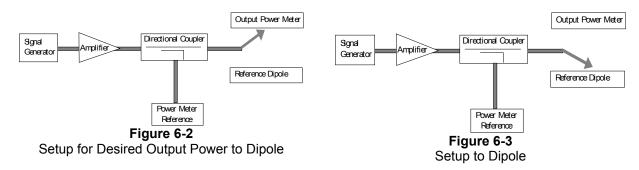
Using the near-field measurement system, scan the antenna over the radiating dipole and record the greatest field reading observed. Due to the nature of E-fields about free-space dipoles, the two E-field peaks measured over the dipole are averaged to compensate for non-parallelity of the setup (see manufacturer method on dipole calibration certificates, page 2). Field strength measurements shall be made only when the probe is stationary.

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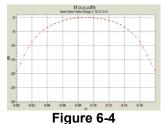
REV 3.1.M

RF power was recorded using both an average and a peak power reading meter.



Using this setup configuration, the signal generator was adjusted for the desired output power (100mW) at a specified frequency. The reference power from the coupled port of the directional coupler is recorded. Next, the output cable is connected to the reference dipole, as shown in Figure 6-3.

The input signal level was adjusted until the reference power from the coupled port of the directional coupler was the same as previously recorded, to compensate for the impedance mismatch between the output cable and the reference dipole. To assure proper operation of the near-field measurement probe the input power to the reference dipole was verified to the full rated output power of the wireless device. The dipole was secured in a holder in a manner to meet the 20 dB reflection. The near-field measurement probe was positioned over the dipole. The antenna was scanned over the appropriate sized area to cover the dipole from end to end. SPEAG uses 2D interpolation algorithms between the measured points. Please see below two dimensional plots showing that the interpolated values interpolate smoothly between 5mm steps for a free-space RF dipole:



2-D Raw Data from scan along dipole axis

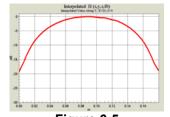


Figure 6-5
2-D Interpolated points from scan along dipole axis



2-D Raw Data from scan along transverse axis



2-D Interpolated points from scan along transverse axis

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# **III. System Check Results**

## **Validation Results**

Date	Frequency (MHz)	Probe S/N	DAE S/N	Dipole S/N	Input Power (dBm)	E-field Result (V/m)	Target Field (V/m)	% Deviation
11/6/2017	835	2353	859	1082	20.0	111.6	106.8	4.5%
11/6/2017	1880	2353	859	1064	20.0	95.3	89.6	6.4%
12/11/2017	2600	2353	859	1013	20.0	89.7	84.5	6.2%

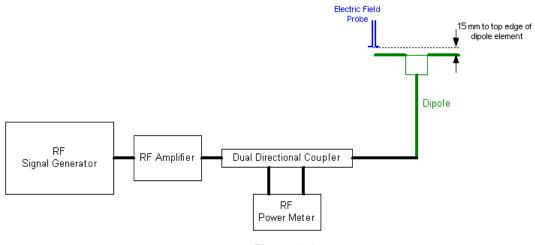


Figure 6-8 System Check Setup

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#### **MODULATION INTERFERENCE FACTOR** 7.

## I. Measuring Modulation Interference Factors

For any specific fixed and repeatable modulated signal, a modulation interference factor (MIF, expressed in dB) may be determined that relates its interference potential to its steady-state RMS signal level or average power level. This factor is a function only of the audio-frequency amplitude modulation characteristics of the signal and is the same for field-strength and conducted power measurements. The MIF is valid only for a specific repeatable audio-frequency amplitude modulation characteristic; any change in modulation characteristic requires determination and application of a new MIF.

The MIF may be determined using a radiated RF field or a conducted RF signal:

- a. Using RF illumination or conducted coupling, apply the specific modulated signal in question to the measurement system at a level within its confirmed operating dynamic range.
- b. Measure the steady-state RMS level at the output of the fast probe or sensor.
- c. Measure the steady-state average level at the weighting output.
- d. Without changing the square-law detector or weighting system, and using RF illumination or conducted coupling, substitute for the specific modulated signal a 1 kHz, 80% amplitude modulated carrier at the same frequency and adjust its strength until the level at the weighting output equals the step c) measurement.
- e. Without changing the carrier level from step d), remove the 1 kHz modulation and again measure the steady-state RMS level indicated at the output of the fast probe or sensor.
- The MIF for the specific modulation characteristic is provided by the ratio of the step e) measurement to the step b) measurement, expressed in dB (20 × log[(step e)/(step b)]).

The following procedure was used to measure the MIF using the SPEAG Audio Interference Analyzer (AIA), Type No: SE UMS 170 CB, Serial No.: 1010:

- 1. The device was placed into a simulated call using a base station simulator or set to transmit using test software for a given mode.
- 2. The device was then set to continuously transmit at maximum power.
- 3. Using a coupler if needed, the device output signal was connected to the RF In port of the AIA, which was connected to a desktop computer. Alternatively, a radiated RF signal may be used with the AIA's built-in antenna.
- 4. The MIF measurement procedure in the DASY software was run, and the resulting MIF value was recorded.
- Steps 1-4 were repeated for all CMRS air interfaces, frequency bands, and modulations.

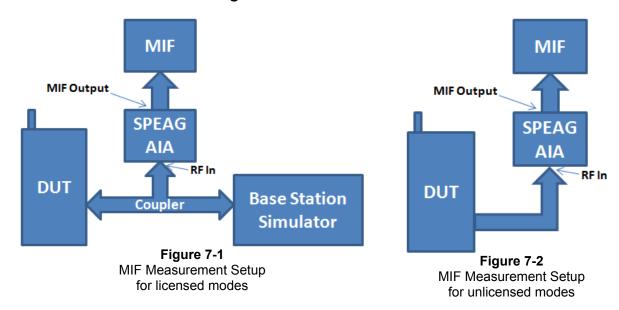
The modulation interference factors obtained were applied to readings taken of the actual wireless device in order to obtain an accurate audio interference level reading using the formula:

#### Audio Interference Level [dB(V/m)] = 20 \* log[Raw Field Value (V/m)] + MIF (dB)

Because the MIF value is output power independent, MIF values for a given mode should be constant across all devices; however, per C63.19-2011 §D.7, MIF values should be measured for each device being evaluated. The voice modes for this device have been investigated in this section of the report.

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# II. MIF Measurement Block Diagrams



## **III. Measured Modulation Interference Factors:**

**Table 7-1**CDMA Modulation Interference Factors<sup>1</sup>

	Cell					PCS		
Mode		908	22H	22H	22H	24E	24E	24E
		564	1013	384	777	25	600	1175
	RC1/SO3	3.07	3.03	3.04	3.06	3.06	3.04	3.06
CDMA	RC1/SO55	-19.66	-19.91	-19.68	-19.35	-19.80	-19.85	-19.88
	EvDO	-19.41	-19.57	-19.40	-19.05	-19.40	-19.43	-19.75

**Table 7-2**GSM Modulation Interference Factors<sup>1</sup>

			GSM850		GSM1900			
Mo	ode	128	190	251	51 512 661 8			
GSM	Voice	3.56	3.56	3.56	3.56	3.56	3.56	
GSIVI	EDGE	3.76	3.76	3.76	3.53	3.39	3.23	

<sup>&</sup>lt;sup>1</sup> Note: Measured MIF values may be lower than sample MIF values provided in ANSI C63.19-2011 Annex D.7 Table D.5 due to manufacturing variations for each device, however per Annex D.7, the sample MIF values of Table D.5 are not intended to substitute for measurements of actual devices under test and their respective operating modes.

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Table 7-3 UMTS Modulation Interference Factors<sup>1</sup>

I.V.	Mode		UMTS V		UMTS IV			UMTS II		
Wode		4132	4183	4233	1312	1412	1513	9262	9400	9538
	12.2 kbps RMC	-23.98	-23.74	-21.99	-24.39	-24.59	-24.50	-24.37	-23.84	-23.78
UMTS	12.2 kbps AMR	-15.66	-15.11	-15.18	-15.05	-15.10	-15.02	-15.07	-15.02	-15.07
	HSUPA Subtest1	-23.25	-23.40	-22.11	-22.00	-21.25	-23.81	-23.31	-23.68	-21.32

Table 7-4 LTE FDD Modulation Interference Factors<sup>1,2</sup>

LTE Band	Frequency [MHz]	Channel	Bandwidth [MHz]	Modulation	RB Size	RB Offset	MIF [dB]
71	680.5	133297	20	16QAM	1	0	-9.78
12	707.5	23095	10	16QAM	1	0	-9.80
13	782.0	23230	10	16QAM	1	0	-9.68
14	793.0	23330	10	16QAM	1	0	-9.83
26	831.5	26865	15	16QAM	1	0	-9.49
66	1745.0	132322	20	16QAM	1	0	-9.80
25	1882.5	26365	20	16QAM	1	0	-9.18
7	2535.0	21100	20	16QAM	1	0	-9.66
30	2310.0	27710	10	16QAM	1	0	-9.49
25	1882.5	26365	20	QPSK	1	0	-14.10
25	1882.5	26365	20	64QAM	1	0	-9.84
25	1882.5	26365	20	16QAM	1	50	-9.03
25	1882.5	26365	20	16QAM	1	99	-9.15
25	1882.5	26365	20	16QAM	50	0	-16.85
25	1882.5	26365	20	16QAM	100	0	-17.36
25	1882.5	26365	15	16QAM	1	36	-8.96
25	1882.5	26365	10	16QAM	1	25	-9.01
25	1882.5	26365	5	16QAM	1	12	-9.00
25	1882.5	26365	3	16QAM	1	7	-9.30
25	1882.5	26365	1.4	16QAM	1	2	-9.22
25	1857.5	26115	15	16QAM	1	36	-9.14
25	1907.5	26615	15	16QAM	1	36	-9.36

<sup>&</sup>lt;sup>1</sup> Note: Measured MIF values may be lower than sample MIF values provided in ANSI C63.19-2011 Annex D.7 Table D.5 due to manufacturing variations for each device, however per Annex D.7, the sample MIF values of Table D.5 are not intended to substitute for measurements of actual devices under test and their respective operating modes.

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<sup>&</sup>lt;sup>2</sup> Note: All FDD LTE bands were found to have substantially similar MIF values given similar RB, BW, and modulation configurations.

**Table 7-5**LTE TDD Power Class 3 Modulation Interference Factors<sup>1,2</sup>

	ETE TEET OWN State of Modulation Interference Lactors										
LTE Band	Frequency [MHz]	Channel	Bandwidth [MHz]	Modulation	RB Size	RB Offset	MIF [dB]				
41	2593.0	40620	20	16QAM	1	0	1.63				
41	2593.0	40620	20	QPSK	1	0	1.43				
41	2593.0	40620	20	64QAM	1	0	1.42				
41	2593.0	40620	20	16QAM	1	50	1.61				
41	2593.0	40620	20	16QAM	1	99	1.60				
41	2593.0	40620	20	16QAM	50	0	1.35				
41	2593.0	40620	20	16QAM	100	0	1.35				
41	2593.0	40620	15	16QAM	1	0	1.61				
41	2593.0	40620	10	16QAM	1	0	1.60				
41	2593.0	40620	5	16QAM	1	0	1.61				
41	2506.0	39750	20	16QAM	1	0	1.64				
41	2549.5	40185	20	16QAM	1	0	1.62				
41	2636.5	41055	20	16QAM	1	0	1.62				
41	2680.0	41490	20	16QAM	1	0	1.63				

**Table 7-6**LTE TDD Power Class 2 Modulation Interference Factors<sup>1,2</sup>

LTE Band	Frequency [MHz]	Channel	Bandwidth [MHz]	Modulation	RB Size	RB Offset	MIF [dB]
41	2593.0	40620	20	16QAM	1	0	1.65
41	2593.0	40620	20	QPSK	1	0	1.45
41	2593.0	40620	20	64QAM	1	0	1.47
41	2593.0	40620	20	16QAM	1	50	1.64
41	2593.0	40620	20	16QAM	1	99	1.62
41	2593.0	40620	20	16QAM	50	0	1.40
41	2593.0	40620	20	16QAM	100	0	1.40
41	2593.0	40620	15	16QAM	1	0	1.66
41	2593.0	40620	10	16QAM	1	0	1.64
41	2593.0	40620	5	16QAM	1	0	1.67
41	2506.0	39750	5	16QAM	1	0	1.66
41	2549.5	40185	5	16QAM	1	0	1.67
41	2636.5	41055	5	16QAM	1	0	1.65
41	2680.0	41490	5	16QAM	1	0	1.65

**Table 7-7**LTE TDD Uplink Carrier Aggregation Modulation Interference Factor<sup>1,3</sup>

				<u> </u>	<u> </u>	99	90.00				000				
		PCC						SCC							
Combinatio n	PCC Band	PCC Bandwidth [MHz]	PCC (UL/DL) Channel	PCC (UL/DL) Frequency [MHz]	Modulatio n	PCC UL# RB	PCC UL RB Offset	SCC Band	SCC Bandwidt h [MHz]	SCC (III /DI)	SCC (UL/DL) Frequency [MHz]	Modulati on	SCC UL# RB	SCC UL RB Offset	MIF [dB]
CA 41C	LTE B41	20	40185	2549.5	16QAM	1	0	LTE B41	20	39987	2529.7	16QAM	1	99	1.36

<sup>&</sup>lt;sup>1</sup> Note: Measured MIF values may be lower than sample MIF values provided in ANSI C63.19-2011 Annex D.7 Table D.5 due to manufacturing variations for each device, however per Annex D.7, the sample MIF values of Table D.5 are not intended to substitute for measurements of actual devices under test and their respective operating modes.

<sup>&</sup>lt;sup>3</sup> Note: The configuration for LTE TDD ULCA was determined from the worst case configuration from Table 7-5. While channel 39750 was the worst case channel, channel 40185 was evaluated to ensure worst case modulation was evaluated for PCC due to the CA combination constraint of CA\_41C.

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<sup>&</sup>lt;sup>2</sup> Note: LTE TDD MIFs for both Power Class 3 and Power Class 2 were taken using UL-DL Configuration 2. More information about the chosen UL-DL Configuration can be found in Section 10.

**Table 7-8**802.11b (2.4GHz, SISO) Modulation Interference Factors<sup>1,2</sup>

	802.11b MIF Measurements [dB]							
Mode		Data Rate [Mbps]						
	1 2 5.5 11							
802.11b	-10.31 -9.59 -7.33 -6.36							

Table 7-9

802.11g (2.4GHz, SISO) Modulation Interference Factors<sup>1,2</sup>

			802.1	1g MIF Mea	asurement	s [dB]					
Mode		Data Rate [Mbps]									
	6	6 9 12 18 24 36 48 54									
802.11g	7.60	7.60 -6.79 -6.26 -5.49 -5.14 -4.79 -4.84 -5.03									

**Table 7-10** 

802.11g (2.4GHz, MIMO) Modulation Interference Factors<sup>1,2</sup>

	802.11g MIF Measurements [dB]								
Mode		Data Rate [Mbps]							
	12	12 18 24 36 48 72 96 108							
802.11g	-7.53	-6.75	-6.23	-5.46	-5.11	-4.76	-4.82	-5.01	

**Table 7-11** 

802.11n (2.4GHz, SISO) Modulation Interference Factors<sup>1,2</sup>

		,	802.11n (2	.4GHz) MIF	Measurer	ments [dB]					
Mode	Data Rate [Mbps]										
	6.5	13	19.5	26	39	52	58.5	65			
802.11n	-7.49	-7.49     -6.20     -5.54     -5.11     -4.84     -4.85     -4.97     -5.08									

**Table 7-12** 

802.11n (2.4GHz, MIMO) Modulation Interference Factors<sup>1,2</sup>

		,	802.11n (2	.4GHz) MIF	Measurer	nents [dB]				
Mode	Data Rate [Mbps]									
	13	26	39	52	78	104	117	130		
802.11n	-7.44	-7.44         -6.15         -5.51         -5.07         -4.80         -4.81         -4.93         -5.05								

**Table 7-13** 

802.11a (5GHz, 20MHz BW, SISO) Modulation Interference Factors<sup>1,2</sup>

	002.114	1 (30112, 20		1a MIF Mea			201013				
Mode	Data Rate [Mbps]										
	6	9	12	18	24	36	48	54			
802.11a	-13.77	-13.77 -12.95 -12.64 -11.55 -11.41 -11.81 -12.18 -13.30									

<sup>&</sup>lt;sup>1</sup> Note: Measured MIF values may be lower than sample MIF values provided in ANSI C63.19-2011 Annex D.7 Table D.5 due to manufacturing variations for each device, however per Annex D.7, the sample MIF values of Table D.5 are not intended to substitute for measurements of actual devices under test and their respective operating modes.

<sup>&</sup>lt;sup>2</sup> Note: WIFI MIF values were found to be independent of the transmit channel.

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# **Table 7-14**802.11a (5GHz. 20MHz BW. MIMO) Modulation Interference Factors<sup>1,2</sup>

			802.1	1a MIF Mea	asurement	s [dB]					
Mode		Data Rate [Mbps]									
	12	18	24	36	48	72	92	108			
802.11a	-13.47	-13.47 -12.85 -12.06 -11.43 -11.80 -11.75 -12.39 -13.17									

#### **Table 7-15**

802 11n (5GHz 20MHz BW SISO) Modulation Interference Factors<sup>1,2</sup>

		20MI	Hz BW 802	.11n (5GHz	) MIF Mea	surements	[dB]				
Mode				Data Rate [Mbps]							
	6.5	13	19.5	26	39	52	58.5	65			
802.11n	40.44	-13.11 -11.96 -11.53 -11.31 -11.48 -11.79 -12.16 -12.50									

#### **Table 7-16**

802.11n (5GHz, 20MHz BW, MIMO) Modulation Interference Factors<sup>1,2</sup>

		20MI	Hz BW 802	.11n (5GHz	) MIF Mea	surements	[dB]				
Mode	de Data Rate [Mbps]										
	13	26	39	52	78	104	117	130			
802.11n	-13.17	-13.17 -12.04 -11.92 -11.31 -11.61 -12.10 -12.44 -12.91									

#### **Table 7-17**

802.11ac (5GHz, 20MHz BW, SISO) Modulation Interference Factors<sup>1,2</sup>

	002.					F Measure				
Mode	Data Rate [Mbps]									
	6.5	13	19.5	26	39	52	58.5	65	78	
802.11ac	-13.38	-12.10	-11.44	-11.26	-11.40	-11.78	-12.01	-12.26	-13.09	

## **Table 7-18**

802.11ac (5GHz, 20MHz BW, MIMO) Modulation Interference Factors<sup>1,2</sup>

		,	20MHz BW	802.11ac	(5GHz) MII	F Measure	ments [dB]					
Mode	Data Rate [Mbps]											
	13	26	39	52	78	104	117	130	156			
802.11ac	-12.49	-12.49 -11.63 -11.80 -12.25 -12.89 -13.95 -13.88 -14.16 -14.96										

#### **Table 7-19**

802.11n (5GHz, 40MHz BW, SISO) Modulation Interference Factors<sup>1,2</sup>

		40MF	Hz BW 802	,							
Mode		Data Rate [Mbps]									
	13.5	27	40.5	54	81	108	121.5	135			
802.11n	-11.69	11.69 -11.06 -11.48 -11.97 -13.32 -14.16 -14.63 -15.12									

<sup>&</sup>lt;sup>1</sup> Note: Measured MIF values may be lower than sample MIF values provided in ANSI C63.19-2011 Annex D.7 Table D.5 due to manufacturing variations for each device, however per Annex D.7, the sample MIF values of Table D.5 are not intended to substitute for measurements of actual devices under test and their respective operating modes.

<sup>&</sup>lt;sup>2</sup> Note: WIFI MIF values were found to be independent of the transmit channel.

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# **Table 7-20**802.11n (5GHz. 40MHz BW. MIMO) Modulation Interference Factors<sup>1,2</sup>

		40MI	lz BW 802	.11n (5GHz	) MIF Mea	surements	[dB]					
Mode				Data Rate [Mbps]								
	27	54	81	108	162	216	243	270				
802.11n	-11.26	-11.26 -11.03 -11.45 -11.62 -13.04 -13.91 -14.90 -15.13										

#### **Table 7-21**

802.11ac (5GHz, 40MHz BW, SISO) Modulation Interference Factors<sup>1,2</sup>

	40MHz BW 802.11ac (5GHz) MIF Measurements [dB]											
Mode		Data Rate [Mbps]										
	13.5	13.5 27 40.5 54 81 108 121.5 135 180										
802.11ac	-11.65	-10.86	-11.33	-11.87	-13.15	-14.08	-14.37	-14.66	-15.42			

#### **Table 7-22**

802.11ac (5GHz. 40MHz BW. MIMO) Modulation Interference Factors<sup>1,2</sup>

		40MHz BW 802.11ac (5GHz) MIF Measurements [dB]										
Mode		Data Rate [Mbps]										
	27         54         81         108         162         216         243         270         360											
		.65 -11.86 -12.79 -13.79 -14.89 -16.27 -16.63 -16.43 -16.66										

#### **Table 7-23**

802.11ac (5GHz, 80MHz BW, SISO) Modulation Interference Factors<sup>1,2</sup>

	s [dB]									
Mode		Data Rate [Mbps]								
	29.3 58.5 87.8 117 175.5 234 263.3 292.5 351									390
802.11ac	-11.32	-12.46	-13.53	-14.31	-15.44	-16.63	-16.62	-16.59	-17.01	-17.24

#### **Table 7-24**

802.11ac (5GHz, 80MHz BW, MIMO) Modulation Interference Factors<sup>1,2</sup>

80MHz BW 802.11ac (5GHz) MIF Measurements [dB]											
Mode		Data Rate [Mbps]									
	58.5	117	175.5	234	351	468	526.5	585	702	780	
802.11ac	-12.30	-14.13	-14.91	-16.20	-16.63	-17.37	-17.32	-17.91	-17.93	-18.47	

<sup>&</sup>lt;sup>1</sup> Note: Measured MIF values may be lower than sample MIF values provided in ANSI C63.19-2011 Annex D.7 Table D.5 due to manufacturing variations for each device, however per Annex D.7, the sample MIF values of Table D.5 are not intended to substitute for measurements of actual devices under test and their respective operating modes.

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<sup>&</sup>lt;sup>2</sup> Note: WIFI MIF values were found to be independent of the transmit channel.

**Table 7-25**Simultaneous 2.4GHz and 5GHz WIFI Modulation Interference Factors<sup>1,2,3</sup>

#	5 GHz	z WIFI	2.4 GH	lz WIFI	Measured MIF
Tx	Ant1	Bm] Ant2	Ant1	3m] Ant2	(dB)
2	х	-	-	х	-5.33
2	-	х	х	-	-6.32
2	х	•	х	-	-6.18
2	1	х	1	х	-5.95
3	х	х	х	-	-6.77
3	х	х	1	х	-6.41
3	х	-	х	х	-5.10
3	-	х	х	х	-6.05
4	х	х	х	х	-6.35

<sup>&</sup>lt;sup>1</sup> Note: Measured MIF values may be lower than sample MIF values provided in ANSI C63.19-2011 Annex D.7 Table D.5 due to manufacturing variations for each device, however per Annex D.7, the sample MIF values of Table D.5 are not intended to substitute for measurements of actual devices under test and their respective operating modes.

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<sup>&</sup>lt;sup>2</sup> Note: WIFI MIF values were found to be independent of the transmit channel.

<sup>&</sup>lt;sup>3</sup> Note: The configuration for each scenario (e.g. bandwidth, data rate, etc.) was determined using the worst-case configuration from SISO and MIMO MIF measurements.

## 8. RF CONDUCTED POWER MEASUREMENTS

## I. Procedures Used to Establish RF Signal for HAC Testing

The handset was placed into a simulated call using a base station simulator in a shielded chamber. Such test signals offer a consistent means for testing HAC and are recommended for evaluating HAC. Measurements were taken with a fully charged battery. In order to verify that the device was tested and maintained at full power, this was configured with the base station simulator.

#### II. HAC Measurement Conditions

#### **Output Power Verification**

Maximum output power is verified on the High, Middle and Low channels for all applicable air interfaces. See Table 8-1 for air interface specific settings of transmit power parameters.

Table 8-1
Power Control Parameters and Settings by Air Interface

Parameter Name:	Parameter Set To:
Power Control Bits	"All Up"
PCL	GSM850: "5"; GSM1900: "0"
TPC	"All 1's"
TPC	"Max Power"
PLS	Mfr Specified
	Power Control Bits PCL TPC TPC

## III. Setup Used to Measure RF Conducted Powers

Power measurements for licensed modes were performed using a base station simulator under digital average power. Power measurements for unlicensed modes were performed using a power meter and power sensor.

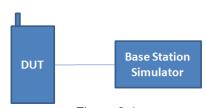


Figure 8-1
Power Measurement Setup for licensed modes

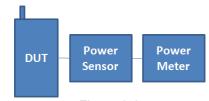


Figure 8-2
Power Measurement Setup for unlicensed modes

#### IV. CDMA Conducted Powers

Band	Channel	Rule Part	Frequency	SO2 [dBm]	SO2 [dBm]	SO2 [dBm]	SO55 [dBm]	SO55 [dBm]	SO75 [dBm]	SO9 [dBm]	SO9 [dBm]	SO3 [dBm]	SO3 [dBm]	SO3 [dBm]	1x EvDO Rev. A [dBm]
	F-RC		MHz	RC1	RC3	RC4	RC1	RC3	RC11	RC2	RC5	RC1	RC3	RC4	(RETAP)
Cellular	564	90S	820.1	25.10	25.07	25.07	25.12	25.08	25.12	25.11	25.08	25.06	25.08	25.07	25.15
	1013	22H	824.7	24.56	24.51	24.54	24.57	24.52	24.57	24.56	24.53	24.54	24.51	24.53	24.55
Cellular	384	22H	836.52	24.70	24.66	24.65	24.71	24.66	24.70	24.71	24.65	24.69	24.64	24.67	24.68
	777	22H	848.31	24.74	24.69	24.70	24.75	24.69	24.74	24.75	24.71	24.73	24.70	24.71	24.71
	25	24E	1851.25	24.17	24.16	24.18	24.19	24.17	24.18	24.19	24.14	24.17	24.15	24.16	24.22
PCS	600	24E	1880	24.28	24.25	24.26	24.28	24.27	24.26	24.26	24.23	24.30	24.25	24.24	24.27
	1175	24E	1908.75	24.08	24.12	24.13	24.15	24.11	24.17	24.14	24.13	24.22	24.14	24.18	24.07

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## V. GSM Conducted Powers

Band	Channel	GSM [dBm] CS (1 Slot)	EDGE [dBm] 1 Tx Slot	
	128	32.86	26.66	
GSM 850	190	32.81	26.60	
	251	32.94	26.56	
	512	29.65	25.54	
GSM 1900	661	29.72	25.74	
	810	29.68	25.36	

# **VI. UMTS Conducted Powers**

Mode	3GPP 34.121 Subtest	Cellular Band [dBm]			AW	S Band [d	Bm]	PCS Band [dBm]			
	Sublest	4132	4183	4233	1312	1412	1513	9262	9400	9538	
WCDMA	12.2 kbps RMC	24.38	24.49	24.46	24.42	24.54	24.61	24.89	24.99	24.79	
WCDIVIA	12.2 kbps AMR	24.40	24.48	24.47	24.40	24.51	24.59	24.84	24.97	24.73	
HSUPA	Subtest 1	23.40	23.57	23.56	22.95	23.06	23.06	23.17	23.29	23.05	

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## VII. LTE Conducted Powers

## a. LTE Band 71

Table 8-2
LTE Band 71 (680.5MHz) Conducted Powers – 20MHz Bandwidth

<u> </u>	1 1 (000	.01111112/	<del>oonaactea i</del>	OWO:0 20:0	II IZ Ballawia
			LTE Band 71 20 MHz Bandwidth		
Modulation	RB Size	RB Offset	Mid Channel 133297 (680.5 MHz)	MPR Allowed per	MPR [dB]
			Conducted Power [dBm]	3GPP [db]	
	1	0	24.52		0
	1	50	24.59	0	0
	1	99	24.47		0
QPSK	50	0	23.58		1
	50	25	23.61	0-1	1
	50	50	23.47	0-1	1
	100	0	23.51		1
	1	0	23.88		1
	1	50	23.90	0-1	1
	1	99	23.83		1
16QAM	50	0	22.70		2
	50	25	22.67	0-2	2
	50	50	22.55	0-2	2
	100	0	22.62		2
	1	0	23.00		2
	1	50	22.89	0-2	2
	1	99	22.72		2
64QAM	50	0	21.92		3
	50	25	21.85	0-3	3
	50	50	21.68		3
	100	0	21.78		3

Note: Since LTE Band 71 at 20MHz bandwidth does not support 3 non-overlapping channels, conducted power measurements were made only on the middle channel.

Table 8-3 LTE Band 71 (680.5MHz) Conducted Powers – 15MHz Bandwidth

			LTE Band 71 15 MHz Bandwidth		
			Mid Channel		
Modulation	RB Size	Size RB Offset	133297 (680.5 MHz)	MPR Allowed per 3GPP [dB]	MPR [dB]
			Conducted Power [dBm]		
	1	0	24.43		0
	1	36	24.45	0	0
	1	74	24.34		0
	36	0	23.55		1
	36	18	23.51	0-1	1
	36	37	23.37	0-1	1
	75	0	23.44		1
	1	0	23.63		1
	1	36	23.61	0-1	1
	1	74	23.50		1
16QAM	36	0	22.58		2
	36	18	22.54	0-2	2
	36	37	22.41	0-2	2
	75	0	22.52		2
	1	0	22.72		2
	1	36	22.66	0-2	2
	1	74	22.54		2
64QAM	36	0	21.65		3
	36	18	21.61	0-3	3
	36	37	21.45	0-3	3
	75	0	21.51		3

Note: Since LTE Band 71 at 15MHz bandwidth does not support 3 non-overlapping channels, conducted power measurements were made only on the middle channel.

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Table 8-4
LTE Band 71 (680.5MHz) Conducted Powers – 10MHz Bandwidth

				LTE Band 71 10 MHz Bandwidth			
Madulatian DD	RB Size RB Offset	Low Channel 133172	Mid Channel 133297	High Channel	MPR Allowed per	MDD (4D)	
Modulation	KB SIZE	RB Oliset	(668.0 MHz)	(680.5 MHz) Conducted Power [dBm	(693.0 MHz)	3GPP [dB]	MPR [dB]
	1	0	24.44	24.36	24.39		0
	1	25	24.41	24.38	24.28	0	0
	1	49	24.33	24.34	24.27		0
QPSK	25	0	23.59	23.49	23.35	0-1	1
	25	12	23.53	23.40	23.31		1
	25	25	23.40	23.37	23.21		1
	50	0	23.49	23.39	23.28		1
	1	0	23.51	23.51	23.52		1
	1	25	23.62	23.60	23.40	0-1	1
	1	49	23.44	23.59	23.43		1
16QAM	25	0	22.62	22.55	22.40		2
	25	12	22.60	22.47	22.41	0-2	2
	25	25	22.46	22.40	22.28	0-2	2
	50	0	22.57	22.52	22.39		2
	1	0	22.69	22.57	22.61		2
	1	25	22.67	22.66	22.52	0-2	2
	1	49	22.57	22.63	22.50		2
64QAM	25	0	21.63	21.55	21.45		3
	25	12	21.62	21.54	21.42	0-3	3
	25	25	21.48	21.44	21.30	0-3	3
	50	0	21.59	21.53	21.38	1	3

Table 8-5
LTE Band 71 (680.5MHz) Conducted Powers – 5MHz Bandwidth

		LIL Buile	(000:0::::12	LTE Band 71	OWOIG CHILL	- Danamati	
				5 MHz Bandwidth			
			Low Channel	Mid Channel	High Channel		
Modulation	RB Size	RB Offset	133147 (665.5 MHz)	133297 (680.5 MHz)	133447 (695.5 MHz)	MPR Allowed per 3GPP [dB]	MPR [dB]
			d	Conducted Power [dBm	n]		
	1	0	24.37	24.44	24.31		0
	1	12	24.38	24.37	24.32	0	0
	1	24	24.42	24.33	24.25		0
QPSK	12	0	23.46	23.45	23.26		1
	12	6	23.45	23.42	23.37	0-1	1
	12	13	23.49	23.36	23.33		1
	25	0	23.50	23.39	23.24		1
	1	0	23.49	23.56	23.39		1
	1	12	23.57	23.54	23.46	0-1	1
	1	24	23.61	23.48	23.43		1
16QAM	12	0	22.51	22.46	22.34		2
	12	6	22.52	22.52	22.45	0-2	2
	12	13	22.59	22.43	22.38	0-2	2
	25	0	22.58	22.45	22.33		2
	1	0	22.57	22.68	22.56		2
	1	12	22.65	22.64	22.60	0-2	2
	1	24	22.67	22.56	22.57	1	2
64QAM	12	0	21.56	21.56	21.40		3
	12	6	21.55	21.57	21.49	0-3	3
	12	13	21.59	21.47	21.42	]	3
	25	0	21.61	21.50	21.32	1	3

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## b. LTE Band 12

Table 8-6 LTE Band 12 (707.5MHz) Conducted Powers - 10MHz Bandwidth

	(		LTE Band 12		
			10 MHz Bandwidth		
			Mid Channel		
Modulation	RB Size	RB Offset	23095 (707.5 MHz)	MPR Allowed per 3GPP [dB]	MPR [dB]
			Conducted Power		
			[dBm]		
	1	0	24.13		0
	1	25	24.26	0	0
	1	49	24.12		0
QPSK	25	0	23.33		1
25	25	12	23.35	0-1	1
	25	25	23.31	0-1	1
	50	0	23.30		1
	1	0	23.43		1
	1	25	23.50	0-1	1
	1	49	23.46		1
16QAM	25	0	22.43		2
	25	12	22.39	0-2	2
	25	25	22.38	0-2	2
	50	0	22.41		2
	1	0	22.39		2
	1	25	22.49	0-2	2
	1	49	22.46		2
64QAM	25	0	21.46		3
	25	12	21.48	0.0	3
	25	25	21.42	0-3	3
	50	0	21.44		3

Note: Since LTE Band 12 at 10MHz bandwidth does not support 3 non-overlapping channels, conducted power measurements were made only on the middle channel.

Table 8-7 LTE Band 12 (707.5MHz) Conducted Powers - 5MHz Bandwidth

				LTE Band 12 5 MHz Bandwidth			
			Low Channel	Mid Channel	High Channel		
Modulation	RB Size	RB Offset	23035 (701.5 MHz)	23095 (707.5 MHz)	23155 (713.5 MHz)	MPR Allowed per 3GPP [dB]	MPR [dB]
			C	Conducted Power [dBm	1]		
	1	0	24.26	24.26	24.19		0
	1	12	24.22	24.25	23.97	0	0
	1	24	24.26	24.23	24.24		0
QPSK	12	0	23.30	23.35	23.07		1
	12	6	23.28	23.36	23.10	0-1	1
	12	13	23.35	23.33	23.25	0-1	1
	25	0	23.36	23.32	23.18		1
	1	0	23.43	23.47	23.32		1
	1	12	23.37	23.46	23.28	0-1	1
	1	24	23.46	23.41	23.36		1
16QAM	12	0	22.39	22.38	22.17		2
	12	6	22.36	22.42	22.16	0-2	2
	12	13	22.43	22.36	22.32	0-2	2
	25	0	22.42	22.41	22.25		2
	1	0	22.52	22.54	22.44		2
	1	12	22.40	22.51	22.18	0-2	2
	1	24	22.53	22.49	22.47		2
64QAM	12	0	21.45	21.47	21.29		3
	12	6	21.44	21.51	21.28	0-3	3
	12	13	21.51	21.43	21.40	0-3	3
	25	0	21.46	21.40	21.27		3

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Table 8-8
LTE Band 12 (707.5MHz) Conducted Powers – 3MHz Bandwidth

		LIL Bunc	12 (1011011112	LTE Band 12	011010 0111112	- Danawiatii	
		1	Low Channel	3 MHz Bandwidth Mid Channel	High Channel	т т	
Modulation	RB Size	RB Offset	23025 (700.5 MHz)	23095 (707.5 MHz)	23165 (714.5 MHz)	MPR Allowed per 3GPP [dB]	MPR [dB]
			(	Conducted Power [dBn	1]		
	1	0	24.31	24.31	24.00		0
	1	7	24.37	24.40	24.25	0	0
	1	14	24.25	24.28	24.27	1 [	0
QPSK	8	0	23.35	23.34	23.11		1
	8	4	23.36	23.36	23.28	1 01	1
	8	7	23.29	23.31	23.35	0-1	1
	15	0	23.34	23.35	23.26		1
	1	0	23.43	23.48	23.15	0-1	1
	1	7	23.52	23.58	23.44		1
	1	14	23.40	23.45	23.41		1
16QAM	8	0	22.42	22.45	22.26		2
	8	4	22.43	22.47	22.29	0-2	2
	8	7	22.36	22.43	22.36	0-2	2
	15	0	22.44	22.45	22.35	1	2
	1	0	22.54	22.55	22.25		2
	1	7	22.62	22.65	22.45	0-2	2
	1	14	22.51	22.54	22.52	1	2
64QAM	8	0	21.47	21.48	21.22		3
	8	4	21.48	21.51	21.34	1	3
	8	7	21.40	21.48	21.48	0-3	3
	15	0	21.44	21.46	21.36	1	3

Table 8-9
LTE Band 12 (707.5MHz) Conducted Powers – 1.4MHz Bandwidth

			12 (10110111112)	LTE Band 12	711010 11111111		
				1.4 MHz Bandwidth			
			Low Channel	Mid Channel	High Channel		
Modulation	RB Size	RB Offset	23017 (699.7 MHz)	23095 (707.5 MHz)	23173 (715.3 MHz)	MPR Allowed per 3GPP [dB]	MPR [dB]
			(	Conducted Power [dBn	n]		
	1	0	24.24	24.19	24.07		0
	1	2	24.31	24.28	24.25		0
	1	5	24.21	24.19	24.17		0
QPSK	3	0	24.22	24.24	24.16	]	0
	3	2	24.27	24.26	24.24		0
	3	3	24.21	24.25	24.20	0-1	0
	6	0	23.26	23.26	23.25		1
	1	0	23.36	23.40	23.29		1
	1	2	23.43	23.47	23.38		1
	1	5	23.37	23.38	23.32	0-1	1
16QAM	3	0	23.35	23.39	23.27	0-1	1
	3	2	23.36	23.42	23.35		1
	3	3	23.32	23.36	23.31		1
	6	0	22.38	22.39	22.36	0-2	2
	1	0	22.46	22.47	22.37		2
	1	2	22.52	22.54	22.49		2
ļ	1	5	22.43	22.46	22.42	1 <u>,</u>	2
64QAM	3	0	22.45	22.48	22.39	0-2	2
ļ	3	2	22.48	22.50	22.46		2
ļ	3	3	22.43	22.45	22.44	1	2
	6	0	21.38	21.37	21.36	0-3	3

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## c. LTE Band 13

Table 8-10 LTE Band 13 (780.0MHz) Conducted Powers – 10MHz Bandwidth

			LTE Band 13 10 MHz Bandwidth		
			Mid Channel		
Modulation	RB Size	RB Offset	23230 (782.0 MHz)	MPR Allowed per 3GPP [dB]	MPR [dB]
			Conducted Power [dBm]	JOFF [UD]	
	1	0	24.58		0
	1	25	24.49	0	0
	1	49	24.43		0
QPSK	25	0	23.59		1
	25	12	23.69	0-1	1
	25	25	23.62	0-1	1
	50	0	23.54		1
	1	0	23.77		1
	1	25	23.79	0-1	1
	1	49	23.84		1
16QAM	25	0	22.61		2
	25	12	22.73	0-2	2
	25	25	22.70	0-2	2
	50	0	22.58		2
	1	0	22.78		2
	1	25	22.80	0-2	2
	1	49	22.66		2
64QAM	25	0	21.63		3
	25	12	21.76	0-3	3
	25	25	21.72	0-3	3
	50	0	21.62		3

Table 8-11
LTE Band 13 (780.0MHz) Conducted Powers – 5MHz Bandwidth

			LTE Band 13 5 MHz Bandwidth		
			Mid Channel	MPR Allowed per	
Modulation	RB Size	RB Offset	(782.0 MHz)	3GPP [dB]	MPR [dB]
			Conducted Power		
			[dBm]		
	1	0	24.57		0
	1	12	24.58	0	0
	1	24	24.26		0
QPSK	12	0	23.68		1
	12	6	23.73	0-1	1
	12	13	23.70	0-1	1
	25	0	23.74		1
	1	0	23.73		1
	1	12	23.70	0-1	1
	1	24	23.74		1
16QAM	12	0	22.65		2
	12	6	22.67	0-2	2
	12	13	22.66	0-2	2
	25	0	22.68		2
	1	0	22.86		2
	1	12	22.78	0-2	2
	1	24	22.79		2
64QAM	12	0	21.78		3
	12	6	21.84	0-3	3
	12	13	21.85	0-3	3
	25	0	21.80		3

Note: Since LTE Band 13 at 5MHz bandwidth does not support 3 non-overlapping channels, conducted power measurements were made only on the middle channel.

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# d. LTE Band 14

Table 8-12 LTE Band 14 (793.0MHz) Conducted Powers – 10MHz Bandwidth

			LTE Band 14 10 MHz Bandwidth		
			Mid Channel 23330	MDD Allowed nor	
Modulation	RB Size	RB Offset	(793.0 MHz)	MPR Allowed per 3GPP [dB]	MPR [dB]
			Conducted Power [dBm]	557. [45]	
	1	0	24.44		0
	1	25	24.57	0	0
	1	49	24.45		0
QPSK	25	0	23.66		1
	25	12	23.62	0-1	1
	25	25	23.54	0-1	1
	50	0	23.60		1
	1	0	23.73		1
	1	25	23.89	0-1	1
	1	49	23.80		1
16QAM	25	0	22.71		2
	25	12	22.73	0-2	2
	25	25	22.63	0-2	2
	50	0	22.65		2
	1	0	22.71		2
	1	25	22.81	0-2	2
	1	49	22.67		2
64QAM	25	0	21.76		3
	25	12	21.69	0-3	3
	25	25	21.60	0-3	3
	50	0	21.72		3

Table 8-13
LTE Band 14 (793.0MHz) Conducted Powers – 5MHz Bandwidth

	LTE Band 14 5 MHz Bandwidth										
Madelatian	DD 01	DD Offers	Mid Channel	MPR Allowed per	MDD (4D)						
Modulation	RB Size	RB Offset	(793.0 MHz)	3GPP [dB]	MPR [dB]						
			Conducted Power								
	1	0	[dBm] 24.54		0						
	1	12	24.60	0	0						
	1	24	24.55	· ·	0						
QPSK	12	0	24.55		1						
QPSK	12	6	23.68		1						
	12	13	23.62	0-1	1						
	25	0	23.62		1						
	25 1	0	23.66		1						
	1	12	23.70	0-1	1						
	1	24	23.79	U-1	1						
16QAM	12	0	23.71		2						
IOQAIVI	12	6	22.72		2						
	12	13	22.73	0-2	2						
	25	0	22.70		2						
	25 1	0	22.71		2						
	1	12	22.79	0-2	2						
	1	24	22.87	U-Z	2						
64QAM	12	0	21.82		3						
04QAIVI	12	6	21.80		3						
	12			0-3	3						
	25	13 0	21.77 21.73		3						
	∠5	U	21.73		3						

Note: Since LTE Band 14 at 5MHz bandwidth does not support 3 non-overlapping channels, conducted power measurements were made only on the middle channel.

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## e. LTE Band 26

Table 8-14

<u>LTE Band 26 (836.5MHz) Conducted Powers – 15MHz Bandwidth</u>

	_0 (000		LTE Band 26 (C-II)		= 66
			LTE Band 26 (Cell) 15 MHz Bandwidth		
			Mid Channel		
Modulation	RB Size	RB Offset	26865 (831.5 MHz)	MPR Allowed per 3GPP [dB]	MPR [dB]
			Conducted Power		
			[dBm]		
	1	0	24.45		0
	1	36	24.48	0	0
	1	74	24.27		0
QPSK	36	0	23.53		1
	36	18	23.58	0-1	1
	36	37	23.51		1
	75	0	23.54		1
	1	0	23.81		1
	1	36	23.78	0-1	1
	1	74	23.56		1
16QAM	36	0	22.63		2
	36	18	22.66	0-2	2
	36	37	22.56	0-2	2
	75	0	22.61		2
	1	0	22.75		2
	1	36	22.69	0-2	2
	1	74	22.48		2
64QAM	36	0	21.66		3
	36	18	21.72	0-3	3
	36	37	21.59	0-3	3
	75	0	21.61		3

Note: Since LTE Band 26 at 15MHz bandwidth does not support 3 non-overlapping channels, conducted power measurements were made only on the middle channel.

Table 8-15 LTE Band 26 (831.5MHz) Conducted Powers – 10MHz Bandwidth

	_			LTE Band 26 (Cell)  10 MHz Bandwidth			
Modulation	RB Size	RB Offset	Low Channel 26740 (819.0 MHz)	Mid Channel  26865 (831.5 MHz)  Conducted Power [dBm	High Channel 26990 (844.0 MHz)	MPR Allowed per 3GPP [dB]	MPR [dB]
	1	0	24.25	24.31	24.33		0
	1	25	24.24	24.37	24.37	0	0
	1	49	24.26	24.28	23.82	1	0
QPSK	25	0	23.30	23.35	23.36		1
	25	12	23.40	23.30	23.30	0-1	1
	25	25	23.36	23.38	23.34	0-1	1
	50	0	23.38	23.27	23.28		1
	1	0	23.42	23.51	23.55		1
	1	25	23.44	23.58	23.60	0-1	1
	1	49	23.46	23.47	22.78		1
16QAM	25	0	22.40	22.43	22.43		2
	25	12	22.49	22.40	22.40	0-2	2
	25	25	22.41	22.42	22.42	0-2	2
	50	0	22.47	22.37	22.36		2
	1	0	22.45	22.59	22.62		2
	1	25	22.50	22.63	22.65	0-2	2
	1	49	22.51	22.55	22.07	1	2
64QAM	25	0	21.42	21.43	21.43		3
	25	12	21.50	21.42	21.41	0-3	3
	25	25	21.44	21.44	21.44	0-3	3
	50	0	21.49	21.39	21.40		3

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Table 8-16
LTE Band 26 (831.5MHz) Conducted Powers – 5MHz Bandwidth

				LTE Band 26 (Cell) 5 MHz Bandwidth			
Modulation F	RB Size	RB Offset	Low Channel 26715 (816.5 MHz)	Mid Channel 26865 (831.5 MHz)	High Channel 27015 (846.5 MHz)	MPR Allowed per 3GPP [dB]	MPR [dB]
				Conducted Power [dBm	1]		
	1	0	24.14	24.21	24.27		0
	1	12	24.21	24.32	24.22	0	0
	1	24	24.16	24.26	23.66		0
QPSK	12	0	23.26	23.24	23.38		1
	12	6	23.28	23.27	23.37	0-1	1
	12	13	23.23	23.28	23.30	0-1	1
	25	0	23.24	23.18	23.32		1
	1	0	23.53	23.53	23.55		1
	1	12	23.56	23.65	23.45	0-1	1
	1	24	23.49	23.57	22.67	]	1
16QAM	12	0	22.41	22.37	22.47		2
	12	6	22.41	22.35	22.44	0-2	2
	12	13	22.31	22.42	22.37	0-2	2
	25	0	22.33	22.30	22.43	]	2
	1	0	22.38	22.49	22.60		2
	1	12	22.47	22.57	22.57	0-2	2
	1	24	22.39	22.52	21.76	] [	2
64QAM	12	0	21.43	21.36	21.52		3
	12	6	21.40	21.38	21.50	0-3	3
	12	13	21.37	21.42	21.43	0-3	3
	25	0	21.34	21.31	21.44	1	3

Table 8-17 LTE Band 26 (831.5MHz) Conducted Powers – 3MHz Bandwidth

				LTE Band 26 (Cell)			
			Low Channel	3 MHz Bandwidth Mid Channel	High Channel	T I	
Modulation	RB Size	RB Offset	26705 (815.5 MHz)	26865 (831.5 MHz)	27025 (847.5 MHz)	MPR Allowed per 3GPP [dB]	MPR [dB]
			(	Conducted Power [dBm	]		
	1	0	24.17	24.17	24.22		0
	1	7	24.21	24.39	24.28	0	0
	1	14	24.20	24.26	23.54		0
QPSK	8	0	23.18	23.19	23.31		1
	8	4	23.19	23.31	23.34	0-1	1
	8	7	23.23	23.29	22.95	0-1	1
	15	0	23.27	23.19	23.31		1
	1	0	23.46	23.51	23.40		1
	1	7	23.55	23.74	23.44	0-1	1
	1	14	23.52	23.62	22.68		1
16QAM	8	0	22.27	22.34	22.42		2
	8	4	22.29	22.46	22.43	0-2	2
	8	7	22.34	22.39	22.12	0-2	2
	15	0	22.32	22.24	22.38		2
	1	0	22.38	22.42	22.49		2
	1	7	22.47	22.65	22.53	0-2	2
	1	14	22.42	22.50	21.88		2
64QAM	8	0	21.31	21.36	21.46		3
	8	4	21.33	21.45	21.45	0-3	3
	8	7	21.37	21.42	21.24	0-3	3
	15	0	21.36	21.31	21.42	1	3

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Table 8-18
LTE Band 26 (831.5MHz) Conducted Powers – 1.4MHz Bandwidth

LTE Band 26 (Cell) 1.4 MHz Bandwidth							
Modulation	RB Size	RB Offset	Low Channel 26697 (814.7 MHz)	Mid Channel 26865 (831.5 MHz) Conducted Power [dBn	High Channel 27033 (848.3 MHz)	MPR Allowed per 3GPP [dB]	MPR [dB]
	1	0	24.06	24.18	24.22		0
	1	2	24.13	24.27	24.29	1	0
QPSK	1	5	24.03	24.18	23.86	0	0
	3	0	24.09	24.25	24.25		0
	3	2	24.11	24.27	24.20		0
	3	3	24.07	24.23	23.96		0
	6	0	23.11	23.24	23.23	0-1	1
	1	0	23.41	23.56	23.41	0-1	1
	1	2	23.47	23.63	23.44		1
	1	5	23.40	23.54	23.08		1
16QAM 3	3	0	23.31	23.48	23.37		1
	3	2	23.34	23.49	23.38		1
	3	3	23.30	23.47	23.15		1
	6	0	22.26	22.38	22.36	0-2	2
64QAM	1	0	22.37	22.54	22.49	0-2	2
	1	2	22.38	22.55	22.52		2
	1	5	22.28	22.43	22.31		2
	3	0	22.32	22.47	22.48		2
	3	2	22.34	22.51	22.49		2
	3	3	22.30	22.45	22.41		2
	6	0	21.21	21.32	21.34	0-3	3

## f. LTE Band 66

Table 8-19 LTE Band 66 (1745.0MHz) Conducted Powers – 20MHz Bandwidth

LTE Band 66 (AWS) 20 MHz Bandwidth							
			Low Channel	Mid Channel	High Channel		
Modulation	RB Size	RB Offset	132072 (1720.0 MHz)	132322 (1745.0 MHz)	132572 (1770.0 MHz)	MPR Allowed per 3GPP [dB]	MPR [dB]
			(	Conducted Power [dBm	1]		
	1	0	24.29	24.37	24.40		0
	1	50	24.09	24.12	24.12	0	0
	1	99	24.02	24.18	24.16		0
QPSK	50	0	23.04	23.35	23.28	0-1	1
	50	25	23.03	23.23	23.16		1
	50	50	23.13	23.19	23.10		1
	100	0	23.19	23.24	23.19		1
	1	0	23.78	23.83	23.51	0-1	1
	1	50	23.36	23.34	23.21		1
	1	99	23.53	23.44	22.97		1
16QAM	50	0	22.23	22.36	22.34		2
	50	25	22.20	22.26	22.26	0-2	2
	50	50	22.24	22.20	22.19		2
	100	0	22.28	22.27	22.27		2
	1	0	22.66	22.70	22.69	0-2	2
	1	50	22.44	22.45	22.41		2
Ī	1	99	22.37	22.50	22.45		2
64QAM	50	0	21.23	21.29	21.35	0-3	3
	50	25	21.23	21.24	21.27		3
	50	50	21.28	21.15	21.18		3
	100	0	21.29	21.25	21.26		3

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Table 8-20 LTE Band 66 (1745.0MHz) Conducted Powers – 15MHz Bandwidth

		L Bana o	0 (1740.0111112)	LTE Band 66 (AWS)	JWC13 1011111	z Banawiath	
				15 MHz Bandwidth			
			Low Channel	Mid Channel	High Channel		
Modulation	RB Size	RB Offset	132047 (1717.5 MHz)	132322 (1745.0 MHz)	132597 (1772.5 MHz)	MPR Allowed per 3GPP [dB]	MPR [dB]
			O	Conducted Power [dBm	1]		
	1	0	24.24	24.35	24.40		0
	1	36	23.80	24.12	24.31	0	0
	1	74	24.09	24.07	24.23		0
QPSK	36	0	22.95	23.24	23.32		1
	36	18	22.84	23.20	23.25	0-1	1
	36	37	22.84	23.19	23.33		1
	75	0	22.85	23.22	23.27		1
	1	0	23.42	23.51	23.50	0-1	1
	1	36	23.06	23.24	23.43		1
	1	74	23.25	23.19	23.36		1
16QAM	36	0	22.18	22.34	22.39		2
	36	18	22.04	22.30	22.32	0-2	2
	36	37	21.96	22.26	22.39	0-2	2
	75	0	21.99	22.30	22.32		2
	1	0	22.55	22.53	22.58		2
	1	36	22.39	22.34	22.54	0-2	2
	1	74	22.45	22.36	22.49	1	2
64QAM	36	0	21.10	21.39	21.41	0-3	3
	36	18	21.00	21.32	21.36		3
	36	37	20.97	21.29	21.39		3
	75	0	21.05	21.28	21.31		3

Table 8-21 LTE Band 66 (1745.0MHz) Conducted Powers – 10MHz Bandwidth

			<u>• (11 1010111112)</u>	LTE Band 66 (AWS)  10 MHz Bandwidth			
			Low Channel	Mid Channel	High Channel		
Modulation	RB Size	RB Offset	132022 (1715.0 MHz)	132322 (1745.0 MHz)	132622 (1775.0 MHz)	MPR Allowed per 3GPP [dB]	MPR [dB]
	Conducted Power [dBm]				]		
	1	0	24.13	24.18	24.26		0
	1	25	23.91	24.13	24.27	0	0
	1	49	23.99	24.10	24.14		0
QPSK	25	0	22.92	23.20	23.27		1
	25	12	22.80	23.19	23.25	0-1	1
	25	25	22.76	23.15	23.13		1
	50	0	22.73	23.23	23.18		1
	1	0	23.36	23.41	23.42	0-1	1
	1	25	23.00	23.32	23.19		1
	1	49	23.13	23.20	23.28		1
16QAM	25	0	22.09	22.28	22.33		2
	25	12	22.00	22.26	22.43	0-2	2
	25	25	21.86	22.19	22.25	0-2	2
	50	0	21.88	22.29	22.29	1	2
	1	0	22.61	22.46	22.55		2
	1	25	22.36	22.37	22.49	0-2	2
İ	1	49	22.25	22.33	22.43	1	2
64QAM	25	0	21.13	21.29	21.39	0-3	3
	25	12	20.92	21.30	21.44		3
ľ	25	25	20.81	21.26	21.37		3
	50	0	20.93	21.33	21.30		3

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Table 8-22 LTE Band 66 (1745.0MHz) Conducted Powers – 5MHz Bandwidth

	LTE Band 66 (1745.0MHz) Conducted Powers — 5MHz Bandwidth  LTE Band 66 (AWS)  5 MHz Bandwidth									
			Low Channel	Mid Channel	High Channel					
Modulation	RB Size	RB Offset	131997 (1712.5 MHz)	132322 (1745.0 MHz)	132647 (1777.5 MHz)	MPR Allowed per 3GPP [dB]	MPR [dB]			
			Conducted Power [dBm]							
	1	0	24.11	24.09	24.06		0			
	1	12	24.03	24.00	24.01	0	0			
	1	24	23.85	23.96	24.05		0			
QPSK	12	0	23.14	23.06	23.14		1			
	12	6	23.12	23.07	23.17	0-1	1			
	12	13	22.97	23.03	23.18		1			
	25	0	22.96	23.09	23.12		1			
	1	0	23.31	23.24	23.28	0-1	1			
	1	12	23.21	23.14	23.30		1			
	1	24	23.13	23.11	23.33		1			
16QAM	12	0	22.21	22.16	22.28		2			
	12	6	22.22	22.14	22.24	0-2	2			
	12	13	22.02	22.07	22.21	0-2	2			
ļ	25	0	22.16	22.14	22.24	1	2			
	1	0	22.38	22.39	22.46		2			
ļ	1	12	22.36	22.37	22.42	0-2	2			
	1	24	22.16	22.25	22.48	1	2			
64QAM	12	0	21.28	21.22	21.37	0-3	3			
	12	6	21.24	21.20	21.33		3			
ļ	12	13	21.21	21.14	21.28		3			
	25	0	21.24	21.12	21.27	1	3			

Table 8-23 LTE Band 66 (1745.0MHz) Conducted Powers – 3MHz Bandwidth

		12 Bana C	70 (114010HH12	LTE Band 66 (AWS)  3 MHz Bandwidth	011010 0111112	Danawia	
			Low Channel	Mid Channel	High Channel		
Modulation	RB Size	RB Offset	131987 (1711.5 MHz)	132322 (1745.0 MHz)	132657 (1778.5 MHz)	MPR Allowed per 3GPP [dB]	MPR [dB]
	Conducted Power [dBm]				]		
	1	0	24.08	23.96	24.04		0
	1	7	24.04	24.12	24.08	0	0
	1	14	23.95	24.09	24.13		0
QPSK	8	0	23.13	23.03	23.09		1
	8	4	23.16	23.04	23.19	0-1	1
	8	7	23.05	23.00	23.11		1
	15	0	23.17	23.04	23.06		1
	1	0	23.20	23.28	23.26	0-1	1
	1	7	23.29	23.36	23.32		1
	1	14	23.31	23.25	23.29		1
16QAM	8	0	22.20	22.08	22.24		2
	8	4	22.23	22.14	22.23	0-2	2
	8	7	22.19	22.12	22.26	0-2	2
	15	0	22.24	22.14	22.22		2
	1	0	22.35	22.39	22.40		2
	1	7	22.38	22.36	22.43	0-2	2
Ī	1	14	22.33	22.29	22.36		2
64QAM	8	0	21.24	21.21	21.27	0-3	3
	8	4	21.20	21.19	21.34		3
	8	7	21.26	21.12	21.29		3
j	15	0	21.22	21.13	21.24		3

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Table 8-24 LTE Band 66 (1745.0MHz) Conducted Powers – 1.4MHz Bandwidth

				LTE Band 66 (AWS) 1.4 MHz Bandwidth			
Modulation	RB Size	RB Offset	Low Channel 131979	Mid Channel 132322	High Channel 132665	MPR Allowed per	MPR [dB]
			(1710.7 MHz)	(1745.0 MHz) Conducted Power [dBm	(1779.3 MHz)	3GPP [dB]	
	1	0	23.99	24.00	23.96		0
	1	2	24.06	24.01	24.14	1	0
	1	5	23.95	23.96	24.03	1	0
QPSK	3	0	24.03	23.99	23.97	0	0
	3	2	24.06	24.05	24.12		0
	3	3	24.01	23.98	24.04		0
	6	0	23.06	22.99	23.09	0-1	1
	1	0	23.21	23.11	23.24	0-1	1
	1	2	23.16	23.16	23.30		1
	1	5	23.09	23.13	23.23		1
16QAM	3	0	23.15	23.05	23.19	0-1	1
	3	2	23.19	23.06	23.26		1
	3	3	23.11	23.09	23.15		1
	6	0	22.19	22.19	22.22	0-2	2
	1	0	22.26	22.20	22.36		2
	1	2	22.28	22.24	22.34		2
	1	5	22.27	22.17	22.32	0-2	2
64QAM	3	0	22.26	22.19	22.31		2
	3	2	22.31	22.21	22.36		2
	3	3	22.23	22.16	22.31		2
	6	0	21.18	21.04	21.19	0-3	3

# g. LTE Band 25

Table 8-25 LTE Band 25 (1882.5MHz) Conducted Powers – 20MHz Bandwidth

		. <b></b>	(	, conaactea i		<u> </u>	
				LTE Band 25 (PCS) 20 MHz Bandwidth			
			Low Channel	Mid Channel	High Channel		
Modulation	RB Size	RB Offset	26140 (1860.0 MHz)	26365 (1882.5 MHz)	26590 (1905.0 MHz)	MPR Allowed per 3GPP [dB]	MPR [dB]
			(	Conducted Power [dBm	1]		
	1	0	24.72	24.77	24.69		0
	1	50	24.31	24.31	24.41	0	0
	1	99	24.30	24.43	24.40		0
QPSK	50	0	23.65	23.49	23.56		1
	50	25	23.42	23.38	23.49	0-1	1
	50	50	23.39	23.31	23.44		1
	100	0	23.43	23.36	23.51		1
	1	0	24.00	23.89	23.98	0-1	1
	1	50	23.84	23.67	23.73		1
	1	99	23.85	23.74	23.63		1
16QAM	50	0	22.72	22.56	22.66		2
	50	25	22.53	22.46	22.60	0-2	2
	50	50	22.47	22.38	22.51	0-2	2
	100	0	22.53	22.44	22.62		2
	1	0	23.00	22.89	23.00		2
	1	50	22.88	22.55	22.91	0-2	2
	1	99	22.93	22.69	22.87		2
64QAM	50	0	21.75	21.60	21.78		3
	50	25	21.58	21.63	21.72	0-3	3
	50	50	21.57	21.60	21.69		3
	100	0	21.55	21.59	21.63	1	3

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Table 8-26 LTE Band 25 (1882.5MHz) Conducted Powers – 15MHz Bandwidth

				LTE Band 25 (PCS) 15 MHz Bandwidth			
Modulation	RB Size	RB Offset	Low Channel 26115 (1857.5 MHz)	Mid Channel 26365 (1882.5 MHz) Conducted Power [dBm	High Channel 26615 (1907.5 MHz)	MPR Allowed per 3GPP [dB]	MPR [dB]
	1	0	24.62	24.46	24.56		0
•	1	36	24.47	24.38	24.40	0	0
	1	74	24.43	24.29	24.26		0
QPSK	36	0	23.59	23.39	23.49		1
	36	18	23.55	23.34	23.45	0-1	1
	36	37	23.35	23.28	23.40		1
	75	0	23.41	23.40	23.46		1
	1	0	23.79	23.63	23.71	0-1	1
	1	36	23.64	23.53	23.67		1
	1	74	23.57	23.42	23.59		1
16QAM	36	0	22.64	22.46	22.58		2
	36	18	22.59	22.41	22.52	0-2	2
	36	37	22.43	22.37	22.49	0-2	2
	75	0	22.56	22.42	22.52		2
	1	0	22.92	22.65	22.76		2
	1	36	22.78	22.54	22.69	0-2	2
	1	74	22.76	22.52	22.63		2
64QAM	36	0	21.64	21.51	21.63	0-3	3
	36	18	21.67	21.47	21.58		3
	36	37	21.52	21.39	21.53		3
	75	0	21.53	21.44	21.59		3

Table 8-27 LTE Band 25 (1882.5MHz) Conducted Powers – 10MHz Bandwidth

	LTE Band 25 (PCS) 10 MHz Bandwidth									
			Low Channel	Mid Channel	High Channel					
Modulation	RB Size	RB Offset	26090 (1855.0 MHz)	26365 (1882.5 MHz)	26640 (1910.0 MHz)	MPR Allowed per 3GPP [dB]	MPR [dB]			
			(	Conducted Power [dBm	1]					
	1	0	24.78	24.58	24.44		0			
	1	25	24.50	24.34	24.38	0	0			
	1	49	24.68	24.43	24.17		0			
QPSK	25	0	23.54	23.39	23.46		1			
	25	12	23.53	23.33	23.44	0-1	1			
	25	25	23.47	23.31	23.43	0-1	1			
	50	0	23.54	23.35	23.47		1			
	1	0	24.00	23.79	23.61		1			
	1	25	23.89	23.56	23.56	0-1	1			
	1	49	23.82	23.59	23.49		1			
16QAM	25	0	22.60	22.45	22.57		2			
	25	12	22.58	22.46	22.47	0-2	2			
	25	25	22.59	22.38	22.53	0-2	2			
	50	0	22.58	22.47	22.51		2			
	1	0	22.88	22.74	22.69		2			
	1	25	22.71	22.62	22.63	0-2	2			
	1	49	22.84	22.69	22.59		2			
64QAM	25	0	21.68	21.51	21.54		3			
	25	12	21.62	21.47	21.53	0-3	3			
	25	25	21.57	21.42	21.46		3			
	50	0	21.64	21.44	21.55		3			

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**Table 8-28** LTE Band 25 (1882 5MHz) Conducted Powers - 5MHz Bandwidth

				LTE Band 25 (PCS) 5 MHz Bandwidth			
Modulation	RB Size	RB Offset	Low Channel 26065 (1852.5 MHz)	Mid Channel 26365 (1882.5 MHz) Conducted Power [dBm	High Channel 26665 (1912.5 MHz)	MPR Allowed per 3GPP [dB]	MPR [dB]
	1	0	24.55	24.34	24.44		0
	<u>.</u> 1	12	24.43	24.25	24.39	- o	0
	1	24	24.47	24.23	24.13	_	0
QPSK	12	0	23.52	23.37	23.47		1
	12	6	23.50	23.34	23.46	† F	1
	12	13	23.48	23.32	23.43	0-1	1
	25	0	23.49	23.29	23.39	<b>1</b>	1
	1	0	23.76	23.48	23.53		1
	1	12	23.62	23.34	23.56	0-1	1
	1	24	23.64	23.47	23.51		1
16QAM	12	0	22.61	22.44	22.49		2
	12	6	22.59	22.37	22.51	0-2	2
	12	13	22.54	22.34	22.46	0-2	2
	25	0	22.56	22.36	22.49	1	2
	1	0	22.77	22.58	22.66		2
	1	12	22.74	22.55	22.68	0-2	2
	1	24	22.71	22.53	22.62	1	2
64QAM	12	0	21.66	21.48	21.63		3
	12	6	21.64	21.46	21.59	0-3	3
	12	13	21.62	21.43	21.52	] 0-3	3
	25	0	21.57	21.42	21.51		3

**Table 8-29** LTE Band 25 (1882.5MHz) Conducted Powers - 3MHz Bandwidth

			20 (10021011111	LTE Band 25 (PCS)			
				3 MHz Bandwidth			
			Low Channel	Mid Channel	High Channel		
Modulation	RB Size	RB Offset	26055 (1851.5 MHz)	26365 (1882.5 MHz)	26675 (1913.5 MHz)	MPR Allowed per 3GPP [dB]	MPR [dB]
			(	Conducted Power [dBm	1]		
	1	0	24.47	24.26	24.39		0
	1	7	24.55	24.40	24.41	0	0
	1	14	24.43	24.23	24.12	1 [	0
QPSK	8	0	23.50	23.30	23.33		1
	8	4	23.48	23.33	23.41	0-1	1
	8	7	23.46	23.27	23.34		1
	15	0	23.49	23.30	23.39		1
	1	0	23.63	23.43	23.45		1
	1	7	23.71	23.57	23.66	0-1	1
	1	14	23.66	23.41	23.43		1
16QAM	8	0	22.55	22.44	22.47		2
	8	4	22.54	22.41	22.53	0-2	2
	8	7	22.59	22.39	22.49	0-2	2
	15	0	22.56	22.38	22.47	1 [	2
	1	0	22.73	22.50	22.56		2
	1	7	22.74	22.59	22.66	0-2	2
	1	14	22.67	22.51	22.51	1	2
64QAM	8	0	21.62	21.43	21.49		3
	8	4	21.63	21.42	21.51	0-3	3
	8	7	21.57	21.40	21.50	0-3	3
	15	0	21.55	21.41	21.49		3

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Table 8-30 LTE Band 25 (1882.5MHz) Conducted Powers – 1.4MHz Bandwidth

				LTE Band 25 (PCS) 1.4 MHz Bandwidth			
Modulation	RB Size	RB Offset	Low Channel 26047 (1850.7 MHz)	Mid Channel 26365 (1882.5 MHz)	High Channel 26683 (1914.3 MHz)	MPR Allowed per 3GPP [dB]	MPR [dB]
				Conducted Power [dBn	1]		
	1	0	24.38	24.44	24.29		0
	1	2	24.43	24.47	24.32		0
	1	5	24.39	24.42	24.02	0	0
QPSK	3	0	24.44	24.45	24.28		0
	3	2	24.49	24.47	24.15		0
	3	3	24.40	24.43	23.99	0-1	0
	6	0	23.42	23.47	23.24		1
	1	0	23.56	23.63	23.39		1
	1	2	23.49	23.68	23.47	0-1	1
	1	5	23.51	23.59	23.35		1
16QAM	3	0	23.51	23.58	23.37	- 0-1	1
	3	2	23.54	23.67	23.38		1
	3	3	23.53	23.50	23.32		1
	6	0	22.49	22.53	22.41	0-2	2
	1	0	22.68	22.68	22.47		2
	1	2	22.70	22.69	22.54		2
	1	5	22.63	22.72	22.51	0-2	2
64QAM	3	0	22.64	22.65	22.51	- U-2 -	2
	3	2	22.66	22.61	22.56		2
	3	3	22.65	22.59	22.49		2
	6	0	21.49	21.57	21.54	0-3	3

# h. LTE Band 30

Table 8-31 LTE Band 30 (2310.0MHz) Conducted Powers – 10MHz Bandwidth

	LTE Band 30 10 MHz Bandwidth								
Modulation	RB Size	RB Offset	Mid Channel 27710 (2310.0 MHz) Conducted Power	MPR Allowed per 3GPP [dB]	MPR [dB]				
			[dBm]						
	1	0	23.70		0				
	1	25	23.69	0	0				
	1	49	23.83		0				
QPSK	25	0	22.81		1				
	25	12	22.78	0-1	1				
	25	25	22.79	0-1	1				
	50	0	22.75		1				
	1	0	22.87		1				
	1	25	22.86	0-1	1				
	1	49	22.97		1				
16QAM	25	0	21.87		2				
	25	12	21.84	0-2	2				
	25	25	21.86	0-2	2				
	50	0	21.83		2				
	1	0	21.93		2				
	1	25	21.96	0-2	2				
	1	49	22.00		2				
64QAM	25	0	20.90		3				
	25	12	20.86	0-3	3				
	25	25	20.90	0-3	3				
	50	0	20.87		3				

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Table 8-32 LTE Band 30 (2310.0MHz) Conducted Powers – 5MHz Bandwidth

			LTE Band 30 5 MHz Bandwidth			
Modulation	RB Size	RB Offset	Mid Channel 27710 (2310.0 MHz)	MPR Allowed per	MPR [dB]	
moudiation	112 0120		Conducted Power [dBm]	3GPP [dB]	[45]	
	1	0	23.67		0	
	1	12	23.66	0	0	
	1	24	23.73		0	
QPSK	12	0	22.72		1	
	12	6	22.74	0-1	1	
	12	13	22.66	0-1	1	
	25	0	22.67		1	
	1	0	22.53		1	
	1	12	22.50	0-1	1	
	1	24	22.56		1	
16QAM	12	0	21.75		2	
	12	6	21.74	0-2	2	
	12	13	21.71	0-2	2	
	25	0	21.75		2	
	1	0	21.62		2	
	1	12	21.55	0-2	2	
	1	24	21.61		2	
64QAM	12	0	20.82		3	
	12	6	20.83	0-3	3	
	12	13	20.78	U-3	3	
	25	0	20.79		3	

Note: Since LTE Band 30 at 5MHz bandwidth does not support 3 non-overlapping channels, conducted power measurements were made only on the middle channel.

## i. LTE Band 7

Table 8-33 LTE Band 7 (2535.0MHz) Conducted Powers – 20MHz Bandwidth

	LTE Band 7								
				20 MHz Bandwidth					
			Low Channel	Mid Channel	High Channel				
Modulation	RB Size	RB Offset	20850	21100	21350	MPR Allowed per	MPR [dB]		
			(2510.0 MHz)	(2535.0 MHz)	(2560.0 MHz)	3GPP [dB]			
				Conducted Power [dBm					
	1	0	23.67	23.80	23.77		0		
	1	50	23.44	23.66	23.49	0	0		
	1	99	23.57	23.71	23.64		0		
QPSK	50	0	22.61	22.71	22.65		1		
	50	25	22.56	22.69	22.20	0-1	1		
	50	50	22.58	22.66	22.53	0-1	1		
	100	0	22.65	22.64	22.57		1		
	1	0	22.52	22.68	22.99		1		
	1	50	22.35	22.49	22.15	0-1	1		
	1	99	22.45	22.69	22.99		1		
16QAM	50	0	21.67	21.77	21.73		2		
	50	25	21.62	21.73	21.35	0.0	2		
	50	50	21.66	21.71	21.62	0-2	2		
	100	0	21.68	21.74	21.63		2		
	1	0	21.91	21.69	21.85		2		
	1	50	21.71	21.54	21.23	0-2	2		
	1	99	21.78	21.66	21.71		2		
64QAM	50	0	20.64	20.82	20.75		3		
	50	25	20.59	20.78	20.33	0-3	3		
	50	50	20.65	20.73	20.65		3		
	100	0	20.74	20.75	20.68		3		

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Table 8-34
LTE Band 7 (2535.0MHz) Conducted Powers – 15MHz Bandwidth

		. I L Dallu	7 (2333.0WII IZ)	LTE Band 7	JWEIS - I JIVII I	z Bandwidth			
				15 MHz Band /					
			Low Channel	Mid Channel	High Channel				
Modulation	RB Size	RB Offset	RB Offset	RB Offset	20825 (2507.5 MHz)	21100 (2535.0 MHz)	21375 (2562.5 MHz)	MPR Allowed per 3GPP [dB]	MPR [dB]
			C	Conducted Power [dBm	1]				
	1	0	23.83	23.71	23.90		0		
	1	36	23.59	23.56	23.79	0	0		
	1	74	23.50	23.58	23.74		0		
QPSK	36	0	22.72	22.64	22.71		1		
	36	18	22.67	22.60	22.74	0-1	1		
	36	37	22.58	22.54	22.79		1		
	75	0	22.63	22.58	22.72		1		
	1	0	22.91	22.93	22.99	0-1	1		
	1	36	22.68	22.72	22.85		1		
	1	74	22.60	22.68	22.89		1		
16QAM	36	0	21.79	21.72	21.87		2		
	36	18	21.74	21.70	21.81	0-2	2		
	36	37	21.64	21.61	21.84	0-2	2		
	75	0	21.68	21.66	21.78		2		
	1	0	21.88	21.92	21.97		2		
	1	36	21.66	21.87	21.87	0-2	2		
	1	74	21.70	21.85	21.94		2		
64QAM	36	0	20.82	20.78	20.84		3		
	36	18	20.79	20.75	20.83	0-3	3		
	36	37	20.67	20.69	20.88		3		
	75	0	20.72	20.73	20.78		3		

Table 8-35 LTE Band 7 (2535.0MHz) Conducted Powers – 10MHz Bandwidth

		. I L Dallu	7 (2333.0WITE)	Conducted Po	JWEIS - IUIVIII	z Bandwidth		
				LTE Band 7 10 MHz Bandwidth				
			Low Channel	Mid Channel	High Channel			
Modulation	RB Size	S Size RB Offset	RB Offset 20800 (2505.0 MHz)	20800	21100 (2535.0 MHz)	21400 (2565.0 MHz)	MPR Allowed per 3GPP [dB]	MPR [dB]
			C	Conducted Power [dBm	1]			
	1	0	23.71	23.76	23.53		0	
	1	25	23.62	23.68	23.81	0	0	
	1	49	23.54	23.59	23.79		0	
QPSK	25	0	22.67	22.68	22.80		1	
	25	12	22.65	22.69	22.86	0-1	1	
	25	25	22.59	22.66	22.79		1	
	50	0	22.63	22.67	22.75		1	
	1	0	22.86	22.89	22.76		1	
	1	25	22.78	22.78	22.91	0-1	1	
	1	49	22.72	22.83	22.90		1	
16QAM	25	0	21.78	21.80	21.83		2	
	25	12	21.72	21.82	21.92	0-2	2	
	25	25	21.66	21.79	21.94	0-2	2	
	50	0	21.75	21.78	21.82		2	
	1	0	21.86	22.00	21.79		2	
	1	25	21.69	21.92	21.98	0-2	2	
	1	49	21.78	21.87	21.96		2	
64QAM	25	0	20.83	20.84	20.83		3	
ļ	25	12	20.78	20.83	20.87	0-3	3	
ľ	25	25	20.76	20.79	20.86		3	
	50	0	20.74	20.81	20.81		3	

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**Table 8-36** LTE Band 7 (2535.0MHz) Conducted Powers - 5MHz Bandwidth

	•		(2000.011112	LTE Band 7	OWO10 OWN12	- Ballawiatii						
	5 MHz Bandwidth											
			Low Channel	Mid Channel	High Channel							
Modulation	RB Size	RB Offset	20775 (2502.5 MHz)	21100 (2535.0 MHz)	21425 (2567.5 MHz)	MPR Allowed per 3GPP [dB]	MPR [dB]					
			C	Conducted Power [dBm								
	1	0	23.75	23.71	23.84		0					
	1	12	23.72	23.70	23.80	0	0					
	1	24	23.69	23.63	23.83		0					
QPSK	12	0	22.77	22.81	22.87		1					
	12	6	22.81	22.72	22.89	0-1	1					
	12	13	22.78	22.70	22.86	0-1	1					
	25	0	22.77	22.74	22.88		1					
	1	0	22.93	22.77	23.00		1					
	1	12	22.87	22.89	22.94	0-1	1					
	1	24	22.82	22.85	22.92		1					
16QAM	12	0	21.84	21.83	21.98		2					
	12	6	21.91	21.82	21.99	0-2	2					
	12	13	21.85	21.74	21.91	0-2	2					
	25	0	21.84	21.79	21.89		2					
	1	0	21.96	21.91	21.89		2					
	1	12	21.87	21.89	21.98	0-2	2					
	1	24	21.89	21.88	21.84		2					
64QAM	12	0	20.84	20.86	20.93		3					
	12	6	20.91	20.87	20.91	0-3	3					
	12	13	20.85	20.80	20.85	0-3	3					
	25	0	20.84	20.69	20.87	1	3					

# j. LTE Band 41 - Power Class 3

**Table 8-37** LTE Band 41 (2593.0MHz) Conducted Powers - 20MHz Bandwidth

	LTE Band 41 20 MHz Bandwidth											
			Low Channel	Low-Mid Channel	Mid Channel	Mid-High Channel	High Channel					
Modulation	RB Size	RB Offset	39750 (2506.0 MHz)	40185 (2549.5 MHz)	40620 (2593.0 MHz)	41055 (2636.5 MHz)	41490 (2680.0 MHz)	MPR Allowed per 3GPP [dB]	MPR [dB]			
Conducted Power [dBm]												
	1	0	24.38	24.41	24.02	23.95	24.05		0			
	1	50	23.98	23.94	23.77	23.74	23.84	0	0			
	1	99	23.96	23.94	23.77	23.79	23.73		0			
QPSK	50	0	23.06	23.07	22.93	22.93	22.96		1			
	50	25	23.01	23.01	22.86	22.85	22.84	0-1	1			
	50	50	22.96	22.92	22.76	22.77	22.81		1			
	100	0	23.01	23.01	22.83	22.87	22.92		1			
	1	0	23.50	23.50	23.20	23.45	23.50		1			
	1	50	23.44	23.42	23.23	23.15	23.29	0-1	1			
	1	99	23.38	23.44	23.20	23.19	23.20		1			
16QAM	50	0	22.14	22.17	21.98	21.88	22.05		2			
	50	25	22.09	22.09	21.90	21.83	21.99	0-2	2			
	50	50	22.01	22.00	21.79	21.74	21.91	0-2	2			
	100	0	22.10	22.11	21.88	21.83	21.99		2			
	1	0	22.31	22.33	22.19	22.05	22.20		2			
	1	50	22.11	22.10	21.97	21.81	21.96	0-2	2			
	1	99	22.05	22.11	21.96	21.84	21.87		2			
64QAM	50	0	21.15	21.19	21.05	20.92	21.08		3			
	50	25	21.11	21.13	21.02	20.84	21.00	0-3	3			
	50	50	21.04	21.04	20.93	20.76	20.93	] 0-3	3			
	100	0	21.11	21.11	21.00	20.85	21.01		3			

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Table 8-38 LTE Band 41 (2593.0MHz) Conducted Powers – 15MHz Bandwidth

	LTE Band 41 (2593.UMHZ) CONDUCTED POWERS — 15MHZ BANDWIGHT LTE Band 41 15 MHz Bandwidth											
			Low Channel	Low-Mid Channel	Mid Channel	Mid-High Channel	High Channel					
Modulation	RB Size	RB Offset	39750 (2506.0 MHz)	40185 (2549.5 MHz)	40620 (2593.0 MHz)	41055 (2636.5 MHz)	41490 (2680.0 MHz)	MPR Allowed per 3GPP [dB]	MPR [dB]			
				Co	nducted Power [dE	Bm]						
	1	0	24.24	24.32	24.25	23.76	23.85		0			
	1	36	24.15	24.19	24.00	23.61	23.72	0	0			
	1	74	24.06	24.21	23.95	23.62	23.63		0			
QPSK	36	0	23.15	23.27	23.12	22.73	22.82		1			
	36	18	23.17	23.21	23.11	22.68	22.78	0-1	1			
	36	37	23.07	23.14	22.96	22.61	22.70	0-1	1			
	75	0	23.11	23.19	23.04	22.66	22.75		1			
	1	0	23.50	23.50	23.50	23.25	23.31		1			
	1	36	23.50	23.49	23.49	23.09	23.21	0-1	1			
	1	74	23.49	23.49	23.47	23.11	23.11		1			
16QAM	36	0	22.20	22.30	22.19	21.75	21.86		2			
	36	18	22.20	22.30	22.14	21.73	21.83	0-2	2			
	36	37	22.16	22.21	22.02	21.69	21.76	] "2	2			
	75	0	22.19	22.27	22.14	21.71	21.84		2			
	1	0	22.39	22.46	22.37	21.92	22.01		2			
	1	36	22.27	22.33	22.18	21.75	21.90	0-2	2			
	1	74	22.26	22.37	22.14	21.80	21.83		2			
64QAM	36	0	21.24	21.35	21.22	20.76	20.91		3			
	36	18	21.23	21.30	21.15	20.77	20.86	0-3	3			
	36	37	21.20	21.27	21.05	20.68	20.82	] ""	3			
l	75	0	21.20	21.29	21.13	20.74	20.88		3			

Table 8-39 LTE Band 41 (2593.0MHz) Conducted Powers – 10MHz Bandwidth

		LIL Da	114 41 (239	3.0WIT12) CC	LTE Band 41	owers – 10	WITTE Dariu	widti			
10 MHz Bandwidth											
			Low Channel	Low-Mid Channel	Mid Channel	Mid-High Channel	High Channel				
Modulation	RB Size	RB Offset	39750 (2506.0 MHz)	40185 (2549.5 MHz)	40620 (2593.0 MHz)	41055 (2636.5 MHz)	41490 (2680.0 MHz)	MPR Allowed per 3GPP [dB]	MPR [dB]		
				Co	nducted Power [di	Bm]					
	1	0	24.18	24.26	24.17	23.71	23.82		0		
	1	25	24.14	24.19	24.04	23.63	23.73	0	0		
	1	49	24.11	24.23	23.89	23.67	23.65		0		
QPSK	25	0	23.15	23.21	23.08	22.68	22.83		1		
	25	12	23.17	23.22	23.08	22.71	22.78	0-1	1		
	25	25	23.11	23.16	22.99	22.60	22.70	]	1		
	50	0	23.14	23.22	23.05	22.69	22.76		1		
	1	0	23.50	23.49	23.49	23.21	23.31		1		
	1	25	23.49	23.48	23.48	23.12	23.18	0-1	1		
	1	49	23.49	23.50	23.40	23.16	23.14		1		
16QAM	25	0	22.20	22.28	22.12	21.71	21.82		2		
	25	12	22.21	22.25	22.10	21.69	21.82	0-2	2		
	25	25	22.12	22.21	22.02	21.66	21.75	0-2	2		
	50	0	22.23	22.30	22.16	21.75	21.85		2		
	1	0	22.35	22.40	22.30	21.88	21.98		2		
	1	25	22.30	22.37	22.21	21.80	21.90	0-2	2		
	1	49	22.27	22.40	22.07	21.79	21.86	1	2		
64QAM	25	0	21.34	21.39	21.30	20.84	20.94		3		
	25	12	21.30	21.39	21.25	20.88	20.95	0-3	3		
	25	25	21.30	21.33	21.13	20.82	20.91	] -3	3		
	50	0	21.23	21.31	21.19	20.81	20.88		3		

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Table 8-40 LTE Band 41 (2593.0MHz) Conducted Powers – 5MHz Bandwidth

	LTE Band 41 (2593.UMHZ) CONQUCTED POWERS — 5MHZ BANGWIGTN  LTE Band 41											
	E Bail width											
			Low Channel	Low-Mid Channel	Mid Channel	Mid-High Channel	High Channel					
Modulation	RB Size	RB Offset	39750 (2506.0 MHz)	40185 (2549.5 MHz)	40620 (2593.0 MHz)	41055 (2636.5 MHz)	41490 (2680.0 MHz)	MPR Allowed per 3GPP [dB]	MPR [dB]			
				Co	nducted Power [di	Bm]						
	1	0	24.14	24.27	24.14	23.73	23.76		0			
	1	12	24.15	24.23	24.10	23.70	23.77	0	0			
	1	24	24.11	24.28	24.04	23.66	23.69		0			
QPSK	12	0	23.14	23.23	23.12	22.71	22.81		1			
	12	6	23.17	23.26	23.11	22.69	22.77	0-1	1			
	12	13	23.11	23.21	23.06	22.70	22.73	U-1	1			
	25	0	23.14	23.22	23.10	22.70	22.78		1			
	1	0	23.50	23.49	23.50	23.17	23.23		1			
	1	12	23.49	23.49	23.49	23.16	23.23	0-1	1			
	1	24	23.48	23.50	23.48	23.14	23.21		1			
16QAM	12	0	22.26	22.32	22.20	21.82	21.88		2			
	12	6	22.30	22.38	22.20	21.80	21.88	0-2	2			
	12	13	22.24	22.28	22.14	21.75	21.80	02	2			
	25	0	22.19	22.28	22.12	21.73	21.80		2			
	1	0	22.34	22.41	22.26	21.84	21.91	]	2			
	1	12	22.34	22.39	22.24	21.83	21.92	0-2	2			
	1	24	22.28	22.46	22.20	21.82	21.84		2			
64QAM	12	0	21.34	21.37	21.27	20.86	20.94		3			
	12	6	21.35	21.43	21.26	20.88	20.92	0-3	3			
	12	13	21.28	21.35	21.18	20.85	20.86	] 5-5	3			
	25	0	21.30	21.40	21.24	20.85	20.91		3			

# k. LTE Band 41 - Power Class 2

Table 8-41 LTE Band 41 (2593.0MHz) Conducted Powers – 20MHz Bandwidth

				,	LTE Band 41 0 MHzBandwidth	OWC13 - 20			
			Low Channel	Low-Mid Channel	Mid Channel	Mid-High Channel	High Channel		
Modulation	RB Size	RB Offset	39750 (2506.0 MHz)	40185 (2549.5 MHz)	40620 (2593.0 MHz)	41055 (2636.5 MHz)	41490 (2680.0 MHz)	MPR Allowed per 3GPP [dB]	MPR [dB]
				Co	nducted Power [de	ßm]			
	1	0	27.27	27.18	27.48	26.94	27.05		0
	1	50	26.81	26.99	27.16	26.74	26.83	0	0
	1	99	26.60	27.06	27.05	26.65	26.71		0
QPSK	50	0	25.81	26.21	26.39	25.88	26.01		1
	50	25	25.91	26.25	26.27	25.87	25.94	0-1	1
	50	50	25.59	26.17	26.12	25.78	25.88	0-1	1
	100	0	25.78	26.20	26.31	25.79	26.02		1
	1	0	26.50	26.48	26.50	26.25	26.36		1
	1	50	26.27	26.47	26.47	26.10	26.18	0-1	1
	1	99	26.02	26.42	26.41	25.99	26.08		1
16QAM	50	0	25.30	25.31	25.47	24.97	25.12		2
	50	25	25.16	25.33	25.44	24.98	25.02	0-2	2
	50	50	24.85	25.26	25.29	24.87	24.94	0-2	2
	100	0	24.68	25.24	25.38	24.88	25.03		2
	1	0	25.35	25.36	25.46	25.05	25.17		2
	1	50	25.14	25.27	25.37	24.88	24.97	0-2	2
	1	99	24.82	25.22	25.31	24.79	24.88		2
64QAM	50	0	24.02	24.32	24.48	23.96	24.12		3
	50	25	24.16	24.35	24.46	24.02	24.07	0-3	3
	50	50	23.83	24.28	24.34	23.87	23.98	] "-5" [	3
	100	0	23.72	24.21	24.44	23.88	24.02		3

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Table 8-42 LTE Band 41 (2593.0MHz) Conducted Powers – 15MHz Bandwidth

			,	1	LTE Band 41 5 MHz Bandwidth				
			Low Channel	Low-Mid Channel	Mid Channel	Mid-High Channel	High Channel		
Modulation	RB Size	RB Offset	39750 (2506.0 MHz)	40185 (2549.5 MHz)	40620 (2593.0 MHz)	41055 (2636.5 MHz)	41490 (2680.0 MHz)	MPR Allowed per 3GPP [dB]	MPR [dB]
	1	0	27.08	27.40	27.36	26.92	26.86		0
	1	36	27.07	27.28	27.18	26.76	26.73	0	0
	1	74	26.87	27.23	27.04	26.73	26.63		0
QPSK	36	0	25.98	26.37	26.29	25.86	25.81		1
	36	18	26.04	26.36	26.26	25.83	25.79	0-1	1
	36	37	25.88	26.28	26.16	25.80	25.71	]	1
	75	0	25.77	26.32	26.20	25.80	25.75		1
	1	0	26.43	26.49	26.47	26.20	26.16		1
	1	36	26.29	26.48	26.41	26.07	26.02	0-1	1
	1	74	26.19	26.44	26.36	26.05	25.92		1
16QAM	36	0	25.16	25.45	25.38	24.97	24.92		2
	36	18	25.23	25.41	25.23	24.96	24.86	0-2	2
	36	37	25.00	25.40	25.25	24.88	24.79	0-2	2
	75	0	24.87	25.40	25.28	24.89	24.83		2
	1	0	25.48	25.49	25.46	25.19	25.12		2
	1	36	25.35	25.47	25.49	25.06	25.02	0-2	2
	1	74	25.28	25.43	25.34	25.04	24.91		2
64QAM	36	0	24.11	24.43	24.35	23.91	23.89		3
	36	18	24.24	24.42	24.31	23.89	23.83	0-3	3
	36	37	24.18	24.34	24.21	23.82	23.76	J -5	3
	75	0	24.12	24.43	24.31	23.89	23.90		3

Table 8-43 LTE Band 41 (2593.0MHz) Conducted Powers – 10MHz Bandwidth

	LTE Band 41 10 MHz Bandwidth											
			Low Channel	Low-Mid Channel	Mid Channel	Mid-High Channel	High Channel					
Modulation	RB Size	RB Offset	39750 (2506.0 MHz)	40185 (2549.5 MHz)	40620 (2593.0 MHz)	41055 (2636.5 MHz)	41490 (2680.0 MHz)	MPR Allowed per 3GPP [dB]	MPR [dB]			
				Co	nducted Power [de	Bm]						
	1	0	26.85	27.34	27.26	26.84	26.81		0			
	1	25	26.95	27.31	27.17	26.79	26.73	0	0			
	1	49	26.82	27.22	27.07	26.69	26.66		0			
QPSK	25	0	25.88	26.32	26.24	25.81	25.79		1			
	25	12	25.95	26.37	26.24	25.80	25.77	0-1	1			
	25	25	25.74	26.26	26.14	25.76	25.71	0-1	1			
	50	0	25.43	26.34	26.19	25.81	25.76		1			
	1	0	26.40	26.48	26.50	26.16	26.11		1			
	1	25	26.12	26.47	26.49	26.09	26.02	0-1	1			
	1	49	25.94	26.45	26.38	26.02	25.99		1			
16QAM	25	0	24.95	25.37	25.32	24.85	24.86		2			
	25	12	25.07	25.14	25.27	24.86	24.82	0-2	2			
	25	25	25.00	25.32	25.20	24.84	24.78	0-2	2			
	50	0	24.75	25.43	25.32	24.91	24.84		2			
	1	0	25.40	25.46	25.49	25.15	25.09		2			
	1	25	25.30	25.44	25.49	25.08	25.00	0-2	2			
	1	49	25.18	25.41	25.33	25.00	24.94		2			
64QAM	25	0	24.12	24.19	24.41	23.92	23.95		3			
	25	12	24.22	24.48	24.34	23.92	23.89	0-3	3			
	25	25	24.17	24.39	24.28	23.86	23.89	0-3	3			
	50	0	23.47	24.47	24.37	23.90	23.89	1	3			

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## Table 8-44 LTE Band 41 (2593.0MHz) Conducted Powers – 5MHz Bandwidth

	LTE Band 41 5 MHz Bandwidth								
			Low Channel	Low-Mid Channel	Mid Channel	Mid-High Channel	High Channel		
Modulation	RB Size	RB Offset	39750 (2506.0 MHz)	40185 (2549.5 MHz)	40620 (2593.0 MHz)	41055 (2636.5 MHz)	41490 (2680.0 MHz)	MPR Allowed per 3GPP [dB]	MPR [dB]
	Conducted Power [dBm]								
	1	0	26.91	27.28	27.19	26.74	26.72		0
	1	12	27.08	27.28	27.19	26.77	26.73	0	0
	1	24	26.95	27.24	27.11	26.69	26.66		0
QPSK	12	0	26.06	26.31	26.21	25.77	25.72		1
	12	6	25.97	26.35	26.25	25.80	25.74	0-1	1
	12	13	25.92	26.26	26.16	25.74	25.71		1
	25	0	25.75	26.32	26.17	25.76	25.78		1
	1	0	26.27	26.47	26.49	26.12	26.02		1
	1	12	26.36	26.48	26.50	26.09	26.02	0-1	1
	1	24	26.23	26.44	26.43	26.03	25.99		1
16QAM	12	0	25.21	25.42	25.34	24.93	24.88		2
	12	6	25.24	25.44	25.38	24.92	24.87	0-2	2
	12	13	25.23	25.41	25.31	24.89	24.94	0-2	2
	25	0	25.03	25.34	25.28	24.84	24.79		2
	1	0	25.32	25.47	25.50	24.95	24.99		2
	1	12	25.38	25.46	25.49	25.06	25.00	0-2	2
	1	24	25.32	25.41	25.40	25.02	24.97	1	2
64QAM	12	0	24.23	24.40	24.37	23.89	23.86		3
	12	6	24.25	24.43	24.36	23.92	23.83	0-3	3
	12	13	24.20	24.41	24.28	23.86	23.79	] ""	3
	25	0	24.01	24.41	24.32	23.90	23.84		3

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# VIII. WIFI Conducted Powers (SISO/MIMO)

**Table 8-45** IEEE 802.11b/g/n (2.4GHz, SISO) Reduced Average RF Power<sup>1</sup>

	2.4GHz Conducted Power [dBm]				
		IEEE Transmission Mode			
Freq [MHz]	Channel	802.11b	802.11g	802.11n	
		Average	Average	Average	
2412	1	13.08	13.26	13.14	
2437	6	13.22	13.49	13.31	
2462	11	13.46	12.76	13.47	

**Table 8-46** IEEE 802.11g/n (2.4GHz, MIMO) Reduced Average RF Power<sup>1</sup>

2.4GHz Conducted Power [dBm]			
Freq [MHz]	Channel	IEEE Transm	ission mode
ried [MHZ]	Chainlei	802.11g	802.11n
2412	1	16.08	15.92
2437	6	16.47	16.30
2462	11	15.99	16.31

**Table 8-47** IEEE 802.11a/n/ac (5GHz, 20MHz BW, SISO) Reduced Average RF Power<sup>1</sup>

	5GHz (20MHz) Conducted Power [dBm]				
Freq [MHz]	Channel	IEEE Transmission Mod			
rieq [wiriz]	Chamilei	802.11a	802.11n	802.11ac	
5180	36	11.36	11.43	11.38	
5200	40	11.70	11.48	11.45	
5220	44	11.55	11.50	11.27	
5240	48	11.49	11.38	11.43	
5260	52	11.42	11.31	11.47	
5280	56	11.53	11.28	11.36	
5300	60	11.52	11.55	11.30	
5320	64	11.40	11.57	11.55	
5500	100	11.37	11.20	11.27	
5580	116	11.45	11.48	11.24	
5660	132	11.53	11.46	12.17	
5700	140	11.41	11.34	11.97	
5745	149	11.23	11.28	12.19	
5785	157	11.18	11.13	12.28	
5825	165	11.20	10.85	12.06	

<sup>&</sup>lt;sup>1</sup> Note: This device utilizes independent power reduction mechanisms for the WIFI transmitter in all WIFI modes for held-to-ear scenarios.

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Table 8-48 IEEE 802.11a/n/ac (5GHz, 20MHz BW, MIMO) Reduced Average RF Power<sup>1</sup>

5GHz (20MHz) Conducted Power [dBm]						
Freq [MHz]	Channal	IEEE Transmission Mode				
Freq [MHZ]	Channel	802.11a	802.11n	802.11ac		
5180	36	14.62	14.72	14.57		
5200	40	14.85	14.80	14.75		
5220	44	14.89	14.85	14.73		
5240	48	14.88	14.83	14.89		
5260	52	14.83	14.74	14.95		
5280	56	14.89	14.80	14.92		
5300	60	14.97	14.91	14.95		
5320	64	14.85	14.90	15.05		
5500	100	14.88	14.83	14.48		
5580	116	15.01	15.02	14.47		
5700	140	14.58	14.47	14.89		
5745	149	14.49	14.34	14.94		
5785	157	14.44	14.21	15.01		
5825	165	14.81	14.00	14.75		

Table 8-49
IEEE 802.11n/ac (5GHz, 40MHz BW, SISO) Reduced Average RF Power<sup>1</sup>

5GHz (40MHz) Conducted Power [dBm]				
Freq [MHz]	Channel	IEEE Transmission Mode		
r req [wiriz]	Citatillei	802.11n	802.11ac	
5190	38	11.30	11.25	
5230	46	11.22	11.38	
5270	54	11.38	11.34	
5310	62	11.47	11.36	
5510	102	11.35	11.35	
5590	118	11.48	11.36	
5630	126	11.39	11.49	
5710	142	11.42	11.40	
5755	151	11.49	11.32	
5795	159	11.21	11.36	

<sup>&</sup>lt;sup>1</sup> Note: This device utilizes independent power reduction mechanisms for the WIFI transmitter in all WIFI modes for held-to-ear scenarios.

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Table 8-50 IEEE 802.11n/ac (5GHz, 40MHz BW, MIMO) Reduced Average RF Power<sup>1</sup>

5GHz (40MHz) Conducted Power [dBm]				
Freq [MHz]	Channel	IEEE Transmission Mode		
Treq [MITZ]	Onannei	802.11n	802.11ac	
5190	38	14.25	14.19	
5230	46	14.25	14.34	
5270	54	14.38	14.42	
5310	62	14.43	14.41	
5510	102	14.55	14.44	
5590	118	14.70	14.53	
5630	126	14.60	14.65	
5710	142	14.59	14.51	
5755	151	14.55	14.46	
5795	159	14.33	14.44	

Table 8-51 IEEE 802.11ac (5GHz, 80MHz BW, SISO) Reduced Average RF Power<sup>1</sup>

5GHz (80MHz) Conducted Power [dBm]				
Freq [MHz]	Channel	IEEE Transmission Mode		
		802.11ac		
5210	42	11.61		
5290	58	11.79		
5530	106	11.81		
5610	122	11.71		
5690	138	12.32		
5775	155	12.29		

Table 8-52 IEEE 802.11ac (5GHz, 80MHz BW, MIMO) Reduced Average RF Power<sup>1</sup>

5GHz (80MHz) Conducted Power [dBm]				
Freq [MHz]	Channel	IEEE Transmission Mode		
		802.11ac		
5210	42	15.07		
5290	58	15.11		
5530	106	15.01		
5610	122	14.99		
5690	138	15.18		
5775	155	15.40		

<sup>&</sup>lt;sup>1</sup> Note: This device utilizes independent power reduction mechanisms for the WIFI transmitter in all WIFI modes for held-to-ear scenarios.

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# IX. WIFI Conducted Powers for Operations with Simultaneous 2.4GHz and 5GHz

**Table 8-53** IEEE 802.11b/g/n (2.4GHz, Ant1) Reduced Average RF Power<sup>1</sup>

2.4GHz Conducted Power [dBm]					
Freq [MHz] Channel IEEE Transmission Mode					
Freq [MHZ]	Chamilei	802.11b 802.11g 802.11n			
2412	1	13.08 13.26 13.14			
2437	6	13.22 13.49 13.31			
2462	11	13.46	12.76	13.47	

**Table 8-54** IEEE 802.11b/g/n (2.4GHz, Ant2) Reduced Average RF Power<sup>1</sup>

2.4GHz Conducted Power [dBm]						
Freq [MHz] Channel IEEE Transmission Mode						
rieq [winz]	Chamilei	802.11b 802.11g 802.11n				
2412	1	12.76 12.87 12.66				
2437	6	13.20 13.43 13.27				
2462	11	13.01	13.19	13.12		

**Table 8-55** IEEE 802.11a/n/ac (5GHz, 20MHz BW, Ant1) Reduced Average RF Power<sup>1</sup>

5GHz (20MHz) Conducted Power [dBm]					
Freq [MHz]	Channel	IEEE 1	<b>Fransmission</b>	Mode	
ried [MHZ]	Chamilei	802.11a	802.11n	802.11ac	
5180	36	11.36	11.43	11.38	
5200	40	11.70	11.48	11.45	
5220	44	11.55	11.50	11.27	
5240	48	11.49	11.38	11.43	
5260	52	11.42	11.31	11.47	
5280	56	11.53	11.28	11.36	
5300	60	11.52	11.55	11.30	
5320	64	11.40	11.57	11.55	
5500	100	11.37	11.20	11.27	
5580	116	11.45	11.48	11.24	
5660	132	11.53	11.46	12.17	
5700	140	11.41	11.34	11.97	
5745	149	11.23	11.28	12.19	
5785	157	11.18	11.13	12.28	
5825	165	11.20	10.85	12.06	

<sup>&</sup>lt;sup>1</sup> Note: This device utilizes independent power reduction mechanisms for the WIFI transmitter in all WIFI modes for held-to-ear scenarios.

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Table 8-56
IEEE 802.11a/n/ac (5GHz, 20MHz BW, Ant2) Reduced Average RF Power<sup>1</sup>

5GHz (20MHz) Conducted Power [dBm]					
Freq [MHz]	Channel	IEEE Transmission Mode			
ried [MHZ]	Chamilei	802.11a	802.11n	802.11ac	
5180	36	11.84	11.97	11.74	
5200	40	11.97	12.07	12.02	
5220	44	12.19	12.16	12.12	
5240	48	12.21	12.22	12.28	
5260	52	12.18	12.12	12.36	
5280	56	12.21	12.25	12.39	
5300	60	12.36	12.23	12.49	
5320	64	12.23	12.18	12.48	
5500	100	12.32	12.37	11.66	
5580	116	12.48	12.49	11.67	
5660	132	12.49	11.58	11.92	
5700	140	11.72	11.57	11.79	
5745	149	11.71	11.38	11.65	
5785	157	11.66	11.27	11.71	
5825	165	12.33	11.13	11.40	

Table 8-57
IEEE 802.11n/ac (5GHz, 40MHz BW, Ant1) Reduced Average RF Power<sup>1</sup>

5GHz (40MHz) Conducted Power [dBm]					
Freq [MHz]	Channel	IEEE Transm	smission Mode		
i req [wiriz]	Chamilei	802.11n 80	802.11ac		
5190	38	11.30	11.25		
5230	46	11.22	11.38		
5270	54	11.38	11.34		
5310	62	11.47	11.36		
5510	102	11.35	11.35		
5590	118	11.48	11.36		
5630	126	11.39	11.49		
5710	142	11.42	11.40		
5755	151	11.49	11.32		
5795	159	11.21	11.36		

<sup>&</sup>lt;sup>1</sup> Note: This device utilizes independent power reduction mechanisms for the WIFI transmitter in all WIFI modes for held-to-ear scenarios.

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**Table 8-58** IEEE 802.11n/ac (5GHz, 40MHz BW, Ant2) Reduced RF Power<sup>1</sup>

5GHz (40MHz) Conducted Power [dBm]					
Freq [MHz]	Channel	IEEE Transm	ission Mode		
Treq [MITZ]	Citatille	802.11n 802.11	802.11ac		
5190	38	11.18	11.11		
5230	46	11.25	11.27		
5270	54	11.36	11.47		
5310	62	11.37	11.43		
5510	102	11.73	11.50		
5590	118	11.89	11.68		
5630	126	11.79	11.79		
5710	142	11.73	11.60		
5755	151	11.59	11.58		
5795	159	11.42	11.50		

**Table 8-59** IEEE 802.11ac (5GHz, 80MHz BW, Ant1) Reduced RF Power<sup>1</sup>

5GHz (80MHz) Conducted Power [dBm]				
Freq [MHz]	Channel	IEEE Transmission Mode		
		802.11ac		
5210	42	11.61		
5290	58	11.79		
5530	106	11.81		
5610	122	11.71		
5690	138	12.32		
5775	155	12.29		

**Table 8-60** IEEE 802.11ac (5GHz, 80MHz BW, Ant2) Reduced RF Power<sup>1</sup>

5GHz (80MHz) Conducted Power [dBm]					
Freq [MHz]	Channel	IEEE Transmission Mode			
ried [ivinz]	Chamilei	802.11ac			
		Average			
5210	42	12.46			
5290	58	12.38			
5530	106	12.18			
5610	122	12.24			
5690	138	12.01			
5775	155	12.49			

<sup>&</sup>lt;sup>1</sup> Note: This device utilizes independent power reduction mechanisms for the WIFI transmitter in all WIFI modes for held-to-ear scenarios.

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# 9. JUSTIFICATION OF HELD TO EAR MODES TESTED

# I. Analysis of RF Air Interface Technologies

An analysis was performed, following the guidance of §4.3 and §4.4 of the ANSI standard, of the RF air interface technologies being evaluated. The factors that will affect the RF interference potential were evaluated, and the worst case operating modes were identified and used in the evaluation. A WD's interference potential is a function both of the WD's average near-field field strength and of the signal's audio-frequency amplitude modulation characteristics. Per §4.4, RF air interface technologies that have low power have been found to produce sufficiently low RF interference potential, so it is possible to exempt them from the product testing specified in Clause 5 of the ANSI standard. An RF air interface technology of a device is exempt from testing when its average antenna input power plus its MIF is ≤17dBm for all of its operating modes. RF air interface technologies exempted from testing in this manner are automatically assigned an M4 rating to be used in determining the overall rating for the WD.

The worst case MIF plus the worst case average antenna input power for all modes are investigated below to determine the testing requirements for this device.

### II. Individual Mode Evaluations

Table 9-1
Max Power + MIF calculations for Low Power Exemptions

Air Interface	Maximum Average Power (dBm)	Worst Case MIF (dB)	Total (Power + MIF, dB)	C63.19 Testing Required
CDMA - RC1/SO55 Full Frame Rate	25.12	-19.35	5.77	No
CDMA - RC1/SO3 1/8 <sup>th</sup> Frame Rate	16.03*	3.07	19.10	Yes
CDMA - EvDO RevA	25.15	-19.05	6.10	No
GSM850	23.91*	3.56	27.47	Yes
GSM1900	20.69*	3.56	24.25	Yes
EDGE850	17.63*	3.76	21.39	Yes***
EDGE1900	16.71*	3.53	20.24	Yes***
UMTS - RMC	24.99	-21.99	3.00	No
UMTS - AMR	24.97	-15.02	9.95	No
UMTS - HSUPA	23.57	-21.25	2.32	No
LTE - FDD	24.78	-8.96	15.82	No
LTE - TDD (PC3)	17.72*	1.64	19.36	Yes
LTE - TDD (PC2)	20.79*	1.67	22.46	Yes
2.4GHz WIFI	16.47	-4.76	11.71	No
5GHz WIFI	15.40	-10.65	4.75	No
Simultaneous 2.4GHz and 5GHz WIFI Operations	18.99**	-5.10	13.89	No

<sup>\*</sup> Note: ANSI C63.19-2011 Sec. 4.4 Footnote 20 indicates the use of a long averaging time for measuring the antenna input power when using this method of exclusion. Therefore, the frame averaged power was calculated for these modes in this investigation.

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- \*\* Note: This value is calculated as the linear sum of the worst-case power for each band and antenna combination while in simultaneous 2.4GHz and 5GHz operation. This calculation is conservative and for use in this investigation only.
- \*\*\* Note: GSM data modes were not evaluated as GSM voice modes were found to be the worst-case modes for the GSM air interface.

## **III. Low-Power Exemption Conclusions**

Per ANSI C63.19-2011, RF Emissions testing for this device is required only for GSM and 1/8<sup>th</sup> Frame Rate CDMA voice modes as well as LTE TDD (Power Class 3 and Power Class 2) data modes. All other air interfaces are exempt.

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#### 10. LTE TDD UPLINK-DOWNLINK CONFIGURATION

# I. Uplink-Downlink Configuration Additional Testing

An investigation was performed on each supported power class for LTE TDD to determine the worstcase Uplink-Downlink configuration for RFE testing.

Per 3GPP TS 36.211, the total frame length for each TDD radio frame of length  $T_f = 307200 \cdot T_s = 10$ ms, where T<sub>s</sub> is a number of time units equal to 1/(15000 x 2048) seconds. Additionally, each radio frame consists of 10 subframes, each of length  $30720 \cdot T_s = 1$  ms, and subframes can be designated as uplink (U), downlink (D), or special subframe (S), depending on the Uplink-Downlink configuration as indicated in Table 4.2-2 of 3GPP TS 36.211. In the transmission duty factor calculation, the special subframe configuration with the shortest UpPTS duration within the special subframe is used and will be applied for measurement. From 3GPP TS 36.211 Table 4.2-1, the shortest UpPTS is 2192 · Ts which occurs in the normal cyclic prefix and special subframe configuration 4.

See table below outlining the calculated transmission duty cycles for each Uplink-Downlink configuration:

> **Table 10-1** Unlink-Downlink Configurations for Type 2 Frame Structures

Uplink-downlink configuration	Downlink-to-Uplink Switch-point periodicity				Su	bfram	e numb	oer				Calculated Transmission
configuration	Switch-point periodicity	0	1	2	3	4	5	6	7	8	9	Duty Cycle (%)
0	5 ms	D	S	U	U	U	D	S	U	U	U	61.4%
1	5 ms	D	S	U	U	D	D	S	U	U	D	41.4%
2	5 ms	D	S	U	D	D	D	S	U	D	D	21.4%
3	10 ms	D	S	U	U	U	D	D	D	D	D	30.7%
4	10 ms	D	S	U	U	D	D	D	D	D	D	20.7%
5	10 ms	D	S	U	D	D	D	D	D	D	D	10.7%
6	5 ms	D	S	U	U	U	D	S	U	U	D	51.4%

# II. Power Class 3 Uplink-Downlink Configuration Additional Testing

Power Class 3 was evaluated with the following radio configuration: channel 40620, 20MHz BW, 16QAM, 1RB, 0RB Offset. For Power Class 3, all configurations (0-6) are supported. The configuration which resulted in the worst-case emissions was used for full testing. See Table 10-2 below for investigation results. The configuration determined in the investigation below was used to measure the MIF values in Table 7-5.

> **Table 10-2** LTE TDD Power Class 3 UL-DL Configuration Investigation Results

Mode / Band	Power Class	Bandwidth	Channel	UL-DL Config.		RB Size	RB Offset	Scan Center	Time Avg. Field (V/m)	Time Avg. Field [dB(V/m)]	MIF (dB)	Audio Interference Level [dB(V/m)]	FCC Limit (dBV/m)	FCC Margin (dB)	Result	Excl Blocks per 5.5
E-Field Emissi	ions															
		20	40620	0	16QAM	1	0	Acoustic	17.64	24.93	-3.17	21.76	35.00	-13.24	M4	none
		20	40620	1	16QAM	1	0	Acoustic	14.13	23.00	-1.57	21.43	35.00	-13.57	M4	none
		20	40620	2	16QAM	1	0	Acoustic	10.42	20.36	1.60	21.96	35.00	-13.04	M4	none
LTE TDD / Band 41	3	20	40620	3	16QAM	1	0	Acoustic	12.96	22.25	-1.29	20.96	35.00	-14.04	M4	none
		20	40620	4	16QAM	1	0	Acoustic	10.39	20.33	0.71	21.04	35.00	-13.96	M4	none
		20	40620	5	16QAM	1	0	Acoustic	7.62	17.63	3.58	21.21	35.00	-13.79	M4	none
		20	40620	6	16QAM	1	0	Acoustic	15.70	23.92	-2.45	21.47	35.00	-13.53	M4	none

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# III. Power Class 2 Uplink-Downlink Configuration Additional Testing

Power Class 2 was evaluated with the following radio configuration: channel 40620, 20MHz BW, 16QAM, 1RB, 0RB Offset. For Power Class 2, only configurations 1-5 are supported. The configuration which resulted in the worst-case emissions was used for full testing. See Table 10-3 below for investigation results. The configuration determined in the investigation below was used to measure the MIF values in Table 7-6.

Table 10-3

LTE TDD Power Class 2 UL-DL Configuration Investigation Results

Mode / Band	Class	Bandwidth	Channel	UL-DL Config.	Mod.	RB Size	RB Offset	Scan Center	Time Avg. Field (V/m)	Time Avg. Field [dB(V/m)]	MIF (dB)	Audio Interference Level [dB(V/m)]	FCC Limit (dBV/m)	FCC Margin (dB)	Result	Excl Blocks per 5.5
E-Field Emissi	ions															
		20	40620	1	16QAM	1	0	Acoustic	15.61	23.87	-1.55	22.32	35.00	-12.68	M4	none
		20	40620	2	16QAM	1	0	Acoustic	11.23	21.01	1.65	22.66	35.00	-12.34	M4	none
LTE TDD / Band 41	2	20	40620	3	16QAM	1	0	Acoustic	13.31	22.48	-1.28	21.20	35.00	-13.80	M4	none
		20	40620	4	16QAM	1	0	Acoustic	11.24	21.02	0.75	21.77	35.00	-13.23	M4	none
		20	40620	5	16QAM	1	0	Acoustic	7.94	18.00	3.69	21.69	35.00	-13.31	M4	none

### **IV. Conclusion**

Per the investigations above, UL-DL Configuration 2 was used for both LTE TDD Power Class 3 and LTE TDD Power Class 2 testing.

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# 11. OVERALL MEASUREMENT SUMMARY

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## I. E-FIELD EMISSIONS:

# Table 11-1 HAC Data Summary for CDMA E-field

	TIAO Data Gammary for Oblita E-ficia													
Mode	Channel	RC/SO	Scan Center	Conducted Power at BS (dBm)	Time Avg. Field (V/m)	Time Avg. Field [dB(V/m)]	MIF (dB)	Audio Interference Level [dB(V/m)]	FCC Limit (dBV/m)	FCC Margin (dB)	Result	Excl Blocks per 5.5		
E-Field Emissi	ions													
	564*	RC1/SO3	Acoustic	25.06	15.84	23.99	3.07	27.06	45.00	-17.94	M4	none		
Cellular	1013	RC1/SO3	Acoustic	24.54	14.43	23.19	3.03	26.22	45.00	-18.78	M4	none		
CDMA	384	RC1/SO3	Acoustic	24.69	14.44	23.19	3.04	26.23	45.00	-18.77	M4	none		
	777	RC1/SO3	Acoustic	24.73	13.92	22.87	3.06	25.93	45.00	-19.07	M4	none		
	25	RC1/SO3	Acoustic	24.17	8.77	18.86	3.06	21.92	35.00	-13.08	M4	none		
PCS CDMA	600	RC1/SO3	Acoustic	24.30	10.60	20.50	3.04	23.54	35.00	-11.46	M4	none		
	1175	RC1/SO3	Acoustic	24.22	7.63	17.65	3.06	20.71	35.00	-14.29	M4	none		

<sup>\*</sup> Note: Cell. CDMA ch.564 is the Part 90S test channel.

Table 11-2
HAC Data Summary for GSM F-field

			П	4C Data	Summa	ry for G	2IM F-LIG	Ia			
Mode	Channel	Scan Center	Conducted Power at BS (dBm)	Time Avg. Field (V/m)	Time Avg. Field [dB(V/m)]	MIF (dB)	Audio Interference Level [dB(V/m)]	FCC Limit (dBV/m)	FCC Margin (dB)	Result	Excl Blocks per 5.5
E-Field Emissi	ons										
	128	Acoustic	32.86	35.17	30.92	3.56	34.48	45.00	-10.52	M4	none
GSM850	190	Acoustic	32.81	37.96	31.59	3.56	35.15	45.00	-9.85	M4	none
	251	Acoustic	32.94	34.39	30.73	3.56	34.29	45.00	-10.71	M4	none
	512	Acoustic	29.65	13.31	22.48	3.56	26.04	35.00	-8.96	M4	none
GSM1900	661	Acoustic	29.72	15.54	23.83	3.56	27.39	35.00	-7.61	M4	none
GSWITHOU	810	Acoustic	29.68	12.42	21.88	3.56	25.44	35.00	-9.56	M4	none
	661	T-Coil	29.72	15.54	23.83	3.56	27.39	35.00	-7.61	M4	none

# Table 11-3 HAC Data Summary for LTE TDD Power Class 3 E-field

	111 to Data Carrinia, y 101 212 122 1 01101 01000 0 2 11010																
Mode / Band	Power Class	Bandwidth	Channel	UL-DL Config.	Mod.	RB Size	RB Offset	Scan Center	Conducted Power at BS (dBm)	Time Avg. Field (V/m)	Time Avg. Field [dB(V/m)]	MIF (dB)	Audio Interference Level [dB(V/m)]	FCC Limit (dBV/m)	FCC Margin (dB)	Result	Excl Blocks per 5.5
E-Field Emissi	ions																
		20	39750	2	16QAM	1	0	Acoustic	23.50	8.68	18.77	1.64	20.41	35.00	-14.59	M4	none
		20	40185	2	16QAM	1	0	Acoustic	23.50	8.89	18.98	1.62	20.60	35.00	-14.40	M4	none
LTE TDD / Band 41	3	20	40620	2	16QAM	1	0	Acoustic	23.20	9.41	19.47	1.63	21.10	35.00	-13.90	M4	none
		20	41055	2	16QAM	1	0	Acoustic	23.45	8.42	18.51	1.62	20.13	35.00	-14.87	M4	none
		20	41490	2	16QAM	1	0	Acoustic	23.50	7.71	17.74	1.63	19.37	35.00	-15.63	M4	none

# Table 11-4 HAC Data Summary for LTE TDD Power Class 2 E-field

	Three Batta Galliniary for ETE 1881 office Glaco E E fiola																
Mode / Band	Power Class	Bandwidth	Channel	UL-DL Config.	Mod.	RB Size	RB Offset	Scan Center	Conducted Power at BS (dBm)	Time Avg. Field (V/m)	Time Avg. Field [dB(V/m)]	MIF (dB)	Audio Interference Level [dB(V/m)]	FCC Limit (dBV/m)	FCC Margin (dB)	Result	Excl Blocks per 5.5
E-Field Emissi	ions																
		5	39750	2	16QAM	1	0	Acoustic	26.27	9.43	19.49	1.66	21.15	35.00	-13.85	M4	none
		5	40185	2	16QAM	1	0	Acoustic	26.47	9.56	19.60	1.67	21.27	35.00	-13.73	M4	none
LTE TDD / Band 41	2	5	40620	2	16QAM	1	0	Acoustic	26.49	10.10	20.08	1.67	21.75	35.00	-13.25	M4	none
		5	41055	2	16QAM	1	0	Acoustic	26.12	8.70	18.79	1.65	20.44	35.00	-14.56	M4	none
		5	41490	2	16QAM	1	0	Acoustic	26.02	8.00	18.06	1.65	19.71	35.00	-15.29	M4	none

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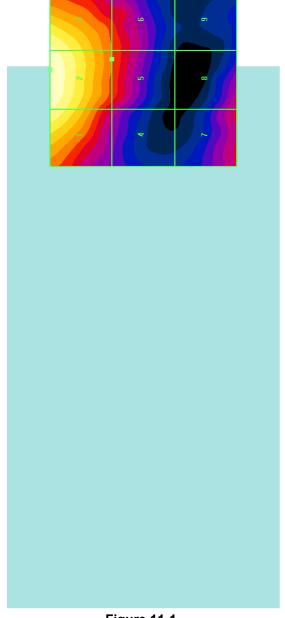


Figure 11-1
Sample E-field Scan Overlay
(See Test Setup Photographs for actual WD overlay)

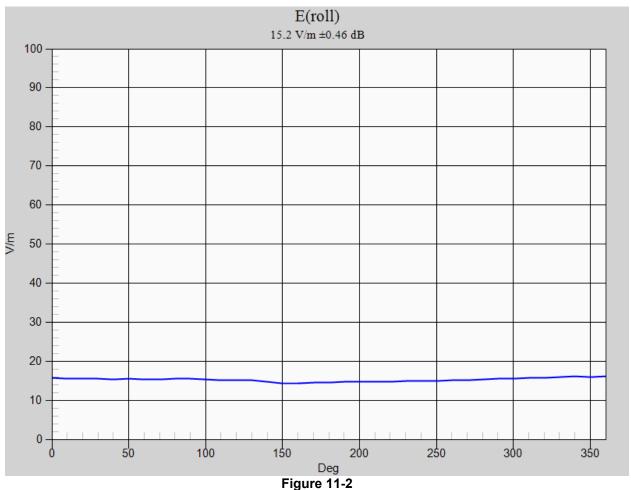
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# II. Worst-case Configuration Evaluation

Table 11-5
Peak Reading 360° Probe Rotation at Azimuth axis

		FU	an Neauli	ig sour F	IODE VOI	alion al A	Ziiiiuuii a	XI2		
Mode	Channel	Scan Center	Time Avg. Field (V/m)	Time Avg. Field [dB(V/m)]	MIF (dB)	Audio Interference Level [dB(V/m)]	FCC Limit (dBV/m)	FCC Margin (dB)	Result	Excl Blocks per 5.5
Probe Rotatio	Probe Rotation at Worst-Case									
GSM1900	661	Acoustic	16.05	24.11	3.56	27.67	35.00	-7.33	M4	none



Worst-Case Probe Rotation about Azimuth axis

<sup>\*</sup> Note: Locations of probe rotation (with and without exclusions) are shown in Figure 11-1 denoted by the green square markers.

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#### **EQUIPMENT LIST** 12.

## **Table 12-1 Equipment List**

Manufacturer	Model	Description	Cal Date	Cal Interval	Cal Due	Serial Number
Agilent	E4438C	ESG Vector Signal Generator	3/24/2017	Biennial	3/24/2019	MY42082385
Agilent	E4432B	ESG-D Series Signal Generator	3/24/2017	Annual	3/24/2018	US40053896
Agilent	N5182A	MXG Vector Signal Generator	2/28/2017	Annual	2/28/2018	MY47420800
Amplifier Research	15S1G6	Amplifier	N/A	CBT*	N/A	433978
Anritsu	ML2496A	Power Meter	4/20/2017	Annual	4/20/2018	1306009
Anritsu	MA2411B	Pulse Power Sensor	2/10/2017	Annual	2/10/2018	1207364
Anritsu	MA2411B	Pulse Power Sensor	2/10/2017	Annual	2/10/2018	1339018
Anritsu	MA24106A	USB Power Sensor	6/7/2017	Annual	6/7/2018	1244512
Anritsu	MA24106A	USB Power Sensor	6/7/2017	Annual	6/7/2018	1248508
Anritsu	MT8821C	Radio Communication Analyzer	8/15/2017	Annual	8/15/2018	6200901190
Mini-Circuits	NLP-1200+	Low Pass Filter DC to 1000 MHz	N/A	CBT*	N/A	N/A
Mini-Circuits	NLP-2950+	Low Pass Filter DC to 2700 MHz	N/A	CBT*	N/A	N/A
Mini-Circuits	BW-N20W5	Power Attenuator	N/A	CBT*	N/A	1226
Pasternack	PE2237-20	Bidirectional Coupler	N/A	CBT*	N/A	N/A
Rohde & Schwarz	CMU200	Base Station Simulator	4/11/2017	Annual	4/11/2018	836371/0079
Rohde & Schwarz	CMU200	Base Station Simulator	12/12/2016	Annual	12/12/2017	833855/0010
Rohde & Schwarz	CMW500	Radio Communication Tester	4/12/2017	Annual	4/12/2018	128635
Seekonk	NC-100	Torque Wrench (8" lb)	9/1/2016	Biennial	9/1/2018	21053
SPEAG	AIA	Audio Interference Analzyer	N/A	CBT*	N/A	1010
SPEAG	DAE4	Dasy Data Acquisition Electronics	5/17/2017	Annual	5/17/2018	859
SPEAG	CD1880V3	Freespace 1880 MHz Dipole	5/12/2016	Biennial	5/12/2018	1064
SPEAG	CD2600V3	Freespace 2600 MHz Dipole	6/14/2017	Biennial	6/14/2019	1013
SPEAG	CD835V3	Freespace 835 MHz Dipole	5/10/2016	Biennial	5/10/2018	1082
SPEAG	ER3DV6	Freespace E-field Probe	1/16/2017	Annual	1/16/2018	2353

Calibration traceable to the National Institute of Standards and Technology (NIST).

\*Note: CBT (Calibrated Before Testing). Prior to testing, the measurement paths containing a cable, attenuator, coupler or filter were connected to a calibrated source (i.e. a signal generator) to determine the losses of the measurement path. The power meter offset was then adjusted to compensate for the measurement system losses. This level offset is stored within the power meter before measurements are made. This calibration verification procedure applies to the system verification and output power measurements. The calibrated reading is then taken directly from the power meter after compensation of the losses for all final power measurements.

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## 13. MEASUREMENT UNCERTAINTY

# Table 13-1 Uncertainty Estimation Table

		Communication					
		Uncert	ainty Estima	ation			
Uncertainty Component	Data (dB)	Data Type	Prob. Dist.	Divisor	Ci (E)	Unc. (dB)	Notes/Comments
Measurement System						-	
RF System Reflections	0.50	Tolerance	N	1.00	1	0.50	* Refl. < -20 dB
Field Probe Calibration	0.21	Tolerance	N	1.00	1	0.21	
Field Probe Isotropy	0.01	Tolerance	N	1.00	1	0.01	
Field Probe Frequency Response	0.135	Tolerance	N	1.00	1	0.14	
Field Probe Linearity	0.013	Tolerance	N	1.00	1	0.01	
Modulation Interference Factor	0.20	Tolerance	R	1.73	1	0.12	Applicable for M-rating testing
Boundary Effects	0.105	Accuracy	R	1.73	1	0.06	*
Probe Positioning Accuracy	0.20	Accuracy	R	1.73	1	0.12	*
Probe Positioner	0.050	Accuracy	R	1.73	1	0.03	*
Extrapolation/Interpolation	0.045	Tolerance	R	1.73	1	0.03	*
Resolution to 2mm error	0.21	Tolerance	N	1.00	1	0.21	
System Detection Limit	0.05	Tolerance	R	1.73	1	0.03	*
Readout Electronics	0.015	Tolerance	N	1.00	1	0.02	*
Integration Time	0.11	Tolerance	R	1.73	1	0.06	*
Response Time	0.033	Tolerance	R	1.73	1	0.02	*
Phantom Thickness	0.10	Tolerance	R	1.73	1	0.06	*
System Repeatability (Field x 2=power)	0.17	Tolerance	N	1.00	1	0.17	*
Test Sample Related							
Device Positioning Vertical	0.2	Tolerance	R	1.73	1	0.12	*
Device Positioning Lateral	0.045	Tolerance	R	1.73	1	0.03	*
Device Holder and Phantom	0.1	Tolerance	R	1.73	1	0.06	*
Power Drift	0.21	Tolerance	R	1.73	1	0.12	
Combined Standard Uncertainty (k=1)						0.66	16.3%
Expanded Uncertainty [95% confidence]						1.31	32.6%
Expanded Uncertainty [95% confidence]	on Field					0.66	16.3%

### Notes:

- Test equipments are calibrated according to techniques outlined in NIS81, NIS3003 and NIST Tech Note 1297. All
  equipments have traceability according to NIST. Measurement Uncertainties are defined in further detail in NIS 81
  and NIST Tech Note 1297 and UKAS M3003.
- 2. \* Uncertainty specifications from Schmidt & Partner Engineering AG (not site specific)

Measurement uncertainty reflects the quality and accuracy of a measured result as compared to the true value. Such statements are generally required when stating results of measurements so that it is clear to the intended audience that the results may differ when reproduced by different facilities. Measurement results vary due to the measurement uncertainty of the instrumentation, measurement technique, and test engineer. Most uncertainties are calculated using the tolerances of the instrumentation used in the measurement, the measurement setup variability, and the technique used in performing the test. While not generally included, the variability of the equipment under test also figures into the overall measurement uncertainty. Another component of the overall uncertainty is based on the variability of repeated measurements (so-called Type A uncertainty). This may mean that the Hearing Aid immunity tests may have to be repeated by taking down the test setup and resetting it up so that there are a statistically significant number of repeat measurements to identify the measurement uncertainty. By combining the repeat measurement results with that of the instrumentation chain using the technique contained in NIS 81 and NIS 3003, the overall measurement uncertainty was estimated.

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# 14. TEST DATA

See following Attached Pages for Test Data.

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## DUT: CD835V3 - SN1082

Type: CD835V3 Serial: 1082

#### Communication System: CW; Frequency: 835 MHz;

Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2011)

#### DASY5 Configuration:

- Probe: ER3DV6 SN2353; Calibrated: 1/16/2017;
- · Sensor-Surface: 0mm (Fix Surface)
- Electronics: DAE4 Sn859; Calibrated: 5/17/2017
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, Version 52.10 (0);

#### 835 MHz / 100mW HAC Dipole Validation at 15mm/Hearing Aid Compatibility Test (41x361x1):

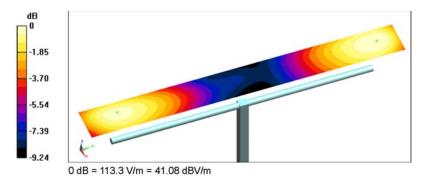
Interpolated grid: dx=0.5000 mm, dy=0.5000 mm

Device Reference Point: 0, 0, -6.3 mm

Reference Value = 120.4 V/m; Power Drift = -0.05 dB

Applied MIF = 0.00 dB

Average Value of Peak (interpolated) = 111.6 V/m



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#### DUT: CD1880V3 - SN1064

Type: CD1880V3 Serial: 1064

#### Communication System: CW; Frequency: 1880 MHz;

Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2011)

#### DASY5 Configuration:

- Probe: ER3DV6 SN2353; Calibrated: 1/16/2017;
- · Sensor-Surface: 0mm (Fix Surface)
- Electronics: DAE4 Sn859; Calibrated: 7/21/2009
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, Version 52.10 (0);

#### 1880 MHz / 100mW HAC Dipole Validation at 15mm/Hearing Aid Compatibility Test (41x181x1):

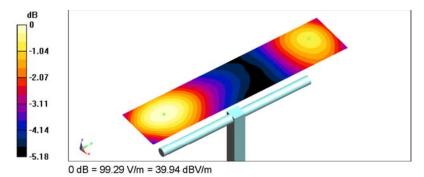
Interpolated grid: dx=0.5000 mm, dy=0.5000 mm

Device Reference Point: 0, 0, -6.3 mm

Reference Value = 161.3 V/m; Power Drift = 0.03 dB

Applied MIF = 0.00 dB

Average Value of Peak (interpolated) = 95.3 V/m



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## DUT: CD2600V3 - SN1013

Type: CD2600V3 Serial: 1013

#### Communication System: CW; Frequency: 2600 MHz;

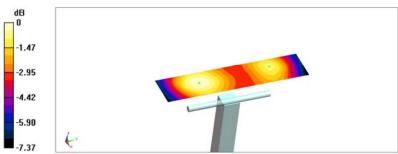
Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2011)

#### DASY5 Configuration:

- Probe: ER3DV6 SN2353; Calibrated: 1/16/2017;
- Sensor-Surface: 0mm (Fix Surface)
- Electronics: DAE4 Sn859; Calibrated: 7/21/2009
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, Version 52.10 (0);

#### 2600 MHz / 100mW HAC Dipole Validation at 15mm/Hearing Aid Compatibility Test (41x181x1):

Interpolated grid: dx=0.5000 mm, dy=0.5000 mm
Device Reference Point: 0, 0, -6.3 mm
Reference Value = 68.38 V/m; Power Drift = 0.01 dB
Applied MIF = 0.00 dB
Average Value of Peak (interpolated) = 89.7 V/m



0 dB = 94.06 V/m = 39.47 dBV/m

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## **DUT: A3LSMG965U**

Type: Portable Handset Serial: 37046 Backlight off Duty Cycle: 1:8

#### Communication System: CDMA; Frequency: 820.1 MHz;

Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2011)

#### DASY5 Configuration:

- Probe: ER3DV6 SN2353; Calibrated: 1/16/2017;
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn859; Calibrated: 5/17/2017
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, Version 52.10 (0);

#### Extended Cellular CDMA Mid Channel / Hearing Aid Compatibility Test (101x101x1):

Interpolated grid: dx=0.5000 mm, dy=0.5000 mm

Device Reference Point: 0, 0, -6.3 mm

Reference Value = 20.01 V/m; Power Drift = -0.07 dB

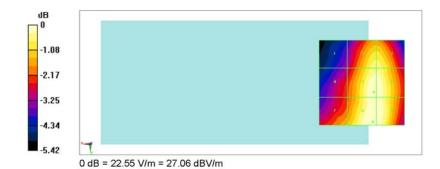
Applied MIF = 3.07 dB

RF audio interference level = 27.06 dBV/m

Emission category: M4

#### MIF scaled E-field

Grid 1 <b>M4</b>	Grid 2 M4	Grid 3 M4
23.95 dBV/m	26.56 dBV/m	26.56 dBV/m
Grid 4 <b>M4</b>	Grid 5 M4	Grid 6 M4
24.84 dBV/m	27.05 dBV/m	27.02 dBV/m
Grid 7 <b>M4</b>	Grid 8 <b>M4</b>	Grid 9 <b>M4</b>
25.77 dBV/m	27.06 dBV/m	27.04 dBV/m



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## **DUT: A3LSMG965U**

Type: Portable Handset Serial: 37046 Backlight off Duty Cycle: 1:8

#### Communication System: CDMA; Frequency: 1880 MHz;

Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2011)

#### DASY5 Configuration:

- Probe: ER3DV6 SN2353; Calibrated: 1/16/2017;
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn859; Calibrated: 5/17/2017
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, Version 52.10 (0);

#### PCS CDMA Mid Channel / Hearing Aid Compatibility Test (101x101x1):

Interpolated grid: dx=0.5000 mm, dy=0.5000 mm
Device Reference Point: 0, 0, -6.3 mm
Reference Value = 6.997 V/m; Power Drift = 0.03 dB
Applied MIF = 3.04 dB
RF audio interference level = 23.54 dBV/m
Emission category: M4

#### MIF scaled E-field

Grid 1 <b>M4</b>	Grid 2 M4	Grid 3 M4
22.62 dBV/m	23.54 dBV/m	22.01 dBV/m
Grid 4 <b>M4</b>	Grid 5 M4	Grid 6 M4
19.27 dBV/m	19.65 dBV/m	19.51 dBV/m
Grid 7 <b>M4</b>	Grid 8 <b>M4</b>	Grid 9 <b>M4</b>
20.04 dBV/m	18.79 dBV/m	17.76 dBV/m



0 dB = 15.04 V/m = 23.54 dBV/m

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## **DUT: A3LSMG965U**

Type: Portable Handset Serial: 37046 Backlight off Duty Cycle: 1:8.3

#### Communication System: GSM; Frequency: 836.6 MHz;

Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2011)

#### DASY5 Configuration:

- Probe: ER3DV6 SN2353; Calibrated: 1/16/2017;
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn859; Calibrated: 5/17/2017
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, Version 52.10 (0);

#### GSM850 Mid Channel / Hearing Aid Compatibility Test (101x101x1):

Interpolated grid: dx=0.5000 mm, dy=0.5000 mm

Device Reference Point: 0, 0, -6.3 mm

Reference Value = 42.40 V/m; Power Drift = 0.07 dB

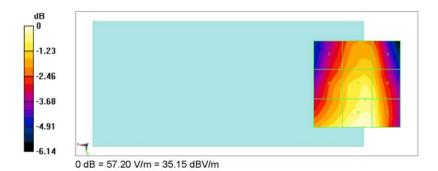
Applied MIF = 3.56 dB

RF audio interference level = 35.15 dBV/m

Emission category: M4

#### MIF scaled E-field

Grid 1 M4	Grid 2 M4	Grid 3 M4
32.95 dBV/m	33.84 dBV/m	33.65 dBV/m
Grid 4 <b>M4</b>	Grid 5 M4	Grid 6 M4
33.67 dBV/m	34.51 dBV/m	34.4 dBV/m
Grid 7 <b>M4</b>	Grid 8 M4	Grid 9 <b>M4</b>
34.54 dBV/m	35.15 dBV/m	34.94 dBV/m



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## **DUT: A3LSMG965U**

Type: Portable Handset Serial: 37046 Backlight off Duty Cycle: 1:8.3

#### Communication System: GSM; Frequency: 1880 MHz;

Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2011)

#### DASY5 Configuration:

- Probe: ER3DV6 SN2353; Calibrated: 1/16/2017;
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn859; Calibrated: 5/17/2017
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, Version 52.10 (0);

#### GSM1900 Mid Channel / Hearing Aid Compatibility Test (101x101x1):

Interpolated grid: dx=0.5000 mm, dy=0.5000 mm

Device Reference Point: 0, 0, -6.3 mm

Reference Value = 10.24 V/m; Power Drift = -0.05 dB

Applied MIF = 3.56 dB

RF audio interference level = 27.39 dBV/m

Emission category: M4

#### MIF scaled E-field

Grid 1 <b>M4</b>	Grid 2 M4	Grid 3 M4
26.83 dBV/m	27.39 dBV/m	27.01 dBV/m
Grid 4 M4	Grid 5 M4	Grid 6 M4
22.3 dBV/m	23.67 dBV/m	23.63 dBV/m
Grid 7 <b>M4</b>	Grid 8 <b>M4</b>	Grid 9 <b>M4</b>
22.59 dBV/m	22.51 dBV/m	20.42 dBV/m



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### **DUT: A3LSMG965U**

Type: Portable Handset Serial: 37046 Backlight off Duty Cycle: 1:4.67

#### Communication System: LTE TDD41; Frequency: 2593 MHz;

Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2011)

#### DASY5 Configuration:

- Probe: ER3DV6 SN2353; Calibrated: 1/16/2017;
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn859; Calibrated: 5/17/2017
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, Version 52.10 (0);

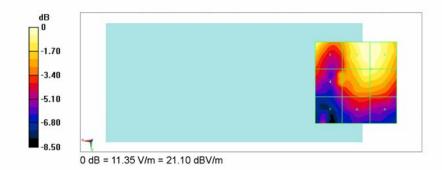
#### Power Class 3 TDD LTE Band 41 Mid Channel, 20MHz BW, 16QAM, 1RB, 0 RB Offset

#### **Hearing Aid Compatibility Test (101x101x1):**

Interpolated grid: dx=0.5000 mm, dy=0.5000 mm
Device Reference Point: 0, 0, -6.3 mm
Reference Value = 8.576 V/m; Power Drift = -0.09 dB
Applied MIF = 1.63 dB
RF audio interference level = 21.10 dBV/m
Emission category: M4

#### MIF scaled E-field

Grid 1 <b>M4</b>	Grid 2 M4	Grid 3 M4
20.92 dBV/m	21.1 dBV/m	21.02 dBV/m
Grid 4 M4	Grid 5 M4	Grid 6 M4
18.66 dBV/m	20.42 dBV/m	20.43 dBV/m
Grid 7 <b>M4</b>	Grid 8 <b>M4</b>	Grid 9 <b>M4</b>
16.44 dBV/m	17.7 dBV/m	17.55 dBV/m



#### PCTEST 2017

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## DUT: A3LSMG965U

Type: Portable Handset Serial: 37046 Backlight off Duty Cycle: 1:4.67

#### Communication System: LTE TDD41; Frequency: 2593 MHz;

Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2011)

#### DASY5 Configuration:

- Probe: ER3DV6 SN2353; Calibrated: 1/16/2017;
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn859; Calibrated: 5/17/2017
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, Version 52.10 (0);

# Power Class 2 TDD LTE Band 41 Mid Channel, 5MHz BW, 16QAM, 1RB, 0 RB Offset

#### **Hearing Aid Compatibility Test (101x101x1):**

Interpolated grid: dx=0.5000 mm, dy=0.5000 mm

Device Reference Point: 0, 0, -6.3 mm

Reference Value = 9.502 V/m; Power Drift = -0.14 dB

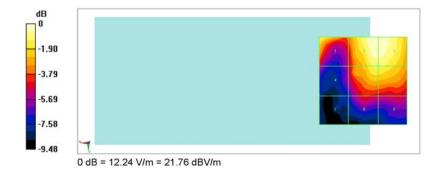
Applied MIF = 1.67 dB

RF audio interference level = 21.75 dBV/m

Emission category: M4

### MIF scaled E-field

Grid 1 <b>M4</b>	Grid 2 M4	Grid 3 <b>M4</b>
20.67 dBV/m	21.75 dBV/m	21.73 dBV/m
Grid 4 <b>M4</b>	Grid 5 M4	Grid 6 M4
17.02 dBV/m	20.64 dBV/m	20.64 dBV/m
Grid 7 <b>M4</b>	Grid 8 <b>M4</b>	Grid 9 <b>M4</b>



#### PCTEST 2017

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# 15. CALIBRATION CERTIFICATES

The following pages include the probe calibration used to evaluate HAC for the DUT.

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Certificate No: ER3-2353\_Jan17

**CALIBRATION CERTIFICATE** 

Object ER3DV6 - SN:2353

PC Test

Client

Calibration procedure(s) QA CAL-02.v8, QA CAL-25.v6

Calibration procedure for E-field probes optimized for close near field

evaluations in air

Calibration date: January 16, 2017

This calibration certificate documents the traceability to national standards, which realize the physical units of measurements (SI).
The measurements and the uncertainties with confidence probability are given on the following pages and are part of the certificate.

All calibrations have been conducted in the closed laboratory facility: environment temperature (22 ± 3)°C and humidity < 70%.

Calibration Equipment used (M&TE critical for calibration)

Primary Standards	ID	Cal Date (Certificate No.)	Scheduled Calibration
Power meter NRP	SN: 104778	06-Apr-16 (No. 217-02288/02289)	Apr-17
Power sensor NRP-Z91	SN: 103244	06-Apr-16 (No. 217-02288)	Арг-17
Power sensor NRP-Z91	SN: 103245	06-Apr-16 (No. 217-02289)	Apr-17
Reference 20 dB Attenuator	SN: S5277 (20x)	05-Apr-16 (No. 217-02293)	Apr-17
Reference Probe ER3DV6	SN: 2328	14-Oct-16 (No. ER3-2328_Oct16)	Oct-17
DAE4	SN: 789	11-Nov-16 (No. DAE4-789_Nov16)	Nov-17
Secondary Standards	ID	Check Date (in house)	Scheduled Check
Power meter E4419B	SN: GB41293874	06-Apr-16 (in house check Jun-16)	In house check: Jun-18
Power sensor E4412A	SN: MY41498087	06-Apr-16 (in house check Jun-16)	In house check: Jun-18
Power sensor E4412A	SN: 000110210	06-Apr-16 (in house check Jun-16)	In house check: Jun-18
RF generator HP 8648C	SN: US3642U01700	04-Aug-99 (in house check Jun-16)	In house check: Jun-18
Network Analyzer HP 8753E	SN: US37390585	18-Oct-01 (in house check Oct-16)	In house check: Oct-17

Name Function Signature

Calibrated by: Johannes Kurikka Laboratory Technician

Approved by: Katja Pokovic Technical Manager

Issued: January 16, 2017
This calibration certificate shall not be reproduced except in full without written approval of the laboratory.

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Glossary:

NORMx,y,z sensitivity in free space diode compression point DCP

CF crest factor (1/duty\_cycle) of the RF signal A, B, C, D modulation dependent linearization parameters

Polarization @ φ rotation around probe axis

9 rotation around an axis that is in the plane normal to probe axis (at measurement center), Polarization 9

i.e., 9 = 0 is normal to probe axis

information used in DASY system to align probe sensor X to the robot coordinate system Connector Angle

#### Calibration is Performed According to the Following Standards:

a) IEEE Std 1309-2005, "IEEE Standard for calibration of electromagnetic field sensors and probes, excluding antennas, from 9 kHz to 40 GHz", December 2005
CTIA Test Plan for Hearing Aid Compatibility, Rev 3.0, November 2013

#### Methods Applied and Interpretation of Parameters:

- NORMx,y,z: Assessed for E-field polarization  $\vartheta$  = 0 for XY sensors and  $\vartheta$  = 90 for Z sensor (f  $\leq$  900 MHz in TEM-cell; f > 1800 MHz: R22 waveguide).
- $NORM(f)x,y,z = NORMx,y,z * frequency_response$  (see Frequency Response Chart).
- DCPx,y,z: DCP are numerical linearization parameters assessed based on the data of power sweep with CW signal (no uncertainty required). DCP does not depend on frequency nor media.
- PAR: PAR is the Peak to Average Ratio that is not calibrated but determined based on the signal characteristics
- Ax,y,z; Bx,y,z; Cx,y,z; Dx,y,z; VRx,y,z: A, B, C, D are numerical linearization parameters assessed based on the data of power sweep for specific modulation signal. The parameters do not depend on frequency nor media. VR is the maximum calibration range expressed in RMS voltage across the diode.
- Spherical isotropy (3D deviation from isotropy): in a locally homogeneous field realized using an open wavequide setup.
- Sensor Offset: The sensor offset corresponds to the offset of virtual measurement center from the probe tip (on probe axis). No tolerance required.
- Connector Angle: The angle is assessed using the information gained by determining the NORMx (no uncertainty required).

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ER3DV6 – SN:2353 January 16, 2017

# Probe ER3DV6

SN:2353

Manufactured: Calibrated:

March 8, 2005 January 16, 2017

Calibrated for DASY/EASY Systems (Note: non-compatible with DASY2 system!)

Certificate No: ER3-2353\_Jan17

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January 16, 2017 ER3DV6 -- SN:2353

# DASY/EASY - Parameters of Probe: ER3DV6 - SN:2353

**Basic Calibration Parameters** 

	Sensor X	Sensor Y	Sensor Z	Unc (k=2)
Norm (µV/(V/m) <sup>2</sup> )	1.49	1.68	1.78	± 10.1 %
DCP (mV) <sup>B</sup>	99.3	98.2	100.1	

**Modulation Calibration Parameters** 

UID	Communication System Name		A dB	Β dB√μV	С	D dB	VR mV	Unc <sup>t</sup> (k=2)
0	CW	X	0.0	0.0	1.0	0.00	210.4	±3.8 %
		Y	0.0	0.0	1.0		207.1	
		Z	0.0	0.0	1.0		201.5	

The reported uncertainty of measurement is stated as the standard uncertainty of measurement multiplied by the coverage factor k=2, which for a normal distribution corresponds to a coverage probability of approximately 95%.

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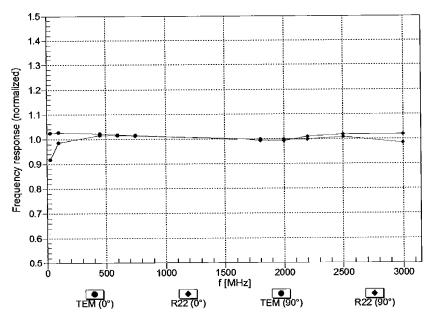
FCC ID: A3LSMG965U	PCTEST HA	AC (RF EMISSIONS) TEST REPORT	SAMSUNG	Approved by: Quality Manager
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B Numerical linearization parameter: uncertainty not required.

E Uncertainty is determined using the max. deviation from linear response applying reclangular distribution and is expressed for the square of the field value.

January 16, 2017 ER3DV6 - SN:2353

# Frequency Response of E-Field (TEM-Cell:ifi110 EXX, Waveguide: R22)



Uncertainty of Frequency Response of E-field: ± 6.3% (k=2)

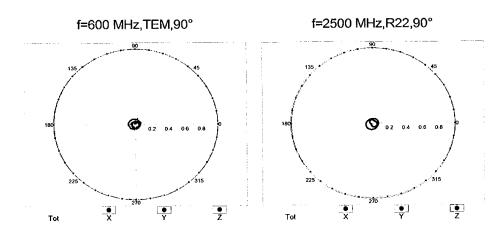
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# Receiving Pattern ( $\phi$ ), $\vartheta = 0^{\circ}$

# Receiving Pattern ( $\phi$ ), $\vartheta = 90^{\circ}$



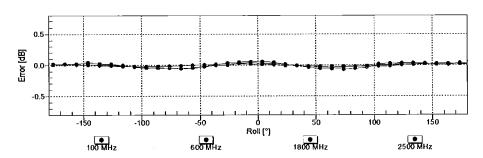
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 FCC ID: A3LSMG965U
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 Approved by: Quality Manager

 Filename:
 Test Dates:
 DUT Type:

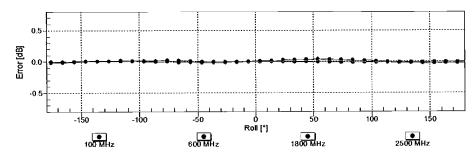
 1M1711060289-13-R1.A3L
 11/06/2017 - 12/11/2017
 Portable Handset

# Receiving Pattern ( $\phi$ ), $\vartheta = 0^{\circ}$



Uncertainty of Axial Isotropy Assessment: ± 0.5% (k=2)

# Receiving Pattern ( $\phi$ ), $\vartheta = 90^{\circ}$



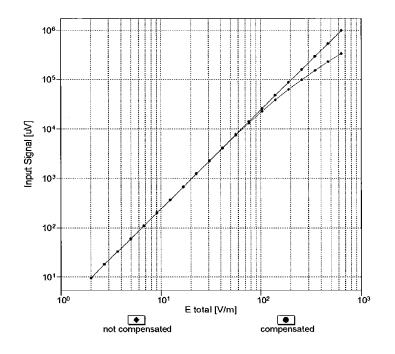
Uncertainty of Axial Isotropy Assessment: ± 0.5% (k=2)

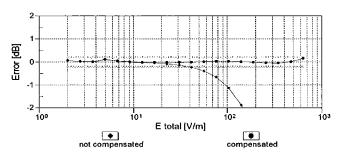
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# Dynamic Range f(E-field) (TEM cell , f = 900 MHz)





Uncertainty of Linearity Assessment: ± 0.6% (k=2)

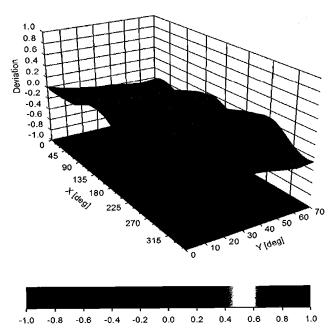
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# **Deviation from Isotropy in Air**

Error (φ, θ), f = 900 MHz



Uncertainty of Spherical Isotropy Assessment: ± 2.6% (k=2)

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ER3DV6 – SN:2353 January 16, 2017

# DASY/EASY - Parameters of Probe: ER3DV6 - SN:2353

#### **Other Probe Parameters**

Sensor Arrangement	Rectangular
Connector Angle (°)	23.8
Mechanical Surface Detection Mode	enabled
Optical Surface Detection Mode	disabled
Probe Overall Length	337 mm
Probe Body Diameter	10 mm
Tip Length	10 mm
Tip Diameter	8 mm
Probe Tip to Sensor X Calibration Point	2.5 mm
Probe Tip to Sensor Y Calibration Point	2.5 mm
Probe Tip to Sensor Z Calibration Point	2.5 mm

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Certificate No: CD835V3-1082\_May16

Object	CD835V3 - SN:	1082	
Calibration procedure(s)	QA CAL-20.v6 Calibration proce	edure for dipoles in air	05/25/2010
Calibration date:	May 10, 2016		05/15/1010
The measurements and the unc	certainties with confidence p	onal standards, which realize the physical unit robability are given on the following pages and ry facility: environment temperature $(22 \pm 3)^{\circ}$ C	d are part of the certificate.
Primary Standards	ID#	Cal Date (Certificate No.)	Scheduled Calibration
Power meter NRP	SN: 104778	06-Apr-16 (No. 217-02288/02289)	Apr-17
Power sensor NRP-Z91	SN: 103244	06-Apr-16 (No. 217-02288)	Apr-17 Apr-17
Power sensor NRP-Z91	SN: 103245	06-Apr-16 (No. 217-02289)	
Reference 20 dB Attenuator	SN: 5058 (20k)	05-Apr-16 (No. 217-02289)	Apr-17
Type-N mismatch combination	SN: 5047.2 / 06327	05-Apr-16 (No. 217-02295)	Apr-17 Apr-17
Probe ER3DV6	SN: 2336	31-Dec-15 (No. ER3-2336_Dec15)	Apr-17 Dec-16
Probe H3DV6	SN: 6065	31-Dec-15 (No. H3-6065_Dec15)	Dec-16
DAE4	SN: 781	04-Sep-15 (No. DAE4-781_Sep15)	Sep-16
	ID#	Check Date (in house)	Scheduled Check
Secondary Standards	10 #		
Secondary Standards Power meter Agilent 4419B	SN: GB42420191	09-Oct-09 (in house check Sep-14)	In house check: Oct-17
		09-Oct-09 (in house check Sep-14) 05-Jan-10 (in house check Sep-14)	
Power meter Agilent 4419B	SN: GB42420191		In house check: Oct-17 In house check: Oct-17 In house check: Oct-17
Power meter Agilent 4419B Power sensor HP E4412A	SN: GB42420191 SN: US38485102	05-Jan-10 (in house check Sep-14)	In house check: Oct-17
Power meter Agilent 4419B Power sensor HP E4412A Power sensor HP 8482A	SN: GB42420191 SN: US38485102 SN: US37295597	05-Jan-10 (in house check Sep-14) 09-Oct-09 (in house check Sep-14)	In house check: Oct-17 In house check: Oct-17
Power meter Agilent 4419B Power sensor HP E4412A Power sensor HP 8482A RF generator R&S SMT-06 Network Analyzer HP 8753E	SN: GB42420191 SN: US38485102 SN: US37295597 SN: 832283/011 SN: US37390585	05-Jan-10 (in house check Sep-14) 09-Oct-09 (in house check Sep-14) 27-Aug-12 (in house check Oct-15)	In house check: Oct-17 In house check: Oct-17 In house check: Oct-17
Power meter Agilent 4419B Power sensor HP E4412A Power sensor HP 8482A RF generator R&S SMT-06	SN: GB42420191 SN: US38485102 SN: US37295597 SN: 832283/011 SN: US37390585	05-Jan-10 (in house check Sep-14) 09-Oct-09 (in house check Sep-14) 27-Aug-12 (in house check Oct-15) 18-Oct-01 (in house check Oct-15)	In house check: Oct-17 In house check: Oct-17 In house check: Oct-17 In house check: Oct-16

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#### References

[1] ANSI-C63.19-2011

American National Standard, Methods of Measurement of Compatibility between Wireless Communications Devices and Hearing Aids,

### Methods Applied and Interpretation of Parameters:

- Coordinate System: y-axis is in the direction of the dipole arms. z-axis is from the basis of the antenna
  (mounted on the table) towards its feed point between the two dipole arms. x-axis is normal to the other axes.
   In coincidence with the standards [1], the measurement planes (probe sensor center) are selected to be at a
  distance of 15 mm above the top metal edge of the dipole arms.
- Measurement Conditions: Further details are available from the hardcopies at the end of the certificate. All
  figures stated in the certificate are valid at the frequency indicated. The forward power to the dipole connector
  is set with a calibrated power meter connected and monitored with an auxiliary power meter connected to a
  directional coupler. While the dipole under test is connected, the forward power is adjusted to the same level.
- Antenna Positioning: The dipole is mounted on a HAC Test Arch phantom using the matching dipole positioner with the arms horizontal and the feeding cable coming from the floor. The measurements are performed in a shielded room with absorbers around the setup to reduce the reflections. It is verified before the mounting of the dipole under the Test Arch phantom, that its arms are perfectly in a line. It is installed on the HAC dipole positioner with its arms parallel below the dielectric reference wire and able to move elastically in vertical direction without changing its relative position to the top center of the Test Arch phantom. The vertical distance to the probe is adjusted after dipole mounting with a DASY5 Surface Check job. Before the measurement, the distance between phantom surface and probe tip is verified. The proper measurement distance is selected by choosing the matching section of the HAC Test Arch phantom with the proper device reference point (upper surface of the dipole) and the matching grid reference point (tip of the probe) considering the probe sensor offset. The vertical distance to the probe is essential for the accuracy.
- Feed Point Impedance and Return Loss: These parameters are measured using a HP 8753E Vector Network
  Analyzer. The impedance is specified at the SMA connector of the dipole. The influence of reflections was
  eliminating by applying the averaging function while moving the dipole in the air, at least 70cm away from any
  obstacles.
- E-field distribution: E field is measured in the x-y-plane with an isotropic ER3D-field probe with 100 mW forward power to the antenna feed point. In accordance with [1], the scan area is 20mm wide, its length exceeds the dipole arm length (180 or 90mm). The sensor center is 15 mm (in z) above the metal top of the dipole arms. Two 3D maxima are available near the end of the dipole arms. Assuming the dipole arms are perfectly in one line, the average of these two maxima (in subgrid 2 and subgrid 8) is determined to compensate for any non-parallelity to the measurement plane as well as the sensor displacement. The E-field value stated as calibration value represents the maximum of the interpolated 3D-E-field, in the plane above the dipole surface.

The reported uncertainty of measurement is stated as the standard uncertainty of measurement multiplied by the coverage factor k=2, which for a normal distribution corresponds to a coverage probability of approximately 95%.

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#### **Measurement Conditions**

DASY system configuration, as far as not given on page 1.

DASY Version	DASY5	V52.8.8
Phantom	HAC Test Arch	
Distance Dipole Top - Probe Center	15 mm	
Scan resolution	dx, dy = 5 mm	
Frequency	835 MHz ± 1 MHz	
Input power drift	< 0.05 dB	

### Maximum Field values at 835 MHz

E-field 15 mm above dipole surface	condition	Interpolated maximum
Maximum measured above high end	100 mW input power	107.5 V/m = 40.63 dBV/m
Maximum measured above low end	100 mW input power	106.1 V/m = 40.51 dBV/m
Averaged maximum above arm	100 mW input power	106.8 V/m ± 12.8 % (k=2)

### Appendix (Additional assessments outside the scope of SCS 0108)

#### **Antenna Parameters**

Frequency	Return Loss	Impedance
800 MHz	16.4 dB	44.5 Ω - 13.4 jΩ
835 MHz	26.3 dB	50.0 Ω + 4.9 jΩ
900 MHz	16.4 dB	57.4 Ω - 14.7 jΩ
950 MHz	21.9 dB	43.6 Ω + 4.0 jΩ
960 MHz	17.2 dB	47.9 Ω + 13.5 jΩ

#### 3.2 Antenna Design and Handling

The calibration dipole has a symmetric geometry with a built-in two stub matching network, which leads to the enhanced bandwidth.

The dipole is built of standard semirigid coaxial cable. The internal matching line is open ended. The antenna is therefore open for DC signals.

Do not apply force to dipole arms, as they are liable to bend. The soldered connections near the feedpoint may be damaged. After excessive mechanical stress or overheating, check the impedance characteristics to ensure that the internal matching network is not affected.

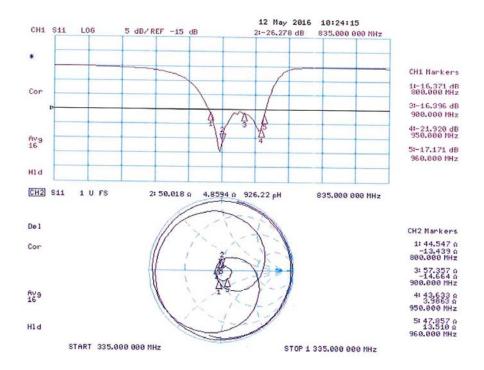
After long term use with 40W radiated power, only a slight warming of the dipole near the feedpoint can be measured.

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# Impedance Measurement Plot



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#### **DASY5 E-field Result**

Date: 10.05.2016

Test Laboratory: SPEAG Lab2

# DUT: HAC-Dipole 835 MHz; Type: CD835V3; Serial: CD835V3 - SN: 1082

Communication System: UID 0 - CW ; Frequency: 835 MHz Medium parameters used:  $\sigma = 0$  S/m,  $\varepsilon_r = 1$ ;  $\rho = 1000$  kg/m<sup>3</sup> Phantom section: RF Section

Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2011)

#### DASY52 Configuration:

- Probe: ER3DV6 SN2336; ConvF(1, 1, 1); Calibrated: 31.12.2015;
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn781; Calibrated: 04.09.2015
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA; Serial: 1070
- DASY52 52.8.8(1258); SEMCAD X 14.6.10(7372)

# Dipole E-Field measurement @ 835MHz/E-Scan - 835MHz d=15mm/Hearing Aid Compatibility Test (41x361x1): Interpolated grid: dx=0.5000 mm, dy=0.5000 mm

Device Reference Point: 0, 0, -6.3 mm

Reference Value = 109.8 V/m; Power Drift = 0.02 dB

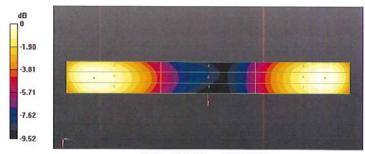
Applied MIF = 0.00 dB

RF audio interference level = 40.63 dBV/m

Emission category: M3

#### MIF scaled E-field

Grid 1 M3 40.52 dBV/m	
Grid 4 M4 35.69 dBV/m	
Grid 7 M3 40.38 dBV/m	



0 dB = 107.5 V/m = 40.63 dBV/m

Certificate No: CD835V3-1082\_May16

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Client

Certificate No: CD1880V3-1064\_May16

#### **CALIBRATION CERTIFICATE** Object CD1880V3 - SN: 1064 Calibration procedure(s) QA CAL-20.v6 Calibration procedure for dipoles in air Calibration date: May 12, 2016 This calibration certificate documents the traceability to national standards, which realize the physical units of measurements (SI). The measurements and the uncertainties with confidence probability are given on the following pages and are part of the certificate. All calibrations have been conducted in the closed laboratory facility: environment temperature (22 ± 3)°C and humidity < 70%. Calibration Equipment used (M&TE critical for calibration) Primary Standards Cal Date (Certificate No.) Scheduled Calibration Power meter NRP SN: 104778 06-Apr-16 (No. 217-02288/02289) Apr-17 Power sensor NRP-Z91 SN: 103244 06-Apr-16 (No. 217-02288) Apr-17 Power sensor NRP-Z91 SN: 103245 06-Apr-16 (No. 217-02289) Apr-17 Reference 20 dB Attenuator SN: 5058 (20k) 05-Apr-16 (No. 217-02292) Apr-17 Type-N mismatch combination SN: 5047.2 / 06327 05-Apr-16 (No. 217-02295) Apr-17 Probe ER3DV6 SN: 2336 31-Dec-15 (No. ER3-2336\_Dec15) Probe H3DV6 SN: 6065 31-Dec-15 (No. H3-6065\_Dec15) Dec-16 DAE4 SN: 781 04-Sep-15 (No. DAE4-781\_Sep15) Sep-16 Secondary Standards ID# Check Date (in house) Scheduled Check Power meter Agilent 4419B SN: GB42420191 09-Oct-09 (in house check Sep-14) In house check: Oct-17 Power sensor HP E4412A SN: US38485102 05-Jan-10 (in house check Sep-14) In house check: Oct-17 Power sensor HP 8482A SN: US37295597 09-Oct-09 (in house check Sep-14) In house check: Oct-17 RF generator R&S SMT-06 SN: 832283/011 27-Aug-12 (in house check Oct-15) In house check: Oct-17 Network Analyzer HP 8753E SN: US37390585 18-Oct-01 (in house check Oct-15) In house check: Oct-16 Function Signature Calibrated by: Jeton Kastrati Laboratory Technician Katja Pokovic Approved by: Technical Manager Issued: May 12, 2016 This calibration certificate shall not be reproduced except in full without written approval of the laboratory.

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Calibration Laboratory of Schmid & Partner Engineering AG Zeughausstrasse 43, 8004 Zurich, Switzerland





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#### References

[1] ANSI-C63.19-2011

American National Standard, Methods of Measurement of Compatibility between Wireless Communications Devices and Hearing Aids.

#### Methods Applied and Interpretation of Parameters:

- Coordinate System: y-axis is in the direction of the dipole arms. z-axis is from the basis of the antenna
  (mounted on the table) towards its feed point between the two dipole arms. x-axis is normal to the other axes.
   In coincidence with the standards [1], the measurement planes (probe sensor center) are selected to be at a
  distance of 15 mm above the top metal edge of the dipole arms.
- Measurement Conditions: Further details are available from the hardcopies at the end of the certificate. All
  figures stated in the certificate are valid at the frequency indicated. The forward power to the dipole connector
  is set with a calibrated power meter connected and monitored with an auxiliary power meter connected to a
  directional coupler. While the dipole under test is connected, the forward power is adjusted to the same level.
- Antenna Positioning: The dipole is mounted on a HAC Test Arch phantom using the matching dipole positioner with the arms horizontal and the feeding cable coming from the floor. The measurements are performed in a shielded room with absorbers around the setup to reduce the reflections. It is verified before the mounting of the dipole under the Test Arch phantom, that its arms are perfectly in a line. It is installed on the HAC dipole positioner with its arms parallel below the dielectric reference wire and able to move elastically in vertical direction without changing its relative position to the top center of the Test Arch phantom. The vertical distance to the probe is adjusted after dipole mounting with a DASY5 Surface Check job. Before the measurement, the distance between phantom surface and probe tip is verified. The proper measurement distance is selected by choosing the matching section of the HAC Test Arch phantom with the proper device reference point (upper surface of the dipole) and the matching grid reference point (tip of the probe) considering the probe sensor offset. The vertical distance to the probe is essential for the accuracy.
- Feed Point Impedance and Return Loss: These parameters are measured using a HP 8753E Vector Network Analyzer. The impedance is specified at the SMA connector of the dipole. The influence of reflections was eliminating by applying the averaging function while moving the dipole in the air, at least 70cm away from any obstacles.
- E-field distribution: E field is measured in the x-y-plane with an isotropic ER3D-field probe with 100 mW forward power to the antenna feed point. In accordance with [1], the scan area is 20mm wide, its length exceeds the dipole arm length (180 or 90mm). The sensor center is 15 mm (in z) above the metal top of the dipole arms. Two 3D maxima are available near the end of the dipole arms. Assuming the dipole arms are perfectly in one line, the average of these two maxima (in subgrid 2 and subgrid 8) is determined to compensate for any non-parallelity to the measurement plane as well as the sensor displacement. The E-field value stated as calibration value represents the maximum of the interpolated 3D-E-field, in the plane above the dipole surface.

The reported uncertainty of measurement is stated as the standard uncertainty of measurement multiplied by the coverage factor k=2, which for a normal distribution corresponds to a coverage probability of approximately 95%.

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### **Measurement Conditions**

DASY system configuration, as far as not given on page 1.

DASY Version	DASY5	V52.8.8
Phantom	HAC Test Arch	
Distance Dipole Top - Probe Center	15 mm	
Scan resolution	dx, dy = 5 mm	
Frequency	1730 MHz ± 1 MHz 1880 MHz ± 1 MHz	
Input power drift	< 0.05 dB	

#### Maximum Field values at 1730 MHz

E-field 15 mm above dipole surface	condition	Interpolated maximum
Maximum measured above high end	100 mW input power	96.1 V/m = 39.66 dBV/m
Maximum measured above low end	100 mW input power	95.3 V/m = 39.58 dBV/m
Averaged maximum above arm	100 mW input power	95.7 V/m ± 12.8 % (k=2)

### Maximum Field values at 1880 MHz

E-field 15 mm above dipole surface	condition	Interpolated maximum
Maximum measured above high end	100 mW input power	91.2 V/m = 39.20 dBV/m
Maximum measured above low end	100 mW input power	88.0 V/m = 38.89 dBV/m
Averaged maximum above arm	100 mW input power	89.6 V/m ± 12.8 % (k=2)

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#### Appendix (Additional assessments outside the scope of SCS 0108)

#### **Antenna Parameters**

#### **Nominal Frequencies**

Frequency	Return Loss	Impedance
1730 MHz	24.0 dB	49.6 Ω + 6.3 jΩ
1880 MHz	19.8 dB	49.5 Ω + 10.2 jΩ
1900 MHz	20.4 dB	52.9 Ω + 9.4 jΩ
1950 MHz	26.8 dB	54.4 Ω + 1.8 jΩ
2000 MHz	22.7 dB	$43.2 \Omega + 0.8 jΩ$

### 3.2 Antenna Design and Handling

The calibration dipole has a symmetric geometry with a built-in two stub matching network, which leads to the enhanced bandwidth.

The dipole is built of standard semirigid coaxial cable. The internal matching line is open ended. The antenna is therefore open for DC signals.

Do not apply force to dipole arms, as they are liable to bend. The soldered connections near the feedpoint may be damaged. After excessive mechanical stress or overheating, check the impedance characteristics to ensure that the internal matching network is not affected.

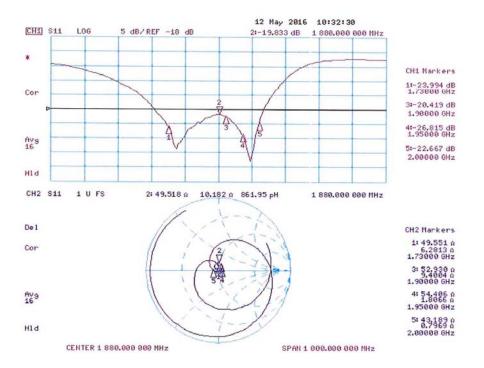
After long term use with 40W radiated power, only a slight warming of the dipole near the feedpoint can be measured.

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### Impedance Measurement Plot



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#### **DASY5 E-field Result**

Date: 10.05.2016

Test Laboratory: SPEAG Lab2

# DUT: HAC Dipole 1880 MHz; Type: CD1880V3; Serial: CD1880V3 - SN: 1064

Communication System: UID 0 - CW ; Frequency: 1880 MHz, Frequency: 1730 MHz Medium parameters used:  $\sigma=0$  S/m,  $\epsilon_r=1$ ;  $\rho=1000$  kg/m³ Phantom section: RF Section Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2011)

#### DASY52 Configuration:

- Probe: ER3DV6 SN2336; ConvF(1, 1, 1); Calibrated: 31.12.2015;
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn781; Calibrated: 04.09.2015
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA; Serial: 1070
- DASY52 52.8.8(1258); SEMCAD X 14.6.10(7372)

Dipole E-Field measurement @ 1880MHz/E-Scan - 1880MHz d=15mm/Hearing Aid Compatibility Test (41x181x1):

Interpolated grid: dx=0.5000 mm, dy=0.5000 mm Device Reference Point: 0, 0, -6.3 mm Reference Value = 151.7 V/m; Power Drift = -0.01 dB Applied MIF = 0.00 dB RF audio interference level = 39.20 dBV/m

Emission category: M2

MIF scaled E-field

Grid 1 M2 39.04 dBV/m	Grid 3 <b>M2</b> <b>39.08 dBV/m</b>
Grid 4 M2 36.76 dBV/m	
Grid 7 M2 38.68 dBV/m	Grid 9 M2 38.8 dBV/m

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Dipole E-Field measurement @ 1880MHz/E-Scan - 1730MHz d=15mm/Hearing Aid Compatibility Test (41x181x1):

Interpolated grid: dx=0.5000 mm, dy=0.5000 mm

Device Reference Point: 0, 0, -6.3 mm

Reference Value = 168.3 V/m; Power Drift = 0.00 dB

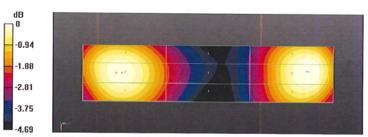
Applied MIF = 0.00 dB

RF audio interference level = 39.66 dBV/m

Emission category: M2

#### MIF scaled E-field

Grid 2 M2 39.58 dBV/m	
Grid 5 M2 37.56 dBV/m	
 Grid 8 M2 39.66 dBV/m	The state of the s



0 dB = 91.23 V/m = 39.20 dBV/m

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Client

**PC Test** 

Certificate No: CD2600V3-1013\_Jun17/2

# CALIBRATION CERTIFICATE (Replacement of No:CD2600V3-1013\_Jun17)

Object

CD2600V3 - SN: 1013

Calibration procedure(s)

QA CAL-20.v6

Calibration procedure for dipoles in air

08/02/201

Calibration date:

June 14, 2017

This calibration certificate documents the traceability to national standards, which realize the physical units of measurements (SI). The measurements and the uncertainties with confidence probability are given on the following pages and are part of the certificate.

All calibrations have been conducted in the closed laboratory facility: environment temperature (22 ± 3)°C and humidity < 70%.

Calibration Equipment used (M&TE critical for calibration)

ID#	Cal Date (Certificate No.)	Scheduled Calibration
SN: 104778	04-Apr-17 (No. 217-02521/02522)	Apr-18
SN: 103244	04-Apr-17 (No. 217-02521)	Apr-18
SN: 103245	04-Apr-17 (No. 217-02522)	Apr-18
SN: 5058 (20k)	07-Apr-17 (No. 217-02528)	Apr-18
SN: 5047.2 / 06327	07-Apr-17 (No. 217-02529)	Apr-18
SN: 4013	21-Jun-16 (No. EF3-4013_Jun16)	Jun-17
SN: 781	02-Sep-16 (No. DAE4-781_Sep16)	Sep-17
ID#	Check Date (in house)	Scheduled Check
SN: GB42420191	09-Oct-09 (in house check Sep-14)	In house check: Oct-17
SN: US38485102	05-Jan-10 (in house check Sep-14)	In house check: Oct-17
SN: US37295597	09-Oct-09 (in house check Sep-14)	In house check: Oct-17
SN: 832283/011	27-Aug-12 (in house check Oct-15)	In house check: Oct-17
SN: US37390585	18-Oct-01 (in house check Oct-16)	In house check: Oct-17
Name	Function	Signature
Johannes Kurikka	Laboratory Technician	me la
Kalja Pokovic	Technical Manager	
	SN: 104778 SN: 103244 SN: 103245 SN: 5058 (20k) SN: 5047.2 / 06327 SN: 4013 SN: 781 ID # SN: GB42420191 SN: US37295597 SN: 832283/011 SN: US37390585 Name Johannes Kurikka	SN: 104778

Issued: July 20, 2017

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Accreditation No.: SCS 0108

#### References

 ANSI-C63.19-2011
 American National Standard, Methods of Measurement of Compatibility between Wireless Communications Devices and Hearing Aids.

#### Methods Applied and Interpretation of Parameters:

- Coordinate System: y-axis is in the direction of the dipole arms. z-axis is from the basis of the antenna
  (mounted on the table) towards its feed point between the two dipole arms. x-axis is normal to the other axes.
  In coincidence with the standards [1], the measurement planes (probe sensor center) are selected to be at a
  distance of 15 mm above the top metal edge of the dipole arms.
- Measurement Conditions: Further details are available from the hardcopies at the end of the certificate. All
  figures stated in the certificate are valid at the frequency indicated. The forward power to the dipole connector
  is set with a calibrated power meter connected and monitored with an auxiliary power meter connected to a
  directional coupler. While the dipole under test is connected, the forward power is adjusted to the same level.
- Antenna Positioning: The dipole is mounted on a HAC Test Arch phantom using the matching dipole positioner with the arms horizontal and the feeding cable coming from the floor. The measurements are performed in a shielded room with absorbers around the setup to reduce the reflections. It is verified before the mounting of the dipole under the Test Arch phantom, that its arms are perfectly in a line. It is installed on the HAC dipole positioner with its arms parallel below the dielectric reference wire and able to move elastically in vertical direction without changing its relative position to the top center of the Test Arch phantom. The vertical distance to the probe is adjusted after dipole mounting with a DASY5 Surface Check job. Before the measurement, the distance between phantom surface and probe tip is verified. The proper measurement distance is selected by choosing the matching section of the HAC Test Arch phantom with the proper device reference point (upper surface of the dipole) and the matching grid reference point (tip of the probe) considering the probe sensor offset. The vertical distance to the probe is essential for the accuracy.
- Feed Point Impedance and Return Loss: These parameters are measured using a HP 8753E Vector Network
  Analyzer. The impedance is specified at the SMA connector of the dipole. The influence of reflections was
  eliminating by applying the averaging function while moving the dipole in the air, at least 70cm away from any
  obstacles.
- E-field distribution: E field is measured in the x-y-plane with an isotropic ER3D-field probe with 100 mW forward power to the antenna feed point. In accordance with [1], the scan area is 20mm wide, its length exceeds the dipole arm length (180 or 90mm). The sensor center is 15 mm (in z) above the metal top of the dipole arms. Two 3D maxima are available near the end of the dipole arms. Assuming the dipole arms are perfectly in one line, the average of these two maxima (in subgrid 2 and subgrid 8) is determined to compensate for any non-parallelity to the measurement plane as well as the sensor displacement. The E-field value stated as calibration value represents the maximum of the interpolated 3D-E-field, in the plane above the dipole surface.

coverage factor k=2, which for a normal distribution corresponds to a coverage probability of approximately 9	
The reported uncertainty of measurement is stated as the standard uncertainty of measurement multiplied by	the

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#### **Measurement Conditions**

DASY system configuration, as far as not given on page 1.

DASY Version	DASY5	V52.10.0
Phantom	HAC Test Arch	
Distance Dipole Top - Probe Center	15 mm	
Scan resolution	dx, dy = 5 mm	
Frequency	2600 MHz ± 1 MHz	
Input power drift	< 0.05 dB	

#### Maximum Field values at 2600 MHz

E-field 15 mm above dipole surface	condition	Interpolated maximum
Maximum measured above high end	100 mW input power	84.9 V/m = 38.58 dBV/m
Maximum measured above low end	100 mW input power	84.0 V/m = 38.48 dBV/m
Averaged maximum above arm	100 mW input power	84.5 V/m ± 12.8 % (k=2)

# Appendix (Additional assessments outside the scope of SCS 0108)

#### **Antenna Parameters**

Frequency	Return Loss	Impedance
2450 MHz	23.3 dB	44.8 Ω - 3.8 jΩ
2550 MHz	32.2 dB	51.0 Ω + 2.3 jΩ
2600 MHz	29.5 dB	53.4 Ω - 0.3 jΩ
2650 MHz	27.0 dB	53.2 Ω - 3.3 jΩ
2750 MHz	19.7 dB	45.7 Ω - 8.9 jΩ

#### 3.2 Antenna Design and Handling

The calibration dipole has a symmetric geometry with a built-in two stub matching network, which leads to the enhanced bandwidth.

The dipole is built of standard semirigid coaxial cable. The internal matching line is open ended. The antenna is therefore open for DC signals.

Do not apply force to dipole arms, as they are liable to bend. The soldered connections near the feedpoint may be damaged. After excessive mechanical stress or overheating, check the impedance characteristics to ensure that the internal matching network is not affected.

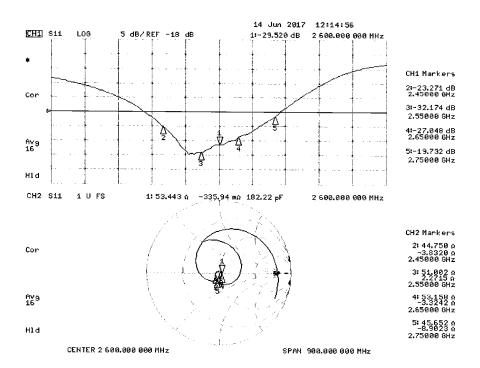
After long term use with 40W radiated power, only a slight warming of the dipole near the feedpoint can be measured.

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### **Impedance Measurement Plot**



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#### **DASY5 E-field Result**

Date: 14.06.2017

Test Laboratory: SPEAG Lab2

#### DUT: HAC Dipole 2600 MHz; Type: CD2600V3; Serial: CD2600V3 - SN: 1013

Communication System: UID 0 - CW ; Frequency: 2600 MHz Medium parameters used:  $\sigma$  = 0 S/m,  $\epsilon_r$  = 1;  $\rho$  = 1000 kg/m<sup>3</sup>

Phantom section: RF Section

#### DASY52 Configuration:

- Probe: EF3DV3 SN4013; ConvF(1, 1, 1); Calibrated:21.06.2016;
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn781; Calibrated: 02.09.2016
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA; Serial: 1070
- DASY52 52.10.0(1444); SEMCAD X 14.6.10(7416)

# Dipole E-Field measurement @ 2600MHz - with EF\_4013/E-Scan - 2600MHz d=15mm/Hearing Aid Compatibility Test (41x181x1): Interpolated grid: dx=0.5000 mm, dy=0.5000 mm

Device Reference Point: 0, 0, -6.3 mm

Reference Value = 68.41 V/m; Power Drift = -0.01 dB

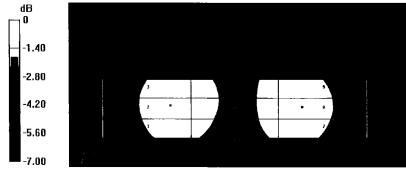
PMR not calibrated. PMF = 1.000 is applied.

E-field emissions = 84.92 V/m

Near-field category: M3 (AWF 0 dB)

#### PMF scaled E-field

Grid 1 M3 81.71 V/m	
Grid 4 M3 77.39 V/m	
Grid 7 M3 82.82 V/m	



0 dB = 84.92 V/m = 38.58 dBV/m

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# 16. CONCLUSION

The measurements, taken in accordance with the procedures provided in the CTIA Test Plan for Hearing Aid Compatibility Rev 3.1, February 2017, indicate that the wireless communications device complies with the HAC limits specified in the ANSI C63.19 Standard and FCC WT Docket No. 01-309 RM-8658. Precise laboratory measures were taken to assure repeatability of the tests. The tested device complies with the requirements in respect to all parameters specific to the test. The test results and statements relate only to the item(s) tested.

Please note that the M-rating for this equipment only represents the field interference possible against a hypothetical and typical hearing aid. The measurement system and techniques presented in this evaluation are proposed in the ANSI standard as a means of best approximating wireless device compatibility with a hearing-aid. The literature is under continual re-construction.

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### 17. REFERENCES

- ANSI/IEEE C63.19-2011, "American National Standard for Methods of Measurement of Compatibility between Wireless Communication Devices and Hearing Aids.", New York, NY, IEEE, May 2011
- 2. CTIA Certification Program, "Test Plan for Hearing Aid Compatibility Rev 3.1", Washington, DC, CTIA, February 2017
- 3. FCC Office of Engineering and Technology KDB, "285076 D01 HAC Guidance v05," September 13, 2017
- FCC Office of Engineering and Technology KDB, "285076 D02 T-Coil Testing for CMRS IP v03," September 13, 2017
- FCC Public Notice DA 06-1215, Wireless Telecommunications Bureau and Office of Engineering and Technology Clarify Use of Revised Wireless Phone Hearing Aid Compatibility Standard, June 6, 2006
- 6. FCC 3G Review Guidance, Laboratory Division OET FCC, May/June 2006
- 7. Berger, H. S., "Compatibility Between Hearing Aids and Wireless Devices," Electronic Industries Forum, Boston, MA, May, 1997
- 8. Berger, H. S., "Hearing Aid and Cellular Phone Compatibility: Working Toward Solutions," Wireless Telephones and Hearing Aids: New Challenges for Audiology, Gallaudet University, Washington, D.C., May, 1997 (To be reprinted in the American Journal of Audiology).
- 9. Berger, H. S., "Hearing Aid Compatibility with Wireless Communications Devices, " IEEE International Symposium on Electromagnetic Compatibility, Austin, TX, August, 1997.
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